Xyce™ Parallel Electronic Simulator
Users’ Guide, Version 6.0.1

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Xyce™ Parallel Electronic Simulator
Users’ Guide, Version 6.0.1

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Abstract

This manual describes the use of the Xyce Parallel Electronic Simulator. Xyce has been designed as a SPICE-compatible, high-performance analog circuit simulator, and has been written to support the simulation needs of the Sandia National Laboratories electrical designers. This development has focused on improving capability over the current state-of-the-art in the following areas:

- Capability to solve extremely large circuit problems by supporting large-scale parallel computing platforms (up to thousands of processors). This includes support for most popular parallel and serial computers.
- A differential-algebraic-equation (DAE) formulation, which better isolates the device model package from solver algorithms. This allows one to develop new types of analysis without requiring the implementation of analysis-specific device models.
- Device models that are specifically tailored to meet Sandia’s needs, including some radiation-aware devices (for Sandia users only).
- Object-oriented code design and implementation using modern coding practices.

Xyce is a parallel code in the most general sense of the phrase — a message passing parallel implementation — which allows it to run efficiently a wide range of computing platforms. These include serial, shared-memory and distributed-memory parallel platforms. Attention has been paid to the specific nature of circuit-simulation problems to ensure that optimal parallel efficiency is achieved as the number of processors grows.
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Written by Alan Hindmarsh, Allan Taylor, Radu Serban.
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Xyce's expression library is based on that inside Spice 3F5 developed by the EECS Department at the University of California.

The EKV3 MOSFET model was developed by the EKV Team of the Electronics Laboratory-TUC of the Technical University of Crete.

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Bug Reports (Sandia only)

http://joseki.sandia.gov/bugzilla
http://charleston.sandia.gov/bugzilla

World Wide Web

http://xyce.sandia.gov
http://charleston.sandia.gov/xyce (Sandia only)

Email

xyce@sandia.gov (outside Sandia)
xyce-sandia@sandia.gov (Sandia only)
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1. Introduction

Welcome to Xyce

The Xyce Parallel Electronic Simulator is a SPICE-compatible circuit simulator that has been written to support the unique simulation needs of electrical designers at Sandia National Laboratories. It is specifically targeted to run on large-scale parallel computing platforms, but is also available on a variety of architectures including single processor workstations. It aims to support a variety of devices and models specific to Sandia needs, as well as standard capabilities available from current commercial simulators.
1.1  **Xyce** Overview

The **Xyce** Parallel Electronic Simulator project was started in 1999 to support the simulation needs of electrical designers at Sandia National Laboratories and has evolved into a mature platform for large-scale circuit simulation.

**Xyce** includes several unique features. An important driver has been the need to simulate very large-scale circuits (100,000 devices or more) on the transistor level. To this end, scalable algorithms for simulating large circuits in parallel have been developed. In addition, **Xyce** includes novel approaches to numerical kernels including model-order reduction, continuation algorithms, time-integration, nonlinear and linear solvers. Also, unlike most SPICE-based codes, **Xyce** uses a differential-algebraic-equation (DAE) formulation, which better isolates the device model package from solver algorithms.

1.2  **Xyce** Capabilities

1.2.1  Support for Large-Scale Parallel Computing

**Xyce** is a truly parallel simulation code, designed and written from the ground up to support large-scale parallel computing architectures with up to thousands of processors. This provides **Xyce** the capability to solve large circuit problems with quick enough runtimes to make these simulations practical. **Xyce** uses a message passing parallel implementation, allowing it to run efficiently on a variety of parallel computing platforms. These include serial, shared-memory and distributed-memory parallel. Careful attention has been paid to the specific nature of circuit-simulation problems to ensure optimal parallel efficiency, even as the number of processors increases.

1.2.2  Differential-Algebraic Equation (DAE) formulation

**Xyce** has been designed to use a DAE formulation. Among other advantages, this has the benefit of allowing the device models to be nearly independent of the type analysis to be performed, and allows a lot of encapsulation between the models and the solver layers of the source code. In a SPICE-based code, new device functions are created for each type of analysis, such as transient and AC analysis. With **Xyce**’s DAE implementation, this is not necessary. The same device load functions can be used for all analysis types, resulting in faster development time for new types of analysis.

1.2.3  Device Model Support

The **Xyce** development team continually adds new device models to **Xyce** to meet the needs of Sandia users. This includes the full set of models that can be found in most SPICE-based codes. For current device availability, consult The **Xyce** Reference Guide [3].
1.3 Reference Guide

The **Xyce** User's Guide companion document, the **Xyce** Reference Guide [3], contains detailed information including a netlist reference for **Xyce**-supported input-file commands and elements; a command line reference, which describes the available command line arguments; and quick-references for users of other circuit codes, such as Orcad's PSpice [4].

1.4 How to Use this Guide

This guide is designed to enable one to quickly find the information needed to use **Xyce**. It assumes familiarity with basic Unix-type commands, and how Unix manages applications and files to perform routine tasks (e.g., starting applications, opening files, and saving work).

**Typographical conventions**

Table 1.1 defines the typographical conventions used in this guide.

<table>
<thead>
<tr>
<th>Notation</th>
<th>Example</th>
<th>Description</th>
</tr>
</thead>
<tbody>
<tr>
<td>Typewriter text</td>
<td>xmpirun -np 4</td>
<td>Commands entered from the keyboard on the command line or text entered in a netlist.</td>
</tr>
<tr>
<td><strong>Bold Roman Font</strong></td>
<td>Set nominal temperature using the TNOM option.</td>
<td>SPICE-type parameters used in models, etc.</td>
</tr>
<tr>
<td><strong>Gray Shaded Text</strong></td>
<td><strong>DEBUGLEVEL</strong></td>
<td>Feature that is designed primarily for use by <strong>Xyce</strong> developers.</td>
</tr>
<tr>
<td>[text in brackets]</td>
<td>Xyce [options] &lt;netlist&gt;</td>
<td>Optional parameters.</td>
</tr>
<tr>
<td>&lt;text in angle brackets&gt;</td>
<td>Xyce [options] &lt;netlist&gt;</td>
<td>Parameters to be inserted by the user.</td>
</tr>
<tr>
<td>&lt;object with asterisk&gt;*</td>
<td>K1 &lt;ind. 1&gt; [&lt;ind. n&gt;*]</td>
<td>Parameter that may be multiply specified.</td>
</tr>
<tr>
<td>&lt;TEXT1</td>
<td>TEXT2&gt;</td>
<td>.PRINT TRAN + DELIMITER=&lt;TAB</td>
</tr>
</tbody>
</table>
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2. Installing and Running Xyce

Chapter Overview

This chapter describes the basic mechanics of installing and running Xyce. It includes the following sections:

- Section 2.1 Xyce Installation
- Section 2.2 Running Xyce
2.1 Xyce Installation

Xyce is distributed in two ways: source code and binary installers. At this time, binary installers are available only to Sandia users.

Installation from binary installers is described in the Xyce Installation Guide, which should have been provided to you along with the installer.

Installation from source code is described in the Xyce Building Guide, and is available on the Xyce web site along with the source code.

2.2 Running Xyce

While it is possible to connect Xyce to graphical interfaces, such as gEDA [5], Xyce is not provided with any graphical user interface. It is primarily used as a command-line-only program across all supported platforms, including traditionally “GUI-centered” platforms such as Mac OS X and Microsoft Windows.

This section describes how Xyce is run from the command line, for serial and MPI parallel simulations.

2.2.1 Command Line Simulation

Running Xyce from the command line is straightforward. The scripts xmpirun and runxyce set up the runtime environment and execute Xyce. Depending on whether one uses a version compiled with MPI support or a serial version, there are two ways to begin running Xyce:

- Running serial Xyce:
  
  > runxyce [options] <netlist filename>

- Running Xyce in parallel:
  
  > xmpirun -np <# procs> [options] <netlist filename>

where [options] are the command line arguments for Xyce. For example, to log output to a file named sample.log type:

  > runxyce -l sample.log <netlist filename>

The next example runs parallel Xyce on four processors and places the results into a comma separated value file named results.csv:

  > xmpirun -np 4 -delim COMMA -o results.csv <netlist filename>
While Xyce is running, simulation progress is output to the command line window.

The above examples assume that <netlist filename> is either in the current working directory, or includes the path (full or relative) to the netlist file. Enclose the filename in quotation marks ("if the path contains spaces. Help is accessible with the -h option.

For MPI runs, [options] may also include command line arguments to mpirun. Consult the documentation installed with MPI on the user's platform for more details concerning MPI options. The -np <# procs> denotes the number of processors to use for the simulation. NOTE: It is critical that the number of processors used must be smaller than the number of devices and voltage nodes in the netlist.

Table 2.1 lists appropriate scripts used to run Xyce for each supported platform.

Table 2.1. Platform scripts for running Xyce.

<table>
<thead>
<tr>
<th>Architecture</th>
<th>OS</th>
<th>Serial Executable</th>
<th>MPI Executable</th>
</tr>
</thead>
<tbody>
<tr>
<td>x86-64</td>
<td>OSX</td>
<td>runxyce</td>
<td>xmpirun</td>
</tr>
<tr>
<td>x86 and x86-64</td>
<td>Linux</td>
<td>runxyce</td>
<td>xmpirun</td>
</tr>
<tr>
<td>x86</td>
<td>Microsoft Windows</td>
<td>runxyce.bat</td>
<td>not available</td>
</tr>
</tbody>
</table>

Sandia HPC platform (TLCC, Glory, Red Sky) users must set several environment variables to run Xyce. A system module is available to handle this. To load the xyce module, use the command:

module load xyce

Consult the system documentation for help with submitting jobs on these platforms

https://computing.sandia.gov

Guidance for Running Xyce in Parallel

The basic mechanics of running Xyce in parallel has been discussed above. For general guidance regarding solver options, partitioning options, and other parallel issues, refer to chapter 10. Distributed memory circuit simulation still contains a number of research issues, so obtaining an optimal simulation in parallel is a bit of an art.

2.2.2 Command Line Options

Xyce supports a handful of command line options that must be given before the netlist filename. Table 2.2 lists Xyce core options.
<table>
<thead>
<tr>
<th>Argument</th>
<th>Description</th>
<th>Usage</th>
<th>Default</th>
</tr>
</thead>
<tbody>
<tr>
<td>-h</td>
<td>Help option. Prints usage and exits.</td>
<td>-h</td>
<td>-</td>
</tr>
<tr>
<td>-v</td>
<td>Prints the version banner and exits.</td>
<td>-v</td>
<td>-</td>
</tr>
<tr>
<td>-delim</td>
<td>Set the output file field delimiter.</td>
<td>-delim &lt;TAB</td>
<td>COMMA</td>
</tr>
<tr>
<td>-o</td>
<td>Place the results into specified file.</td>
<td>-o &lt;file&gt;</td>
<td>-</td>
</tr>
<tr>
<td>-l</td>
<td>Place the log output into specified file.</td>
<td>-l &lt;file&gt;</td>
<td>-</td>
</tr>
<tr>
<td>-r</td>
<td>Output a binary rawfile.</td>
<td>-r &lt;file&gt;</td>
<td>-</td>
</tr>
<tr>
<td>-a</td>
<td>Use with -r to output a readable (ascii) rawfile.</td>
<td>-r &lt;file&gt; -a</td>
<td>-</td>
</tr>
<tr>
<td>-nox</td>
<td>Use the NOX nonlinear solver.</td>
<td>-nox &lt;ON</td>
<td>OFF&gt;</td>
</tr>
<tr>
<td>-info</td>
<td>Output information on parameters.</td>
<td>-info [device prefix] [level] [ON</td>
<td>OFF]</td>
</tr>
<tr>
<td>-linsolv</td>
<td>Set the linear solver.</td>
<td>-linsolv &lt;KLU</td>
<td>SUPERLU</td>
</tr>
<tr>
<td>-param</td>
<td>Print a terse summary of model parameters, device parameters and default values.</td>
<td>-param</td>
<td>-</td>
</tr>
<tr>
<td>-syntax</td>
<td>Check netlist syntax and exit.</td>
<td>-syntax</td>
<td>-</td>
</tr>
<tr>
<td>-norun</td>
<td>Netlist syntax and topology and exit.</td>
<td>-norun</td>
<td>-</td>
</tr>
<tr>
<td>-maxord</td>
<td>Maximum time integration order.</td>
<td>-maxord &lt;1..5&gt;</td>
<td>-</td>
</tr>
<tr>
<td>-gui</td>
<td>GUI file output.</td>
<td>-gui</td>
<td>-</td>
</tr>
<tr>
<td>-jacobian_test</td>
<td>Jacobian matrix diagnostic.</td>
<td>-jacobian_test</td>
<td>-</td>
</tr>
</tbody>
</table>

While these options are intended for general use, others may exist for new features that are disabled by default, and older, deprecated features. The Xyce Reference Guide provides a comprehensive list, including trial and deprecated options.
3. Simulation Examples with Xyce

Chapter Overview

This chapter provides several simple examples of Xyce usage. An example circuit is provided for each available analysis type.

- Section 3.1 Example Circuit Construction
- Section 3.2 DC Sweep Analysis
- Section 3.3 Transient Analysis
3.1 Example Circuit Construction

This section describes how to use Xyce to create the simple diode clipper circuit shown in figure 3.2.

**Xyce** only supports circuit creation via netlist editing. **Xyce** supports most of the standard netlist entries common to Berkeley SPICE 3F5 and Orcad PSpice. For users familiar with PSpice netlists, the **Xyce** Reference Guide [3] lists the differences between PSpice and **Xyce** netlists.

**Example: diode clipper circuit**

Using a plain text editor (e.g., VI, Emacs, Notepad) but not a word processor (e.g., OpenOffice or Microsoft Word), create a file containing the netlist of figure 3.1. For this example, the file is named clipper.cir.

The netlist in figure 3.1 illustrates some of the syntax of a netlist input file. Netlists always begin with a title line (e.g. "Diode Clipper Circuit"), and may contain comments (lines beginning with the "*" character), devices, and model definitions. Netlists must always end with the "*.END" statement.

The diode clipper circuit contains two-terminal devices (diodes, resistors, and capacitors), each of which specifies two connecting nodes and either a model (for the diode) or a value (resistance or capacitance). The netlist of figure 3.1 describes the circuit in the schematic of figure 3.2.

This netlist file is not yet complete and will not run properly using **Xyce** (see section 2.2 for instructions on running **Xyce**) as it lacks an analysis statement. This chapter later describes how to add the appropriate analysis statement and run the clipper circuit.
Diode Clipper Circuit
*
* Voltage Sources
VCC 1 0 5V
VIN 3 0 0V
* Diodes
D1 2 1 D1N3940
D2 0 2 D1N3940
* Resistors
R1 2 3 1K
R2 1 2 3.3K
R3 2 0 3.3K
R4 4 0 5.6K
* Capacitor
C1 2 4 0.47u
*
* GENERIC FUNCTIONAL EQUIVALENT = 1N3940
* TYPE: DIODE
* SUBTYPE: RECTIFIER
.MODEL D1N3940 D(
+ IS = 4E-10
+ RS = .105
+ N = 1.48
+ TT = 8E-7
+ CJO = 1.95E-11
+ VJ = .4
+ M = .38
+ EG = 1.36
+ XTI = -8
+ KF = 0
+ AF = 1
+ FC = .9
+ BV = 600
+ IBV = 1E-4)
*
.END

Figure 3.1. Diode clipper circuit netlist
3.2 DC Sweep Analysis

This section includes an example of DC sweep analysis using Xyce. The DC response of the clipper circuit is obtained by sweeping the DC voltage source ($V_{in}$) from -10 to 15 volts in one-volt steps. Chapter 7.2 provides more details about DC analysis, as does the Xyce Reference Guide [3].

Example: DC sweep analysis

To set up and run a DC sweep analysis using the diode clipper circuit:

1. Open the diode clipper circuit netlist file (clipper.cir) using a standard text editor (e.g. Vi, Emacs, Notepad, etc.).

2. Enter the analysis control statement in the netlist:

   .DC VIN -10 15 1

3. Enter the output control statement:

   .PRINT DC V(3) V(2) V(4)
4. Save the netlist file and run Xyce on the circuit. For example, to run serial Xyce:

   > runxyce clipper.cir

5. Open the results file (clipper.cir.prn) and examine (or plot) the output voltages that were calculated for nodes 3 (Vin), 2 and 4 (Out). Figure 3.4 shows the output plotted as a function of the swept variable Vin.

![Figure 3.4. DC sweep voltages at Vin, node 2, and Vout](image)

### 3.3 Transient Analysis

This section contains an example of transient analysis in Xyce. In this example the DC clipper circuit of the previous section has been modified so the input voltage source (Vin) is a time-dependent sinusoidal input source. The frequency of Vin is 1 kHz, and has an amplitude of 10 volts. For more details about transient analysis see chapter 7.3 or the Xyce reference guide [3].

**Example: transient analysis**

To set up and run a transient analysis using the diode clipper circuit:

1. Open the diode clipper circuit netlist file (clipper.cir) using a standard text editor (e.g. VI, Emacs, Notepad, etc.).

2. Remove DC analysis and output statements if added in the previous example (figure 3.4).

3. Enter the analysis control in the netlist:

   .TRAN 2ns 2ms
Diode Clipper Circuit with DC sweep analysis statement
 *
 * Voltage Sources
 VCC 1 0 5V
 VIN 3 0 0V
 * Analysis Command
 .DC VIN -10 15 1
 * Output
 .PRINT DC V(3) V(2) V(4)
 * Diodes
 D1 2 1 D1N3940
 D2 0 2 D1N3940
 * Resistors
 R1 2 3 1K
 R2 1 2 3.3K
 R3 2 0 3.3K
 R4 4 0 5.6K
 * Capacitor
 C1 2 4 0.47u
 *
 * GENERIC FUNCTIONAL EQUIVALENT = 1N3940
 * TYPE: DIODE
 * SUBTYPE: RECTIFIER
 .MODEL D1N3940 D(
 + IS = 4E-10
 + RS = .105
 + N = 1.48
 + TT = 8E-7
 + CJ0 = 1.95E-11
 + VJ = .4
 + M = .38
 + EG = 1.36
 + XTI = -8
 + KF = 0
 + AF = 1
 + FC = .9
 + BV = 600
 + IBV = 1E-4)
 *
 .END

Figure 3.3. Diode clipper circuit netlist for DC sweep analysis
4. Enter the output control statement:

```
.PRINT TRAN V(3) V(2) V(4)
```

5. Modify the input voltage source (Vin) to generate the sinusoidal input signal:

```
VIN 3 0 SIN(0V 10V 1kHz)
```

6. At this point, the netlist should look similar to the netlist in figure 3.5. Save the netlist file and run Xyce on the circuit. For example, to run serial Xyce:

```
> runxyce clipper.cir
```

7. Open the results file and examine (or plot) the output voltages for nodes 3 (Vin), 2, and 4 (Out). The plot in figure 3.6 shows the output plotted as a function of time.

Figure 3.5 shows the modified netlist and figure 3.6 shows the corresponding results.

![Figure 3.6. Sinusoidal input signal and clipped outputs](image)
Diode clipper circuit with transient analysis statement

* Voltage Sources
VCC 1 0 5V
VIN 3 0 SIN(0V 10V 1kHz)

* Analysis Command
.TRAN 2ns 2ms

* Output
.PRINT TRAN V(3) V(2) V(4)

* Diodes
D1 2 1 D1N3940
D2 0 2 D1N3940

* Resistors
R1 2 3 1K
R2 1 2 3.3K
R3 2 0 3.3K
R4 4 0 5.6K

* Capacitor
C1 2 4 0.47u

* GENERIC FUNCTIONAL EQUIVALENT = 1N3940
* TYPE: DIODE
* SUBTYPE: RECTIFIER
.MODEL D1N3940 D(
+ IS = 4E-10
+ RS = .105
+ N = 1.48
+ TT = 8E-7
+ CJ0 = 1.95E-11
+ VJ = .4
+ M = .38
+ EG = 1.36
+ XTI = -8
+ KF = 0
+ AF = 1
+ FC = .9
+ BV = 600
+ IBV = 1E-4)

.END

Figure 3.5. Diode clipper circuit netlist for transient analysis
4. Netlist Basics

Chapter Overview

This chapter contains introductory material on netlist syntax and usage. Sections include:

- Section 4.1 General Overview
- Section 4.2 Devices Available for Simulation
- Section 4.3 Parameters and Expressions
4.1 General Overview

4.1.1 Introduction

Using a netlist to describe a circuit for Xyce is the primary method for running a circuit simulation. Netlist support within Xyce largely conforms to that used by Berkeley SPICE 3F5 with several new options for controlling functionality unique to Xyce.

In a netlist, the circuit is described by a set of element lines defining circuit elements and their associated parameters, the circuit topology (i.e., the connection of the circuit elements), and a variety of control options for the simulation. The first line in the netlist file must be a title and the last line must be “.END”. Between these two constraints, the order of the statements is irrelevant.

4.1.2 Nodes

Nodes and elements form the foundation for the circuit topology. Each node represents a point in the circuit that is connected to the leads of multiple elements (devices). Each lead of every element is connected to a node, and each node is connected to multiple element leads.

A node is simply a named point in the circuit. The naming of normal nodes is only known within the level of circuit hierarchy where they appear; normal nodes defined in the main circuit are not visible to subcircuits, nor are nodes defined in a subcircuit visible to the top-level circuit. Nodes can be passed into subcircuits through an argument list, and in this case subcircuits are given limited access to nodes from the upper-level circuit.

Global Nodes

For cases where a particular node is used widely throughout various subcircuits it can be more convenient to use a global node, which is referenced by the same name throughout the circuit. This is often the case for power rails such as VDD or VSS.

Global nodes start with the prefix $G. Examples of global node names would be: $G.VDD or $G1. Nodes or global nodes require no declaration, as they are declared implicitly by appearing in element lines.

4.1.3 Elements

An element line defines each circuit element instance. While each element type determines the specific format, the general format is given by:

\[
\text{<type><name> <node information> <element information...>}
\]

The <type> must be a letter (A through Z) with the <name> immediately following. For example, RARESISTOR specifies a device of type “R” (for “Resistor”) with a name ARESISTOR. Nodes are
separated by spaces, and additional element information required by the device is given after the node list as described in the Netlist Reference section of the Xyce Reference Guide \[3\]. Xyce ignores character case when reading a netlist such that RARESISTOR is equivalent to rare resistor. The only exception to this case insensitivity occurs when including external files in a netlist where the filename specified in the netlist must have the same case as the actual filename.

A number field may be an integer or a floating-point value. Either one may be followed by one of the following scaling factors:

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Equivalent Value</th>
</tr>
</thead>
<tbody>
<tr>
<td>T</td>
<td>$10^{12}$</td>
</tr>
<tr>
<td>G</td>
<td>$10^9$</td>
</tr>
<tr>
<td>Meg</td>
<td>$10^6$</td>
</tr>
<tr>
<td>K</td>
<td>$10^3$</td>
</tr>
<tr>
<td>mil</td>
<td>$25.4 \times 10^{-6}$</td>
</tr>
<tr>
<td>m</td>
<td>$10^{-3}$</td>
</tr>
<tr>
<td>u ($\mu$)</td>
<td>$10^{-6}$</td>
</tr>
<tr>
<td>n</td>
<td>$10^{-9}$</td>
</tr>
<tr>
<td>p</td>
<td>$10^{-12}$</td>
</tr>
<tr>
<td>f</td>
<td>$10^{-15}$</td>
</tr>
</tbody>
</table>

Node information is given in terms of node names, which are arbitrary character strings. The only requirement is that the ground node is named '0'. There is one restriction on the circuit topology: there can be no loop of voltage sources and/or inductors. In addition to this requirement, the following additional topology constraints are highly recommended:

- Every node has a DC path to ground.
- Every node has at least two connections (with the exception of unterminated transmission lines and MOSFET substrate nodes).

While Xyce can theoretically handle netlists that violate the above two constraints, such topologies are typically the result of human error in creating a netlist file, and will often lead to convergence failures. Chapter 14 provides more information on this topic.

The following line provides an example of an element line that defines a resistor between nodes 1 and 3 with a resistance value of 10 kΩ.

**Example:**

RARESISTOR 1 3 10K

42
Title, Comments and End

The first line of the netlist is the title line of the netlist. This line is treated as a comment even if it does not begin with an asterisk. It is a common mistake to forget the meaning of this first line and begin the circuit elements on the first line; doing so will probably result in a parsing error.

Example: Test RLC Circuit

The ".END" line must be the last line in the netlist.

Example: .END

Comments are supported in netlists and are indicated by placing an asterisk at the beginning of the comment line. They may occur anywhere in the netlist but they must be at the beginning of a line. Xyce also supports in-line comments. An in-line comment is designated by a semicolon and may occur on any line. Xyce ignores everything after a semicolon. Xyce also considers lines beginning with a leading white space as comments.

Example: * This is a netlist comment.

Example: WRONG:.DC .... * This type of in-line comment is not supported.

Example: .DC .... ; This type of in-line comment is supported.

Continuation Lines

Continuation lines begin with a + symbol, and their contents are appended to those of the previous line. If the previous line or lines were comments, the continuation line is appended to the first noncomment line preceding it.

Netlist Commands

Command elements are used to describe the analysis being defined by the netlist. Examples include analysis types, initial conditions, device models, and output control. The Xyce Reference Guide [3] contains a reference for these commands.

Example: .PRINT TRAN V(Vout)

Analog Devices

Xyce-supported analog devices include most of the standard circuit components normally found in circuit simulators, such as SPICE 3F5, PSpice, etc., plus several Sandia-specific devices.

4.2 Devices Available for Simulation

This section describes the different types of Xyce-supported analog devices, such as standard analog devices, sources (dependent and independent), and subcircuits. Each device description contains the following information:

- A description and an example of the netlist syntax.
- Corresponding model types and descriptions, where applicable
- Corresponding lists of model parameters and descriptions, where applicable
- Associated schematic symbol and model equations, as necessary.

These analog devices include all of the standard circuit components needed for most analog circuits. User-defined models may also be implemented using the .MODEL (model definition) statement and macromodels as subcircuits using the .SUBCKT (subcircuit) statement.

4.2.1 Analog Devices

Xyce supports many analog devices, including sources, subcircuits, and behavioral models. The devices are classified into device types, each of which can have one or more model types. For example, the BJT device type has two model types: NPN and PNP.

The device element statements in the netlist always start with the name of the individual device instance. The first letter of the name determines the device type. The format of the subsequent information depends on the device type and its parameters. Table 4.1 provides a quick reference to the analog devices and the form of their netlist formats supported by Xyce. Except where noted, the devices are based upon those found in [6]. The Xyce Reference Guide [3] provides a more complete description of the syntax for supported devices.

Table 4.1: Analog Device Quick Reference.

<table>
<thead>
<tr>
<th>Device Type</th>
<th>Designator Letter</th>
<th>Typical Netlist Format</th>
</tr>
</thead>
<tbody>
<tr>
<td>Nonlinear Dependent Source</td>
<td>B</td>
<td>B&lt;name&gt; &lt;+ node&gt; &lt;+ node&gt; + &lt;I or V&gt;=&lt;expression&gt;</td>
</tr>
<tr>
<td>Capacitor</td>
<td>C</td>
<td>C&lt;name&gt; &lt;+ node&gt; &lt;+ node&gt; [model name] &lt;value&gt; + [IC=&lt;initial value&gt;]</td>
</tr>
<tr>
<td>Diode</td>
<td>D</td>
<td>D&lt;name&gt; &lt;anode node&gt; &lt;cathode node&gt; + &lt;model name&gt; [area value]</td>
</tr>
<tr>
<td>Device Type</td>
<td>Designator Letter</td>
<td>Typical Netlist Format</td>
</tr>
<tr>
<td>-----------------------------------</td>
<td>-------------------</td>
<td>----------------------------------------------------------------------------------------</td>
</tr>
<tr>
<td>Voltage Controlled Voltage Source</td>
<td>E</td>
<td>E&lt;name&gt; &lt;+ node&gt; &lt;+ node&gt; &lt;+ controlling node&gt;</td>
</tr>
<tr>
<td></td>
<td></td>
<td>+ &lt;+ controlling node&gt; &lt;gain&gt;</td>
</tr>
<tr>
<td>Current Controlled Current Source</td>
<td>F</td>
<td>F&lt;name&gt; &lt;+ node&gt; &lt;+ node&gt;</td>
</tr>
<tr>
<td></td>
<td></td>
<td>+ &lt;+ controlling V device name&gt; &lt;gain&gt;</td>
</tr>
<tr>
<td>Voltage Controlled Current Source</td>
<td>G</td>
<td>G&lt;name&gt; &lt;+ node&gt; &lt;+ node&gt; &lt;+ controlling node&gt;</td>
</tr>
<tr>
<td></td>
<td></td>
<td>+ &lt;+ controlling node&gt; &lt;transconductance&gt;</td>
</tr>
<tr>
<td>Current Controlled Voltage Source</td>
<td>H</td>
<td>H&lt;name&gt; &lt;+ node&gt; &lt;+ node&gt;</td>
</tr>
<tr>
<td></td>
<td></td>
<td>+ &lt;+ controlling V device name&gt; &lt;gain&gt;</td>
</tr>
<tr>
<td>Independent Current Source</td>
<td>I</td>
<td>I&lt;name&gt; &lt;+ node&gt; &lt;+ node&gt; [DC &lt;value&gt;]</td>
</tr>
<tr>
<td></td>
<td></td>
<td>+ [AC [magnitude value [phase value] ] ]</td>
</tr>
<tr>
<td></td>
<td></td>
<td>+ [transient specification]</td>
</tr>
<tr>
<td>Mutual Inductor</td>
<td>K</td>
<td>K&lt;name&gt; &lt;inductor l&gt; [&lt;ind. n&gt;*]</td>
</tr>
<tr>
<td></td>
<td></td>
<td>+ &lt;linear coupling or model&gt;</td>
</tr>
<tr>
<td>Inductor</td>
<td>L</td>
<td>L&lt;name&gt; &lt;+ node&gt; &lt;+ node&gt; [model name] &lt;value&gt;</td>
</tr>
<tr>
<td></td>
<td></td>
<td>+ [IC=&lt;initial value&gt;]</td>
</tr>
<tr>
<td>JFET</td>
<td>J</td>
<td>J&lt;name&gt; &lt;drain node&gt; &lt;gate node&gt; &lt;source node&gt;</td>
</tr>
<tr>
<td></td>
<td></td>
<td>+ &lt;model name&gt; [area value]</td>
</tr>
<tr>
<td>MOSFET</td>
<td>M</td>
<td>M&lt;name&gt; &lt;drain node&gt; &lt;gate node&gt; &lt;source node&gt;</td>
</tr>
<tr>
<td></td>
<td></td>
<td>+ &lt;bulk/substrate node&gt; [SOI node(s)]</td>
</tr>
<tr>
<td></td>
<td></td>
<td>+ &lt;model name&gt; [common model parameter]*</td>
</tr>
<tr>
<td>Lossy Transmission Line (LTRA)</td>
<td>O</td>
<td>O&lt;name&gt; &lt;A port (+) node&gt; &lt;A port (-) node&gt;</td>
</tr>
<tr>
<td></td>
<td></td>
<td>+ &lt;B port (+) node&gt; &lt;B port (-) node&gt;</td>
</tr>
<tr>
<td></td>
<td></td>
<td>+ &lt;model name&gt;</td>
</tr>
<tr>
<td>Bipolar Junction Transistor (BJT)</td>
<td>Q</td>
<td>Q&lt;name&gt; &lt;collector node&gt; &lt;base node&gt;</td>
</tr>
<tr>
<td></td>
<td></td>
<td>+ &lt;emitter node&gt; [substrate node]</td>
</tr>
<tr>
<td></td>
<td></td>
<td>+ &lt;model name&gt; [area value]</td>
</tr>
<tr>
<td>Resistor</td>
<td>R</td>
<td>R&lt;name&gt; &lt;+ node&gt; &lt;+ node&gt; [model name] &lt;value&gt;</td>
</tr>
<tr>
<td></td>
<td></td>
<td>+ [L=&lt;length&gt;] [W=&lt;width&gt;]</td>
</tr>
<tr>
<td>Voltage Controlled Switch</td>
<td>S</td>
<td>S&lt;name&gt; &lt;+ switch node&gt; &lt;+ switch node&gt;</td>
</tr>
<tr>
<td></td>
<td></td>
<td>+ &lt;+ controlling node&gt; &lt;+ controlling node&gt;</td>
</tr>
<tr>
<td></td>
<td></td>
<td>+ &lt;model name&gt;</td>
</tr>
<tr>
<td>Transmission Line</td>
<td>T</td>
<td>T&lt;name&gt; &lt;A port + node&gt; &lt;A port - node&gt;</td>
</tr>
<tr>
<td></td>
<td></td>
<td>+ &lt;B port + node&gt; &lt;B port - node&gt;</td>
</tr>
<tr>
<td></td>
<td></td>
<td>+ &lt;ideal specification&gt;</td>
</tr>
<tr>
<td>Independent Voltage Source</td>
<td>V</td>
<td>V&lt;name&gt; &lt;+ node&gt; &lt;+ node&gt; [DC &lt;value&gt;]</td>
</tr>
<tr>
<td></td>
<td></td>
<td>+ [AC [magnitude value [phase value] ] ]</td>
</tr>
<tr>
<td></td>
<td></td>
<td>+ [transient specification]</td>
</tr>
<tr>
<td>Subcircuit</td>
<td>X</td>
<td>X&lt;name&gt; [node]* &lt;subcircuit name&gt;</td>
</tr>
<tr>
<td></td>
<td></td>
<td>+ [PARAMS: [&lt;name&gt;=&lt;value&gt;]*]</td>
</tr>
<tr>
<td>Current Controlled Switch</td>
<td>W</td>
<td>W&lt;name&gt; &lt;+ switch node&gt; &lt;+ switch node&gt;</td>
</tr>
<tr>
<td></td>
<td></td>
<td>+ &lt;+ controlling V device name&gt; &lt;model name&gt;</td>
</tr>
</tbody>
</table>
Table 4.1: Analog Device Quick Reference.

<table>
<thead>
<tr>
<th>Device Type</th>
<th>Designator Letter</th>
<th>Typical Netlist Format</th>
</tr>
</thead>
<tbody>
<tr>
<td>Digital Devices</td>
<td>Y&lt;name&gt;</td>
<td>Y&lt;name&gt; [node]* &lt;model name&gt;</td>
</tr>
<tr>
<td>PDE Devices</td>
<td>YPDE</td>
<td>YPDE &lt;name&gt; [node]* &lt;model name&gt;</td>
</tr>
<tr>
<td>ROM Devices</td>
<td>YROM</td>
<td>YROM &lt;name&gt; &lt;+ node&gt; &lt;= node</td>
</tr>
<tr>
<td></td>
<td></td>
<td>+ BASE_FILENAME=&lt;filename&gt;</td>
</tr>
<tr>
<td></td>
<td></td>
<td>+ [MASK_VARS=&lt;true/false&gt;]</td>
</tr>
<tr>
<td></td>
<td></td>
<td>+ [USE_PORT_DESCRIPTION=&lt;0/1&gt;]</td>
</tr>
<tr>
<td>Accelerated masses</td>
<td>YACC</td>
<td>YACC &lt;name&gt; &lt;acceleration&gt; &lt;velocity&gt; &lt;position&gt;</td>
</tr>
<tr>
<td></td>
<td></td>
<td>+[x0=&lt;initial position&gt;] [v0=&lt;initial velocity&gt;]</td>
</tr>
<tr>
<td>MESFET</td>
<td>Z</td>
<td>Z&lt;name&gt; &lt;drain node&gt; &lt;gate node&gt; &lt;source node&gt;</td>
</tr>
<tr>
<td></td>
<td></td>
<td>+ &lt;model name&gt; [area value]</td>
</tr>
</tbody>
</table>

4.3 Parameters and Expressions

In addition to explicit values, the user may use parameters and expressions to symbolize numeric values in the circuit design.

4.3.1 Parameters

A parameter is a symbolic name representing a numeric value. Parameters must start with a letter or underscore. The characters after the first can be letter, underscore, or digits. Once a parameter is defined (by having its name declared and having a value assigned to it) at a particular level in the circuit hierarchy, it can be used to represent circuit values at that level or any level directly beneath it in the circuit hierarchy. One way to use parameters is to apply the same value to multiple part instances.

4.3.2 How to Declare and Use Parameters

For using a parameter in a circuit, one must:

- Define the parameter using a .PARAM statement within a netlist
- Replace an explicit value with the parameter in the circuit

Xyce reserving the following keywords that may not be used as parameter names:

- Time
Though \( V_t \) and \( GMIN \) are reserved and may not be used as parameter names, neither is actually defined and usable in \textit{Xyce} at this time. Both \textit{Time} and \textit{TEMP} are defined and may be used in time- or temperature-dependent expressions, where such expressions are permitted.

**Example: Declaring a parameter**

1. Locate the level in the circuit hierarchy at which the \texttt{.PARAM} statement declaring a parameter will be placed. To declare a parameter capable of being used anywhere in the netlist, place the \texttt{.PARAM} statement at the top-most level of the circuit.

2. Name the parameter and give it a value. The value can be numeric or given by an expression:

   \[
   \texttt{.SUBCKT subckt1 n1 n2 n3} \\
   \texttt{.PARAM res = 100} \\
   \texttt{*} \\
   \texttt{* other netlist statements here} \\
   \texttt{*} \\
   \texttt{.ENDS}
   \]

   3. \texttt{NOTE:} The parameter \texttt{res} can be used anywhere within the subcircuit \texttt{subckt1}, including subcircuits defined within it, but cannot be used outside of \texttt{subckt1}.

**Example: Using a parameter in the circuit**

1. Locate the numeric value (a device instance parameter value, model parameter value, etc.) that is to be replaced by a parameter.

2. Replace the numeric value with the parameter name contained within braces (\{\}) as in:

   \[
   \texttt{R1 1 2 \{res\}}
   \]

   \texttt{NOTE:} Ensure the value being replaced remains accessible within the current hierarchy level.

**Limitations on parameter definitions**

As chapter 6 describes, there is considerable flexibility in the use of parameters. They can be set to expressions containing other parameters, and can be passed down the hierarchy into subcircuits. Fundamentally, however, parameters are constants evaluated at the beginning of a run; therefore, all terms in the expression defining the parameter must be constants known at the beginning of the run. It is not legal to use time-dependent expressions in parameter declarations (either by including voltage nodes or currents, or by including reference to the variable \texttt{TIME}).
Parameters defined within a given scope can be used in any expression within that scope. The only limitation on ordering is for the use of a parameter in an expression that defines the value of another parameter. In that case, all parameters used in the expression must be defined before being used to define another parameter. So, in the following example:

```
R1 1 0 {B+C} ; OK because the expression is not used to define a param
.PARAM A=3
.PARAM B={A+1} ; OK because A is defined above
.PARAM D={C+2} ; Illegal because C is not yet known
.PARAM C=2
```

### 4.3.3 Global Parameters

A normal parameter defined at the main circuit level will have global scope. Such parameters suffer from limitations, such as: (1) they are constant during the simulation, and (2) the parameter may be redefined within a subcircuit, which would change the value in the subcircuit and below. Global parameters address these limitations.

A global parameter differs from a normal parameter in that it can only be defined at the main circuit level, and it is allowed to change during a simulation. Global parameters act as variables rather than constants during the simulation. Examples of some global parameter usages are:

```
.param dTdt=100
.global_param T={27+dTdt*time}
R1 1 2 RMOD TEMP={T}
```

or

```
.global_param T=27
R1 1 2 RMOD TEMP={T}
C1 1 2 CMOD TEMP={T}
.step T 20 50 10
```

In these examples, T is used to represent an environmental variable that changes.

**NOTE:** Normal parameters may be used in expressions defining global parameters, but the opposite is not allowed.

### 4.3.4 Expressions

In **Xyce**, an expression is a mathematical relationship that may be used any place one would use a number (numeric or boolean). Except in the case of expressions used in analog behavioral modeling sources (see chapter[5] **Xyce** evaluates the expression to a value when it reads in the circuit netlist, not each time its value is needed. Therefore, all terms in an expression must be known at the beginning of a run.
To use an expression in a circuit netlist:

1. Locate the value to be replaced (component, model parameter, etc.).

2. Substitute the value with an expression using the \{\} syntax:

   \{ expression \}

   where \textit{expression} can contain any of the following:

   - Available operators (table \[4.2\])
   - Included functions (tables \[4.3\], \[4.5\] and \[4.6\])
   - User-defined functions
   - User-defined parameters within scope
   - Literal operands.

The braces (\{\}) instruct \textit{Xyce} to evaluate the expression and use the resulting value. Additional time-dependent constructs are available in expressions used in analog behavioral modeling sources (see chapter \[6\]).

**Example: Using an expression**

Scaling the DC voltage of a 12\text{V} independent voltage source, designated \textit{VF}, by some factor can be accomplished by the following netlist statements (in this example the factor is 1.5):

\begin{verbatim}
  .PARAM FACTORV=1.5
  VF 3 4 \{FACTORV*12\}
\end{verbatim}

\textit{Xyce} will evaluate the expression to 12 \times 1.5 or 18 volts.

---

\(^1\)Logical and relational operators are used only with the \textit{IF()} function.
**Table 4.2.** Expression operators

<table>
<thead>
<tr>
<th>Class of operator</th>
<th>Operator</th>
<th>Meaning</th>
</tr>
</thead>
<tbody>
<tr>
<td>arithmetic</td>
<td>+</td>
<td>addition or string concatenation</td>
</tr>
<tr>
<td></td>
<td>-</td>
<td>subtraction</td>
</tr>
<tr>
<td></td>
<td>*</td>
<td>multiplication</td>
</tr>
<tr>
<td></td>
<td>/</td>
<td>division</td>
</tr>
<tr>
<td></td>
<td>**</td>
<td>exponentiation</td>
</tr>
<tr>
<td>logical¹</td>
<td>~</td>
<td>unary NOT</td>
</tr>
<tr>
<td></td>
<td></td>
<td>¹ A note on logical operators: For many languages, the logical operators `</td>
</tr>
<tr>
<td></td>
<td></td>
<td>¹ Logical operators are used in boolean expressions. They are more commonly used than relational operators.</td>
</tr>
<tr>
<td>relational</td>
<td>==</td>
<td>equality</td>
</tr>
<tr>
<td></td>
<td>!=</td>
<td>non-equality</td>
</tr>
<tr>
<td></td>
<td>&gt;</td>
<td>greater-than</td>
</tr>
<tr>
<td></td>
<td>&gt;=</td>
<td>greater-than or equal</td>
</tr>
<tr>
<td></td>
<td>&lt;</td>
<td>less-than</td>
</tr>
<tr>
<td></td>
<td>&lt;=</td>
<td>less-than or equal</td>
</tr>
</tbody>
</table>
Table 4.3. Arithmetic functions in expressions

<table>
<thead>
<tr>
<th>Function</th>
<th>Meaning</th>
<th>Explanation</th>
</tr>
</thead>
<tbody>
<tr>
<td>ABS(x)</td>
<td>$</td>
<td>x</td>
</tr>
<tr>
<td>DDT(x)</td>
<td>$\frac{d}{dt}x(t)$</td>
<td>time derivative of $x$</td>
</tr>
<tr>
<td>DDX(f(x),x)</td>
<td>$\frac{\partial}{\partial x}f(x)$</td>
<td>partial derivative of $f(x)$ with respect to $x$</td>
</tr>
<tr>
<td>IF(t,x,y)</td>
<td>$x$ if $t$ is true,</td>
<td>$t$ is an expression using the relational operators in Table 4.2</td>
</tr>
<tr>
<td></td>
<td>$y$ otherwise</td>
<td></td>
</tr>
<tr>
<td>INT(x)</td>
<td>$\text{sgn}(x)[</td>
<td>x</td>
</tr>
<tr>
<td>LIMIT(x,y,z)</td>
<td>$y$ if $x &lt; y$</td>
<td></td>
</tr>
<tr>
<td></td>
<td>$x$ if $y &lt; x &lt; z$</td>
<td>$x$ limited to range $y$ to $z$</td>
</tr>
<tr>
<td></td>
<td>$z$ if $x &gt; z$</td>
<td></td>
</tr>
<tr>
<td>M(x)</td>
<td>$</td>
<td>x</td>
</tr>
<tr>
<td>MIN(x,y)</td>
<td>$\min(x,y)$</td>
<td>minimum of $x$ and $y$</td>
</tr>
<tr>
<td>MAX(x,y)</td>
<td>$\max(x,y)$</td>
<td>maximum of $x$ and $y$</td>
</tr>
<tr>
<td>PWR(x,y)</td>
<td>$x^y$</td>
<td>$x$ raised to $y$ power</td>
</tr>
<tr>
<td>POW(x,y)</td>
<td>$x^y$</td>
<td>$x$ raised to $y$ power</td>
</tr>
<tr>
<td>PWRS(x,y)</td>
<td>$x^y$ if $x &gt; 0$</td>
<td></td>
</tr>
<tr>
<td></td>
<td>$0$ if $x = 0$</td>
<td>sign corrected $x$ raised to $y$ power</td>
</tr>
<tr>
<td></td>
<td>$-(-x)^y$ if $x &lt; 0$</td>
<td></td>
</tr>
</tbody>
</table>
Table 4.4. Arithmetic functions in expressions (cont’d)

<table>
<thead>
<tr>
<th>Function</th>
<th>Meaning</th>
<th>Explanation</th>
</tr>
</thead>
<tbody>
<tr>
<td>RAND()</td>
<td>$0 &lt; \text{result} &lt; 1$</td>
<td>random constant number between 0 and 1</td>
</tr>
<tr>
<td>SDT(x)</td>
<td>$\int x(t)dt$</td>
<td>time integral of $x$</td>
</tr>
<tr>
<td>SGN(x)</td>
<td>+1 if $x &gt; 0$</td>
<td>sign value of $x$</td>
</tr>
<tr>
<td></td>
<td>0 if $x = 0$</td>
<td></td>
</tr>
<tr>
<td></td>
<td>-1 if $x &lt; 0$</td>
<td></td>
</tr>
<tr>
<td>SIGN(x,y)</td>
<td>$\text{sgn}(y)</td>
<td>x</td>
</tr>
<tr>
<td>STP(x)</td>
<td>1 if $x &gt; 0$</td>
<td>step function</td>
</tr>
<tr>
<td></td>
<td>0 otherwise</td>
<td></td>
</tr>
<tr>
<td>SQRT(x)</td>
<td>$\sqrt{x}$</td>
<td>square root of $x$</td>
</tr>
<tr>
<td>TABLE(x,y,z,*)</td>
<td>$f(x)$ where $f(y) = z$</td>
<td>piecewise linear interpolation, multiple $(y,z)$ pairs can be specified</td>
</tr>
<tr>
<td>URAMP(x)</td>
<td>$x$ if $x &gt; 0$</td>
<td>ramp function</td>
</tr>
<tr>
<td></td>
<td>0 otherwise</td>
<td></td>
</tr>
<tr>
<td>Function</td>
<td>Meaning</td>
<td>Explanation</td>
</tr>
<tr>
<td>----------</td>
<td>---------</td>
<td>-------------</td>
</tr>
<tr>
<td>ACOS(x)</td>
<td>arccos(x)</td>
<td>result in radians</td>
</tr>
<tr>
<td>ACOSH(x)</td>
<td>$\cosh^{-1}(x)$</td>
<td>hyperbolic arccosine of $x$</td>
</tr>
<tr>
<td>ARCTAN(x)</td>
<td>arctan(x)</td>
<td>result in radians</td>
</tr>
<tr>
<td>ASIN(x)</td>
<td>arcsin(x)</td>
<td>result in radians</td>
</tr>
<tr>
<td>ASINH(x)</td>
<td>$\sinh^{-1}(x)$</td>
<td>hyperbolic arcsine of $x$</td>
</tr>
<tr>
<td>ATAN(x)</td>
<td>arctan(x)</td>
<td>result in radians</td>
</tr>
<tr>
<td>ATANH(x)</td>
<td>$\tanh^{-1}(x)$</td>
<td>hyperbolic arctangent of $x$</td>
</tr>
<tr>
<td>ATAN2(x,y)</td>
<td>arctan(x/y)</td>
<td>result in radians</td>
</tr>
<tr>
<td>COS(x)</td>
<td>cos(x)</td>
<td>$x$ in radians</td>
</tr>
<tr>
<td>COSH(x)</td>
<td>cosh(x)</td>
<td>hyperbolic cosine of $x$</td>
</tr>
<tr>
<td>EXP(x)</td>
<td>$e^x$</td>
<td>$e$ to the $x$ power</td>
</tr>
<tr>
<td>LN(x)</td>
<td>ln(x)</td>
<td>log base $e$</td>
</tr>
<tr>
<td>LOG(x)</td>
<td>log(x)</td>
<td>log base 10</td>
</tr>
<tr>
<td>LOG10(x)</td>
<td>log(x)</td>
<td>log base 10</td>
</tr>
<tr>
<td>SIN(x)</td>
<td>sin(x)</td>
<td>$x$ in radians</td>
</tr>
<tr>
<td>SINH(x)</td>
<td>sinh(x)</td>
<td>hyperbolic sine of $x$</td>
</tr>
<tr>
<td>TAN(x)</td>
<td>tan(x)</td>
<td>$x$ in radians</td>
</tr>
<tr>
<td>TANH(x)</td>
<td>tanh(x)</td>
<td>hyperbolic tangent of $x$</td>
</tr>
<tr>
<td>Function</td>
<td>Explanation</td>
<td></td>
</tr>
<tr>
<td>----------</td>
<td>-------------</td>
<td></td>
</tr>
</tbody>
</table>
| SPICE.EXP(V1, V2, TD1, TAU1, TD2, TAU2) | SPICE style transient exponential  
V1 = initial value  
V2 = pulsed value  
TD1 = rise delay time  
TAU1 = rise time constant  
TD2 = fall delay time  
TAU2 = fall time constant |
| SPICE.PULSE(V1, V2, TD, TR, TF, PW, PER) | SPICE style transient pulse  
V1 = initial value  
V2 = pulsed value  
TD = delay  
TR = rise time  
TF = fall time  
PW = pulse width  
PER = period |
| SPICE.SFFM(V0, VA, FC, MDI, FS) | SPICE style transient single frequency FM  
V0 = offset  
VA = amplitude  
FC = carrier frequency  
MDI = modulation index  
FS = signal frequency |
| SPICE.SIN(V0, VA, FREQ, TD, THETA) | SPICE style transient sine wave  
V0 = offset  
VA = amplitude  
FREQ = frequency (Hz)  
TD = delay  
THETA = damping factor |
Chapter Overview

This chapter provides model ideas and summarizes ways to create and modify models. Sections include:

- Section 5.1 Model Definition
- Section 5.2 Subcircuit Creation
- Section 5.3 Model Organization
- Section 5.4 Model Interpolation
5.1 Model Definitions

A model describes the electrical performance of a part, such as a specific vendor’s version of a 2N2222 transistor. To simulate a part requires specification of simulation properties. These properties define the model of the part.

Depending on the given device type and the requirements of the circuit design, a model is specified using a model parameter set, a subcircuit netlist, or both.

In general, model parameter sets define the parameters used in ideal models of specific device types, while subcircuit netlists allow the user to combine ideal device models to simulate more complex effects. For example, one could simulate a bipolar transistor using the Xyce BJT device by specifying model parameters extracted to fit the simulation behavior to the behavior of the part used. One could also develop a subcircuit macro-model of a capacitor that adds effects such as lead inductance and resistance to the basic capacitor device.

Both methods of defining a model use a netlist format, with precise syntax rules. In this section we give an overview of how to define model parameter sets in Xyce. A subsequent section will provide a similar overview of how to define subcircuit models. For full details, consult the Reference Guide [3].

Defining models using model parameters

Although Xyce has no built-in part models, models can be defined for a device by changing some or all of the model parameters from their defaults via the .MODEL statement. For example:

```
M5 3 2 1 0 MLOAD1
.MODEL MLOAD1 NMOS (LEVEL=3 VTO=0.5 CJ=0.025pF)
```

This example defines a MOSFET device M5 that is an instance of a part described by the model parameter set MLOAD1. The MLOAD1 parameter set is defined in the .MODEL statement.

Most device types in Xyce support some form of model parameters. Consult the Xyce Reference Guide [3] for the model parameters supported by each device type.

Defining models using subcircuit netlists

In Xyce, models may also be defined using the .SUBCKT/.ENDS subcircuit syntax. This syntax allows the creation of Netlists, which define the configuration and function of the part, and the use of Variable input parameters, which can be used to create device-specific implementations of the model. The .SUBCKT syntax, and an example of how to use .SUBCKT to implement a model, are given in Section 5.2.
5.2 Subcircuit Creation

A subcircuit can be created within Xyce using the `.SUBCKT` keyword. The `.ENDS` keyword is used to mark the end of the subcircuit. All the lines between the two keywords are considered to be part of the subcircuit. Figure 5.1 provides an example of how a subcircuit is defined and used.

```plaintext
****other devices
X5 5 6 7 8 l3dsc1 PARAMS: ScaleFac=2.0
X6 9 10 11 12 l3dsc1
****more netlist commands

*** SUBCIRCUIT: l3dsc1
*** Parasitic Model: microstrip
*** Only one segment
.SUBCKT l3dsc1 1 3 2 4 PARAMS: ScaleFac=1.0
C01 1 0 4.540e-12
RG01 1 0 7.816e+03
L1 1 5 3.718e-08
R1 5 2 4.300e-01
C1 2 0 4.540e-12
RG1 2 0 7.816e+03
C02 3 0 4.540e-12
RG02 3 0 7.816e+03
L2 3 6 3.668e-08
R2 6 4 4.184e-01
C2 4 0 4.540e-12
RG2 4 0 7.816e+03
CM012 1 3 5.288e-13
KM12 L1 L2 2.229e-01
CM12 2 4 {5.288e-13*ScaleFac}
.ENDS
```

**Figure 5.1.** Example subcircuit model.

In this example, a subcircuit model named l3dsc1, which implements one part of a microstrip transmission line, is defined between the `.SUBCKT/.ENDS` lines; and two different instances of the subcircuit are used in the `X` lines. This somewhat artificial example shows how input parameters are used, where the last capacitor in the subcircuit is scaled by the input parameter `ScaleFac`. If input parameters are not specified on the `X` line (as in the case of device `X6`), then the default values specified on the `.SUBCKT` line are used. Non-default values are specified on the `X` line using the `PARAMS:` keyword. Consult the Xyce Reference Guide [3] for precise syntax.

In addition to devices, a subcircuit may contain definitions, such as models via the `.MODEL` statement, parameters via the `.PARAM` statement, and functions via the `.FUNC` statement. Xyce also
supports the definition of one or more subcircuits within another subcircuit. Subcircuits can be
nested to an arbitrary extent, where one subcircuit can contain another subcircuit, which can con-
tain yet another subcircuit, and so on.

The creation of nested subcircuits requires an understanding of “scope,” such that each subcircuit
defines the scope for the definitions it contains. That is, the definitions contained within a subcircuit
can be used within that subcircuit and within any subcircuit it contains, but not at any higher level.
Definitions occurring in the main circuit have global scope and can be used anywhere in the circuit.
A name, such as a model, parameter, function, or subcircuit name, occurring in a definition at one
level of a circuit hierarchy can be redefined at any lower level contained directly by the subcircuit.
In this case, the new definition applies at the given level and those below.

The idea of “scope” is best provided by an example. In the netlist provided in Figure 5.2, the
model named MOD1 can be used in subcircuits SUB1 and SUB2, but not in the subcircuit SUB3. The
parameter P1 has a value of 10 in subcircuit SUB1 and a value of 20 in subcircuit SUB2. In subcircuit
SUB3, P1 has no meaning.

```plaintext
.SUBCKT SUB1 1 2 3 4
.MODEL MOD1 NMOS(LEVEL=2)
.PARAM P1=10
  *
  * subcircuit devices omitted for brevity
  *
.SUBCKT SUB2 1 3 2 4
.PARAM P1=20
  *
  * subcircuit devices omitted for brevity
  *
. ENDS
. ENDS

 SUBCKT SUB3 1 2 3 4
  *
  * subcircuit devices omitted for brevity
  *
. ENDS
```

Figure 5.2. Example subcircuit heirarchy.
5.3 Model Organization

While it is always possible to make a self-contained netlist in which all models for all parts are included along with the circuit definition, *Xyce* provides a simple mechanism to conveniently organize frequently used models into separate model libraries. Models are simply collected into model library files, and then accessed by netlists as needed by inserting an `.INCLUDE` directive. This section describes the process in detail.

5.3.1 Model Libraries

Device model and subcircuit definitions may be organized into model libraries as text files (similar to netlist files) with one or more model definitions. Many users choose to name model library files ending with `.lib`, but they may be named using any convention.

In general, most users create model libraries files that include similar model types. In these files, the *header comments* describe the models therein.

5.3.2 Model Library Configuration using `.INCLUDE`

*Xyce* uses model libraries by inserting an `.INCLUDE` statement into a netlist. Once a file is included, its contents become available to the netlist just as if the entire contents had been inserted directly into the netlist.

As an example, one might create the following model library file called `bjtmodels.lib`, containing `.MODEL` statements for common types of bipolar junction transistors:

```plaintext
*bjtmodels.lib
* Bipolar transistor models
.MODEL Q2N2222 NPN (Is=14.34f Xti=3 Eg=1.11 Vaf=74.03 Bf=5 Ne=1.307
+ Ise=14.34f Ikf=.2847 Xtb=1.5 Br=6.092 Nc=2 Isc=0 Ikr=0 Rc=1
+ Cjc=7.306p Mjc=.3416 Vjc=.75 Fc=.5 Cje=22.01p Mje=.377 Vje=.75
+ Tr=46.91n Tf=411.1p Itf=.6 Vtf=1.7 Xtf=3 Rb=10)

.MODEL 2N3700 NPN (IS=17.2E-15 BF=100)

.MODEL 2N2907A PNP (IS=1.E-12 BF=100)
```

The models Q2N2222, 2N3700 and 2N2907A could then be used in a netlist by including the `bjtmodels.lib` file.

```plaintext
.INCLUDE "bjtmodels.lib"
Q1 1 2 3 Q2N2222
Q2 5 6 7 2N3700
```
Because the contents of an included file are simply inserted into the netlist at the point where the 
.INCLUDE statement appears, the scoping rules for .INCLUDE statements are the same as for other 
types of definitions as outlined in the preceding sections.

NOTE: The path to the library file is assumed to be relative to the execution directory, but absolute 
pathnames are permissible. The entire file name, including its “extension” must be specified. 
There is no assumed default extension.

5.3.3 Model Library Configuration using .LIB

An alternative technique for organizing model libraries employs the .LIB command. With .LIB, a 
library file can contain multiple versions of a model and specific versions may be selected at the 
top level using a keyword on the .LIB line.

There are two different uses for the .LIB command. In the main netlist, .LIB functions in a similar 
manner to .INCLUDE: it reads in a file. Inside that file, .LIB and .ENDL are used to specify blocks 
of model code that may be included independently of other parts of the same file.

As an example, if you had two different 2N2222 transistor models extracted at different TNOM 
values, you could define them in a model library inside .LIB/.ENDL pairs:

```
* transistors.lib file
.lib roomtemp
.MODEL Q2N2222 NPN (TNOM=27 Is=14.34f Xti=3 Eg=1.11 Vaf=74.03 Bf=5 Ne=1.307
  + Ise=14.34f Ikf=.2847 Xtb=1.5 Br=6.092 Nc=2 Isc=0 Ikr=0 Rc=1
  + Cjc=7.306p Mjc=.3416 Vjc=.75 Fc=.5 Cje=22.01p Mje=.377 Vje=.75
  + Tr=46.91n Tf=411.1p Itf=.6 Vtf=1.7 Xtf=3 Rb=10)
.endl
.lib hightemp
.MODEL Q2N2222 NPN (TNOM=55 [...parameters omitted for brevity...])
.endl
```

Note that both models are given identical names, but are enclosed within .LIB/.ENDL pairs with 
different names. When this file is used in a netlist, a specific model can be used by specifying it 
on the .LIB line in the main netlist:

```
*This netlist uses only the high temperature model from the library
.lib transistors.lib hightemp
Q1 collector base emitter Q2N2222
[...]```
The exact format and usage of the .LIB command is documented in the Xyce Reference Guide [3].

5.4 Model Interpolation

Traditionally, SPICE simulators handle thermal effects by coding temperature dependence of model parameters into each device. These expressions modify the nominal device parameters given in the .MODEL card when the ambient temperature is not equal to $TNOM$, the temperature at which parameters were extracted.

These temperature correction equations may be reasonable at temperatures close to $TNOM$, but Sandia users of Xyce have found them inadequate when simulations must be performed over a wide range of temperatures. To address this inadequacy, Xyce implements a model interpolation option that allows the user to specify multiple .MODEL cards, each extracted from real device measurements at a different $TNOM$. From these model cards, Xyce will interpolate parameters based on the ambient temperature using either linear or quadratic interpolation.

Interpolation of models is accessed through the model parameter TEMPMODEL in the models that support this capability. In the netlist, a base model is specified, and is followed by multiple models at other temperatures.

Interpolation of model cards in this fashion is currently implemented only in the BJT level 1, JFET, MESFET, and MOSFETS levels 1-6, 10, and 18.

The use of model interpolation is best shown by example:

```plaintext
Jtest 1a 2a 3 SA2108 TEMP= 40
*
.MODEL SA2108 PJF ( TEMPMODEL=QUADRATIC TNOM = 27
+ LEVEL=2 BETA= 0.003130 VTO = -1.9966 PB = 1.046
+ LAMBDA = 0.00401 DELTA = 0.578; THETA = 0;
+ IS = 1.393E-10 RS = 1e-3)
*
.MODEL SA2108 PJF ( TEMPMODEL=QUADRATIC TNOM = -55
+ LEVEL=2 BETA = 0.00365 VTO = -1.9360 PB = 0.304
+ LAMBDA = 0.00286 DELTA = 0.2540 THETA = 0.0
+ IS = 1.393E-10 RD = 0.0 RS = 1e-3)
*
.MODEL SA2108 PJF ( TEMPMODEL=QUADRATIC TNOM = 90
+ LEVEL=2 BETA = 0.002770 VTO = -2.0350 PB = 1.507
+ LAMBDA = 0.00528 DELTA = 0.630 THETA = 0.0
+ IS = 1.393E-10 RS = 5.66)
```

Note that the model names are all identical for the three .MODEL lines, and that they all specify TEMPMODEL=QUADRATIC, but with different $TNOM$. For parameters that appear in all three .MODEL lines, the value of the parameter will be interpolated using the TEMP= value in the
device line, which in this example is 40°C, in the first line. For parameters that are not interpolated, such as RD, it is not necessary to include these in the second and third .MODEL lines.

Currently, QUADRATIC and PWL (piecewise linear) are the only arguments for TEMP-MODEL. The quadratic method includes a limiting feature that prevents the parameter value from exceeding the range of values specified in the .MODEL lines. For example, the RS value in the example would take on negative values for most of the interval between -55 and 27, as the value at 90 is very high. This truncation is necessary as parameters can easily take on values (such as the negative resistance of RS in this example) that will cause a Xyce failure.

For certain parameters (currently only BJT parameters IS and ISE), interpolation is done not on the parameter itself, but on the the log of the parameter, which provides for excellent interpolation of these parameters that vary over many orders of magnitude, and with this type of temperature dependence.

The interpolation scheme used for model interpolation bases the interpolation on the difference between the ambient temperature and the TNOM value of the first model card in the netlist, which can sometimes lead to poorly conditioned interpolation. Thus it is often best that the first model card in the netlist be the one that has the “middle” TNOM, as in the example above. This assures that no matter where in the range of temperature values the ambient temperature lies, it is a minimal distance from the base point of the interpolation.
6. Analog Behavioral Modeling

Chapter Overview

This chapter describes analog behavioral modeling in Xyce. Sections include:

- Section 6.1 Overview of Analog Behavioral Modeling
- Section 6.2 Specifying ABM Devices
- Section 6.3 Guidance for ABM Use
6.1 Overview of Analog Behavioral Modeling

The analog behavioral modeling capability of Xyce provides for flexible descriptions of electronic components or subsystems in terms of a transfer function or lookup table. In other words, a mathematical relationship is used to model a circuit segment removing the need for component-by-component design information for those components or subsystems.

The $B$ device, or nonlinear dependent source, is the primary device used for analog behavioral modeling in Xyce. A $B$ device can serve as either a voltage or current source, and by using expressions dependent on voltages and currents elsewhere in the circuit the user can produce a wide range of behaviors.

6.2 specifying ABM Devices

ABM devices ($B$ devices) are specified in a netlist the same way as other devices. Customizing the operational behavior of the device is achieved by defining an ABM expression describing how inputs are transformed into outputs.

For example, the following pair of lines would provide exactly the same behavior as a 10K resistor between nodes 1 and 2, and is written to be a current source with current specified using Ohm’s law and the constant resistance value of 10K $\Omega$.

```
.PARAM Res1=10K
Blinearres 1 2 I={(V(2)-V(1))/Res1}
```

A nonlinear resistor could be specified similarly:

```
.PARAM R1=0.15
.PARAM R2=6
.PARAM E2 = \{2*E1\}
.PARAM delr = \{R1-R0\}
.PARAM k1 = \{1/E1**2\}
.PARAM r2 = \{R0+sqrt(2)*delr\}

.FUNC Rreg1(a,b,c,d) \{a +(b-a)*c/d\}
.Func Rreg2(a,b,c,d,f) \{a+sqrt(2-b*(2*c-d)**2)*f\}

Bnlr 4 2 V = \{I(Vmon) * IF( + V(101) < E1, Rreg1(R0,R1,V(101),E1), + IF( + V(101) < E2, Rreg2(R0,k1,E1,V(101),delr), R2 + )
```
In this example, Bnlr provides a voltage between nodes 4 and 2, determined using Ohm's law with a resistance that is a function of the voltage on node 101 and a number of parameters. These two examples demonstrate how the B source can be used either as a voltage source (by specifying V={expression}) or as a current source (with I={expression}).

NOTE: Unlike expressions used in parameters or function declarations, expressions in the nonlinear dependent source may contain voltages and currents from other parts of the circuit, or even explicit time-dependent functions. Xyce evaluates these expressions when current or voltage through the ABM source is needed. Expressions used in parameters or function declarations are evaluated only once, prior to the start of the circuit simulation.

### 6.2.1 Additional constructs for use in ABM expressions

ABM expressions follow the same rules as other expressions in a netlist, with the additional ability to specify signals (node voltages and voltage source currents) and explicitly time-dependent functions in the expression. In ABM expressions, refer to signals by name. Xyce recognizes the following constructs in ABM expressions:

- V(<node name>)
- V(<node name>,<node name>) (the voltage difference between the first and second nodes)
- I(<voltage source name>)
- The variable, TIME
- The constants, PI and EXP, which equal π and e, respectively.
- Lookup tables

In a hierarchical circuit (a circuit with possibly nested levels of subcircuits), voltage source names in an ABM expression must be the name of a voltage source in the same subcircuit as the ABM device, or in a subcircuit instantiated by that subcircuit. Similarly, node names in an ABM expression must be the node names of one or more devices in the same subcircuit as the ABM device, or in a subcircuit instantiated by that subcircuit.

### 6.2.2 Examples of Analog Behavioral Modeling

A variety of examples of legal usage of analog behavioral modeling is probably the most effective means of demonstrating what is allowed. The following netlist fragment shows the range of simple items allowed in ABM expressions:

* Current through B1 given as expression of voltage drop between
* nodes 2 and 3 plus current through voltage source Vr4mon
The range of items that can be used in the current and voltage parameters of a B (or E, F, G, or H) source is far greater than what is allowed for expressions in other contexts. In particular, the use of solution values ($V(*)$, $V(*,*)$, $I(V*)$) are prohibited in all other expressions because they lead to unstable behavior if used elsewhere beside ABM. Time-dependent expressions are allowed for some device parameters, but this feature should be used with caution, as the behavior of the non-ABM device cannot be guaranteed to be correct when its device parameters are not constant throughout the run.

In addition to these simple items, lookup tables provide a means of specifying a piecewise linear function in an expression. A table expression is specified with the keyword TABLE followed by an expression that is evaluated as the independent variable of the function, followed by a list of pairs of independent variable/dependent variable values. For example:

**Example:**

```
B1 1 0 V={TABLE \{time\} = (0, 0) (1, 2) (2, 4) (3, 6)}
```

An equivalent example uses the table function, which has a simpler syntax, but may be hard to read for long tables:

**Example:**

```
B1 1 0 V={TABLE(time, 0, 0, 1, 2, 4, 3, 6)}
```

The previous two examples will produce a voltage source whose voltage is a simple linear function of time. At $t = 0$ the voltage is 0 volts, at time $t = 1s$ the voltage is 2 volts, and at times in between the voltage is determined by linear interpolation. Similarly, the voltage will be 4 volts at $t = 2s$ and 6 volts at $t = 3s$ with linear interpolation at times in between the tabulated values.
It is also possible to create ABM sources from files of time-value pairs by providing the name of the file containing the pairs between quotation marks ("):

**Example:**  
Bfile 1 0 V="myfile"

The file provided must have one time-voltage pair per line, separated by spaces. Comma-separated files are not supported, and will not be parsed correctly. If the file “myfile” contains the following data:

0 0  
1 2  
2 4  
3 6

then the “Bfile” example above will be identical to either of the “B1” examples above. The quoted-file syntax is in fact converted internally to precisely the same TABLE format as the first B1 example, with an independent variable of TIME and the given time-value pairs inserted.\(^1\)

Finally, the independent variable of the table source does not have to be a simple expression:

**Example:**  
Bcomplicated 1 0 V=\{TABLE \{V(5)-V(3)/4+I(V6)*Res1\} = (0, 0) (1, 2) (2, 4) (3, 6)\}

### 6.2.3 Alternate behavioral modeling sources

In addition to the primary nonlinear dependent source, the B source, Xyce also supports the PSpice extensions to the standard Spice voltage- and current-controlled sources, the E, F, G, and H sources. Xyce provides these sources for PSpice compatibility, and converts them internally into equivalent B sources. The Xyce Reference Guide [3] netlist reference chapter provides the syntax of these compatibility devices.

### 6.3 Guidance for ABM Use

#### 6.3.1 ABM devices add equations to the system of equations used by the solver

As Xyce solves a complex nonlinear set of equations at each time step, it is important to remember this system of equations is solved iteratively to obtain a converged solution. Specifying an ABM

---

\(^1\)The use of a B source in this manner is similar to using the FILE option to the PWL voltage source as documented in the Reference Guide, but unlike the PWL source, the file-based table function does NOT support reading comma-separated files.
device in a Xyce netlist adds one or more equations to the nonlinear problem that Xyce must solve.

When the nonlinear solver has converged, the expression given in the ABM device will be satisfied to within a solver tolerance. However, during the course of the iterative solve, the unconverged values of nodal voltages and currents, which are often inputs and outputs of ABM devices, are not guaranteed to be solutions to the system of equations.

During this preconverged phase, solution variables are not guaranteed to have physically reasonable values. They could, for example, temporarily have the wrong sign. Only at the end of a successful nonlinear iterative solve are the solution variables consistent, legal values. This convergence behavior motivates the caveats on ABM usage given in the next subsection.

### 6.3.2 Expressions used in ABM devices must be valid for any possible input

While ABM devices look temptingly like calculators, it is potentially dangerous to use them as such. The previous subsection stated that during the nonlinear solution of each timestep equations, nodal voltages and currents are usually not solutions to the full set of equations, and often violate Kirchhoff's laws. Only at the end of the nonlinear solution are all the constraints on voltages and currents satisfied. This has some important consequences to the user of ABM devices.

All expressions involving nodal voltages and currents used in ABM devices should be valid for any possible value they might see — even those that appear to be physically meaningless and those that a knowledgeable user might never expect to see in the real circuit. This is particularly important when using square roots or exponentiating to a fractional power. For example, consider the following netlist fragment:

```plaintext
*...other parts of more complex circuit deleted...
* potentially bad usage of ABM device
Vexample 1 0 5V
d1 1 0 diode_model
B1 2 0 V={sqrt(v(1))}
rl 2 0 10k
*...other parts of more complex circuit deleted...
```

This example demonstrates a potentially dangerous usage. It is assumed, because node 1 is connected to a 5V DC source, that the argument of the square root function is always positive. However, it could be the case that during the nonlinear solution of the full circuit that an unconverged value of node 1 might be negative. Tracking down mistakes such as this can be difficult, as on most platforms B1 will result in a “Not a Number” value for the nodal voltage of node 2, but the program will not crash. This frequently results in inexplicable “Timestep too small” errors.

Although such things can be avoided by protecting the arguments of functions with a limited domain, care must be taken when doing this. One obvious way to protect the example circuit fragment would be to take the absolute value of V(1) before calling the square root (sqrt) function:
There are many other ways to protect the square root function from negative arguments, such as by using the maximum of zero and V(1). Some alternatives might be more appropriate than others in different contexts.

Note, though, that it would be a mistake to attempt to generate the absolute value as shown here:

There are two things wrong with this example — first, node 3 is floating and this alone could lead to convergence problems. Second, by adding the second ABM device one has merely created an equation whose solution is that node 3 contains the absolute value of the voltage on node 1. However, until convergence is reached there is no guarantee node 3 will be precisely the absolute value of V(3), nor is it guaranteed that node 3 will have a positive voltage. To re-iterate, nodes have values that are solutions to the set of equations created by the netlist only at convergence.

6.3.3 ABM devices should not be used purely for output postprocessing

Users sometimes use ABM devices to provide output postprocessing. For example, if a user was interested in the absolute value, or the log of an output voltage then that user might create an ABM circuit element to calculate the desired output value.

Using ABM sources in this manner is bad practice though. By creating a circuit element whose only purpose is postprocessing, Xyce is forced to include it and the corresponding nonlinear solve in the circuit, which can cause unnecessary solver problems. If postprocessing is the goal, it is much better to use expressions directly on the .PRINT line.

An example of a “bad use” of ABM sources can be found in the following code fragment:

* Bad example
Although the source B1 provides a postprocessing output, it doesn't play a functional role in the circuit; Xyce would still be forced to include B1 in the problem it is attempting to solve.

A better solution to the previous problem is given here:

```
* Good example
VIN 1 0 DC 5V
R1 1 2 2K
D1 3 0 DMOD
VMON 2 3 0
.MODEL DMOD D (IS=100FA)
.DC VIN 5 5 1
.PRINT DC I(VMON) V(3) V(test1) {abs(I(VMON))*1.0e-10}
```

Section 9.1 and the Xyce Reference Guide provide a more detailed explanation of how to use expressions in the .PRINT line.
7. Analysis Types

Chapter Overview

This chapter describes the different analysis types available in Xyce. It includes the following sections:

- Section 7.1 Introduction
- Section 7.2 DC Analysis
- Section 7.3 Transient Analysis
- Section 7.4 STEP Parametric Analysis
- Section 7.5 Harmonic Balance Analysis
- Section 7.6 AC Analysis
7.1 Introduction

*Xyce* supports several simulation analysis options, including DC bias point (.DC, section 7.2), transient (.TRAN, section 7.3), AC (.AC, section 7.6), and harmonic balance (.HB, section 7.5).

Using .STEP (section 7.4), *Xyce* can also apply an outer parametric loop to any type of analysis. This allows one (for example) to sweep a model parameter and perform a transient simulation for each parameter value.

There are some analysis types typically found in SPICE-style simulators that are still a work in progress for *Xyce*. Operating point analysis (.OP, section 7.2.3) is partially supported in *Xyce*.

7.2 Steady-State (.DC) Analysis

The DC sweep analysis capability in *Xyce* computes the DC bias point of a circuit for a range of values of input sources. DC sweep is supported for a source or device parameter, through a range of specified values. As the sweep proceeds, *Xyce* computes the bias point for each value in the specified range of the sweep.

If the variable to be swept is a voltage or current source, a DC source must be used and its value set in the netlist (see *Xyce* Reference Guide [3]). In simulating the DC response of an analog circuit, *Xyce* eliminates time dependence from the circuit by treating capacitor elements as open circuits and inductor elements as short circuits, while using only the DC values of voltage and current sources.

7.2.1 .DC Statement

To specify a .DC analysis, include a .DC line in the netlist. Some examples of typical .DC lines are:

**Example:**

```
.DC V1 7m 5m -1m
.DC I1 5u 10u 1u
.DC M1:L 7u 5u -1u
.DC OCT V0 0.125 64 2
.DC DEC R1 100 10000 3
.DC TEMP LIST 10.0 15.0 18.0 27.0 33.0
```

The examples include all four types of sweep — linear, octave, decade, and list, and demonstrates sweeping over voltage and current sources as well as device parameters. The *Xyce* Reference Guide [3] provides a complete description of each.
7.2.2 Setting Up and Running a DC Sweep

Following the example given in section 3.2, figure 7.1 shows the diode clipper circuit netlist with a DC sweep analysis specified. Here, the voltage source $V_{in}$ is swept from -10 to 15 in 1-volt increments, resulting in 26 DC operating point calculations.

NOTE: Xyce ignores the default setting for $V_{in}$ during these calculations. All other source values use the specified values (in this case, $V_{CC} = 5V$).

Running Xyce on this netlist produces an output results file named clipper.cir.prn. Obtaining this file requires specifying the .PRINT DC line. Plotting this data produces the graph shown in figure 7.2.

![Diode Clipper Circuit](image)

**Figure 7.1.** Diode clipper circuit netlist for DC sweep analysis.

7.2.3 OP Analysis

Xyce also supports .OP analysis statements. In Xyce, consider .OP as a shorthand for a single-step DC sweep, in which all the default operating point values are used. One may also consider
.OP analysis to be the operating point calculation that would occur as the initial step to a transient calculation, without the subsequent time steps.

This capability was mainly added to enable the code to handle legacy netlists using this analysis statement type. In most versions of SPICE, using .OP results in extra output not available from a DC sweep. Xyce will also output some of this extra information about devices, but the capability is not fully implemented.

7.2.4 Output

During analysis a number of output files may be generated. The selection of which files are created depends on a variety of factors, most obvious of which is the .PRINT command. Table 7.1 lists the format options and files created. The column labeled “Additional Columns” lists the additional data that is written, though not specified on the .PRINT line.

7.3 Transient Analysis

The transient response analysis simulates the response of the circuit from TIME=0 to a specified time. Throughout a transient analysis, any or all of the independent sources may have time-dependent values.

In Xyce (and most other circuit simulators), the transient analysis begins by performing its own bias point calculation at the beginning of the run, using the same method as used for DC sweep. This is required to set the initial conditions for the transient solution as the initial values of the sources may differ from their DC values.
### Table 7.1. Output generated for DC analysis

<table>
<thead>
<tr>
<th>Trigger</th>
<th>Files</th>
<th>Additional Columns</th>
</tr>
</thead>
<tbody>
<tr>
<td>.PRINT DC</td>
<td>circuit-file.prn</td>
<td>INDEX TIME</td>
</tr>
<tr>
<td>.PRINT DC NOINDEX</td>
<td>circuit-file.prn</td>
<td>TIME</td>
</tr>
<tr>
<td>.PRINT DC FORMAT=CSV</td>
<td>circuit-file.csv</td>
<td>TIME</td>
</tr>
<tr>
<td>.PRINT DC FORMAT=RAW</td>
<td>circuit-file.raw</td>
<td>TIME</td>
</tr>
<tr>
<td>.PRINT DC FORMAT=TECPLLOT</td>
<td>circuit-file.dat</td>
<td>TIME</td>
</tr>
<tr>
<td>.PRINT DC FORMAT=PROBE</td>
<td>circuit-file.csd</td>
<td>TIME</td>
</tr>
<tr>
<td>runxyce -r</td>
<td>circuit-file.raw</td>
<td>All circuit variables printed</td>
</tr>
<tr>
<td>runxyce -r -a</td>
<td>circuit-file.raw</td>
<td>All circuit variables printed</td>
</tr>
<tr>
<td>.OP</td>
<td>log-file</td>
<td>Operating point information</td>
</tr>
</tbody>
</table>

### 7.3.1 .TRAN Statement

To run a transient simulation, the circuit netlist file must contain a .TRAN command.

**Example:**

```
.TRAN 100us 300ms
.TRAN 100p 12.05u 9.95u
```

The Xyce Reference Guide [3] provides a detailed explanation of the .TRAN statement. The netlist must also contain one of the following:

- Independent, transient source (see table 7.2),
- Initial condition on a reactive element, or
- Time-dependent behavioral modeling source (see chapter 6)

### 7.3.2 Defining a Time-Dependent (transient) Source

**Overview of Source Elements**

Source elements, either voltage or current, are entered in the netlist file as described in the Xyce Reference Guide [3]. Table 7.2 lists the time-dependent sources available in Xyce for either voltage...
Table 7.2. Summary of Xyce-supported time-dependent sources

<table>
<thead>
<tr>
<th>Source Element Name</th>
<th>Description</th>
</tr>
</thead>
<tbody>
<tr>
<td>EXP</td>
<td>Exponential Waveform</td>
</tr>
<tr>
<td>PULSE</td>
<td>Pulse Waveform</td>
</tr>
<tr>
<td>PWL</td>
<td>Piecewise Linear Waveform</td>
</tr>
<tr>
<td>SFFM</td>
<td>Frequency-modulated Waveform</td>
</tr>
<tr>
<td>SIN</td>
<td>Sinusoidal Waveform</td>
</tr>
</tbody>
</table>

or current. For voltage sources, the name is preceded by V while current sources are preceded by I.

To use time-dependent or transient sources, place the source element line in the netlist and characterize the transient behavior using the appropriate parameters. Each transient source element has a separate set of parameters dependent on its transient behavior. In this way, the user can create analog sources that produce sine wave, square pulse, exponential pulse, single-frequency FM, and PLWs.

Defining Transient Sources

To define a transient source, select one of the supported sources: independent voltage or current, choose a transient source type from table 7.2, and provide the transient parameters (refer to the Xyce Reference Guide [3] to fully define the source).

The following example of an independent sinusoidal voltage source in a circuit netlist creates a voltage source between nodes 1 and 5 that oscillates sinusoidally between -5V and +5V with a frequency of 50 KHz. The arguments specify an offset of -5V, a 10V amplitude, and a 50KHz frequency, in that order.

**Example:** Vexample 1 5 SIN(-5V 10V 50K)

7.3.3 Transient Time Steps

During the simulation, Xyce uses a calculated time step that is continuously adjusted for accuracy and efficiency (see [7] and [8]). Calculation timestep increases during periods of circuit idleness, and decreases during dynamic portions of the waveform. Users may control maximum internal step size by specifying the step ceiling value in the .TRAN command (see the Xyce Reference Guide [3]).

The internal calculation time steps used might not be consistent with the user-requested output time steps. By default, Xyce outputs solution results at every time step it calculates. If the user selects output timesteps via the .OPTIONS OUTPUT statement (see chapter 9), then Xyce will output
results at the interval requested, interpolating solution variables to desired output times if necessary.

7.3.4 Time Integration Methods

For a transient analysis, several time integration methods can be selected to solve the circuit model's differential algebraic equations. The following algorithms are available:

- Variable order Trapezoidal (combines Trapezoidal and Backward Euler)
- Backward Difference Formula, orders 1-5
- Gear method, orders 1-2.

You can set the method, maxord and minord parameters to select the time integration methods via a .OPTIONS line. The following table shows the possible settings for those three parameters. (Note: Consult the Reference Guide for the exact syntax of the .OPTIONS line for each time integration method.) The default time integration method in Xyce is Trap, which is the same as SPICE, PSPICE and HSPICE.

Table 7.3. Summary of Xyce-supported time integration methods

<table>
<thead>
<tr>
<th>Integration Methods</th>
<th>Option Settings</th>
<th>Comments</th>
</tr>
</thead>
<tbody>
<tr>
<td>Backward-Euler</td>
<td>method=trap maxord=1</td>
<td>Backward-Euler only</td>
</tr>
<tr>
<td>Trap</td>
<td>method=trap</td>
<td>combines Trapezoidal and Backward Euler (default)</td>
</tr>
<tr>
<td>Trap only</td>
<td>method=trap minord=2</td>
<td>Trapezoidal only</td>
</tr>
<tr>
<td>Backward Difference Formula</td>
<td>method=bdf</td>
<td>higher order integration</td>
</tr>
<tr>
<td>Gear</td>
<td>method=gear</td>
<td>combines Backward Euler and 2nd order Gear</td>
</tr>
<tr>
<td>Gear2 only</td>
<td>method=gear minord=2</td>
<td>2nd order Gear only</td>
</tr>
</tbody>
</table>

The Trapezoidal method is often the preferred method because it is accurate and fast. However, this method can exhibit artificial point-to-point ringing, which can be controlled by using tighter tolerances. If a circuit fails to converge with the Trapezoidal method then you can re-run the transient analysis using the Gear or BDF method.

The Gear method and Backward Difference Formula (BDF) method may help convergence for some circuits. The 2nd order Gear method is typically more accurate than Backward-Euler method. However, both of these methods are overly stable methods, and they can damp the actual circuit behavior when simulating high Q resonators such as oscillators. The Backward-Euler method has more damping effect than the 2nd order Gear method. This effect can be alleviated by using
tighter tolerances in the simulations. However, it is suggested to use the pure Trapezoidal method for oscillators.

The Backward Difference Formula (BDF) method can use higher order integration up to order 5. It uses variable time step size and variable order. If the order used is more than 2nd order then the results are interpolated using high order polynomial interpolations.

7.3.5 Error Controls

There are two basic time-step error control methods in Xyce — Local Truncation Error (LTE) based and non-LTE based.

Local Truncation Error (LTE) Strategy

All time integration methods use the LTE-based strategy by default. The accuracy of the simulation can be controlled by specifying appropriate relative and absolute error tolerances (RELTOL and ABSTOL).

Example:
.OPTIONS TIMEINT RELTOL=1e-4 ABSTOL=1e-8

The total tolerance of LTE is
\[ \text{Tol}_{LTE} = \text{abstol} + \text{reitol} \cdot \text{ref} \]

The parameter \( \text{ref} \) is the reference value that the relative error is compared to. It can be controlled by setting newlte option.

Example:
.OPTIONS TIMEINT NEWLTE=1

When newlte is set to be true, the reference value is the maximum of all the signals at the current time. When newlte is set to be false, the reference value is the current value at each node.

The Trapezoid integrator algorithm introduces no numerical dissipation. So, a strong ringing (artificially introduced by the numerical algorithm) will occur when sources or models introduce discontinuities. This can result in a large local truncation error estimate, ultimately leading to a “time-step too small” error. In this case, using the Gear and BDF methods or a non-LTE strategy may help.

Non-LTE Strategy

The non-LTE strategy used in Xyce is based on success of the nonlinear solve, and is enabled by setting ERROPTION=1. Since the step-size selection is based only upon nonlinear iteration statistics rather than accuracy, it is highly suggested that DELMAX be specified, in a circuit-specific
manner, for all three time integrators. The purpose of DELMAX is to limit the largest time step taken.

The behavior of this setting (ERROPTION=1) is slightly different for the BDF integrator and other integrators. For the BDF integrator, if the nonlinear solver converges, then the step-size is doubled. On the other hand, if the nonlinear solver fails to converge, then the step-size is cut by one eighth.

Example:
.OPTIONS TIMEINT ERROPTION=1 DELMAX=1.0e-4

For the Trapezoid and Gear integrators, the options are slightly more refined. If the number of nonlinear iterations is below NLMIN, then the step size is doubled. If the number of nonlinear iterations is above NLMAX then the step size is cut by one eighth. In between, the step size is not changed. An example using Trap (METHOD=7) is given below.

Example:
.OPTIONS TIMEINT METHOD=7 ERROPTION=1 NLMIN=3 NLMAX=8 DELMAX=1.0e-4

If the number of Newton iterations is bigger than NLmax and TIMESTEPSREVERSAL is not set, then Xyce will cut the next step. If the number of Newton iterations is bigger than NLmax and TIMESTEPSREVERSAL is set, then Xyce will reject the current step and also cut the current step.

Example:
.OPTIONS TIMEINT METHOD=7 ERROPTION=1 DELMAX=1.0e-4 TIMESTEPSREVERSAL=1

7.3.6 Checkpointing and Restarting

Xyce was designed to simulate large, complex circuits over long simulation runs. Because complex simulations can take many hours (or even days) to complete, it can sometimes be helpful to use “checkpointing.” When checkpointing is used, Xyce periodically saves its complete simulation state. The saved state can be used to restart Xyce from one of these “checkpoints.” In the event of a computer crash, power outage, or should the simulation need to be interrupted for some other reason, checkpointing allows the user to restart a long simulation in the middle of a run without having to start over.

Xyce uses the .OPTIONS RESTART netlist command to control all checkpoint output and restarting.

Checkpointing Command Format

- .OPTIONS RESTART [PACK=<0|1>] JOB=<job name> [INITIAL_INTERVAL=<interval> [<t0> <i0> [<t1> <i1>...]]]
  PACK=<0|1> indicates whether restart data files will contain byte-packed (binary) data(PACK=1,
the default) or unpacked (ASCII) ($\text{PACK}=0$). $\text{JOB}=<\text{job name}>$ identifies the prefix for restart files. The actual restart files will be the job name appended with the current simulation time (e.g., $\text{name1e-05}$ for $\text{JOB}=\text{name}$ and simulation time 1e-05 seconds). Furthermore, the $\text{INITIAL_INTERVAL}=<\text{interval}>$ identifies the initial interval time used for restart output. The $<\text{tx}, \text{ix}>$ intervals identify times ($\text{tx}$) at which the output interval ($\text{ix}$) will change. This functionality is identical to that described for the $\text{.OPTIONS OUTPUT}$ command (section 9.1).

■ **Example** — Generate checkpoints at every time step (default):

```
.OPTIONS RESTART JOB=checkpt
```

■ **Example** — Generate checkpoints every 0.1 $\mu$s:

```
.OPTIONS RESTART JOB=checkpt INITIAL_INTERVAL=0.1us
```

■ **Example** — Generate unpacked checkpoints every 0.1 $\mu$s:

```
.OPTIONS RESTART PACK=0 JOB=checkpt INITIAL_INTERVAL=0.1us
```

■ **Example** — Initial interval of 0.1 $\mu$s, at 1 $\mu$s in the simulation, change to interval of 0.5 $\mu$s, and at 10 $\mu$s change to an interval of 0.1 $\mu$s:

```
.OPTIONS RESTART JOB=checkpt INITIAL_INTERVAL=0.1us 1us 0.5us
+ 10us 0.1us
```

### Restarting Command Format

```
.OPTIONS RESTART <FILE=<filename> | JOB=<job name> START_TIME=<time>>
+ [INITIAL_INTERVAL=<interval> [<t0> <i0> [<t1> <i1> ...]]]]
```

To restart from an existing restart file, specify the file by using either the $\text{FILE}=<\text{filename}>$ parameter to explicitly request a file or $\text{JOB}=<\text{job name}>$ $\text{START_TIME}=<\text{time}>$ to specify a file prefix and a specific time. The time must exactly match an output file time for the simulator to correctly load the file.

To continue checkpointing the simulation in a restarted run, append $\text{INITIAL_INTERVAL}=<\text{interval}>$ and the following intervals to the command in the same format as previously described. Without these additional parameters, the simulation will restart as requested, but will not generate further checkpoint files.

■ **Example** — Restart from checkpoint file at 0.133 $\mu$s:

```
.OPTIONS RESTART JOB=checkpt START_TIME=0.133us
```

■ **Example** — Restart from checkpoint file at 0.133 $\mu$s:

```
.OPTIONS RESTART FILE=checkpt0.000000133
```

■ **Example** — Restart from 0.133 $\mu$s and continue checkpointing at 0.1 $\mu$s intervals:

```
.OPTIONS RESTART FILE=checkpt0.000000133 JOB=checkpt_again
+ INITIAL_INTERVAL=0.1us
```
7.3.7 Output

During analysis a number of output files may be generated. The selection of which files are created depends on a variety of factors, most obvious of which is the \texttt{.PRINT} command. Table 7.4 lists the format options and files created. The column labeled “Additional Columns” lists the additional data that is written, though not specified on the \texttt{.PRINT} line.

Table 7.4. Output generated for Transient analysis

<table>
<thead>
<tr>
<th>Trigger</th>
<th>Files</th>
<th>Additional Columns</th>
</tr>
</thead>
<tbody>
<tr>
<td>\texttt{.PRINT TRAN}</td>
<td>circuit-file.prn</td>
<td>INDEX TIME</td>
</tr>
<tr>
<td>\texttt{.PRINT TRAN NOINDEX}</td>
<td>circuit-file.prn</td>
<td>TIME</td>
</tr>
<tr>
<td>\texttt{.PRINT TRAN FORMAT=CSV}</td>
<td>circuit-file.csv</td>
<td>TIME</td>
</tr>
<tr>
<td>\texttt{.PRINT TRAN FORMAT=RAW}</td>
<td>circuit-file.raw</td>
<td>TIME</td>
</tr>
<tr>
<td>\texttt{.PRINT TRAN FORMAT=TECPLLOT}</td>
<td>circuit-file.dat</td>
<td>TIME</td>
</tr>
<tr>
<td>\texttt{.PRINT TRAN FORMAT=PROBE}</td>
<td>circuit-file.csd</td>
<td>TIME</td>
</tr>
<tr>
<td>\texttt{runzyce -r}</td>
<td>circuit-file.raw</td>
<td>All circuit variables printed</td>
</tr>
<tr>
<td>\texttt{runzyce -r -a}</td>
<td>circuit-file.raw</td>
<td>All circuit variables printed</td>
</tr>
<tr>
<td>\texttt{.OP}</td>
<td>log-file</td>
<td>Operating point information</td>
</tr>
</tbody>
</table>
7.4 STEP Parametric Analysis

The .STEP command performs a parametric sweep for all the analyses of the circuit. When the .STEP command is invoked, typical analyses, such as .DC, .AC, and .TRAN are performed for each value of the stepped parameter.

This capability is very similar, but not identical, to the STEP capability in PSPICE [4]. Xyce can use .STEP to sweep over any device instance or device model parameter, as well as the circuit temperature. It is not legal to sweep parameters defined in .PARAM statements, but it is legal to sweep global parameters defined in .global.param statements. Section 4.3 discusses these two distinct parameter definitions.

7.4.1 .STEP Statement

A .STEP analysis may be specified by simply adding a .STEP line to a netlist. Unlike .DC, .STEP by itself is not an adequate analysis specification, as it merely specifies an outer loop around the normal analysis. A standard analysis line, either specifying .TRAN, .AC and .DC analysis, is still required.

Some examples of typical .STEP lines are:

Example:

```
.STEP M1:L 7u 5u -1u
.STEP OCT V0 0.125 64 2
.STEP DEC R1 100 10000 3
.STEP TEMP LIST 10.0 15.0 18.0 27.0 33.0
```

.STEP has a format similar to that of the .DC format specification. In the first example, M1:L is the name of the parameter (in this instance, the length parameter of the MOSFET M1), 7u is the initial value of the parameter, 5u is the final value of the parameter, and -1u is the step size. Like .DC, .STEP in Xyce can also handle sweeps by decade, octave, or specified lists of values. Consult the Xyce Reference Guide [3] for complete explanations of each sweep type.

7.4.2 Sweeping over a Device Instance Parameter

The first example uses M1:L as the parameter, but it could have used any model or instance parameter existing in the circuit. Internally, Xyce handles the parameters for all device models and device instances in the same way. Users can uniquely identify any parameter by specifying the device instance name, followed by a colon (:), followed by the specific parameter name. For example, all the MOSFET models have an instance parameter for the channel length, L. For a MOSFET instance specified in a netlist, named M1, then the full name for the M1 channel length parameter is M1:L.

Figure 7.3 provides a simple application of .STEP to a device instance. This is the same diode clipper circuit as was used in the transient analysis chapter, except that a single line (in red) has
been added. The .STEP line will cause Xyce to sweep the resistance of the resistor, R4, from 3.0 KOhm to 15.0 KOhm, in 2.0-KOhm increments, meaning seven transient simulations will be performed, each one with a different value for R4.

As the circuit is executed multiple times, the resulting output file is a little more sophisticated. The .PRINT statement is still used in much the same way as before. However, the .prn output file contains the concatenated output of each .STEP increment. The end of this section provides details of how .STEP changes output files.

```
Transient Diode Clipper Circuit with Step Analysis
* Voltage Sources
VCC 1 0 5V
VIN 3 0 SIN(0V 10V 1kHz)
* Analysis Command
.TRAN 2ns 2ms
* Output
.PRINT TRAN V(3) V(2) V(4)
* Step statement
.STEP R4:R 3.0K 15.0K 2.0K
* Diodes
D1 2 1 D1N3940
D2 0 2 D1N3940
* Resistors
R1 2 3 1K
R2 1 2 3.3K
R3 2 0 3.3K
R4 4 0 5.6K
* Capacitor
C1 2 4 0.47u
.MODEL D1N3940 D(
+ IS=4E-10 RS=.105 N=1.48 TT=8E-7
+ CJO=1.95E-11 VJ=.4 M=.38 EG=1.36
+ XTI=8 KF=0 AF=1 FC=.9
+ BV=600 IBV=1E-4)
.END
```

Figure 7.3. Diode clipper circuit netlist for step transient analysis

### 7.4.3 Sweeping over a Device Model Parameter

Sweeping a model parameter can be done in an identical manner to an instance parameter. Figure 7.4 contains the same circuit as in figure 7.3 but with additional .STEP line referring to a model parameter, D1N3940:IS.

NOTE: .STEP line syntax differs from .DC line syntax in that multiple parameters require separate
7.4.4 Sweeping over Temperature

It is also possible to sweep over temperature. To do so, simply specify temp as the parameter name. It will work in the same manner as .STEP when applied to model and instance parameters.

7.4.5 Special cases: Sweeping Independent Sources, Resistors, Capacitors

For some devices, there is generally only one parameter that one would want to sweep. For example, a linear resistor’s only parameter of interest is resistance, R. Similarly, for a DC voltage
or current source, one is usually only interested in the magnitude of the source. Finally, linear capacitors generally only have capacitance, C, as a parameter of interest.

For these simple devices, it is not necessary to specify both the parameter and device on the .STEP line: only the device name is strictly required, as these three types of devices have default parameters that are assumed if no parameter name is given explicitly.

Examples of usage are given below. The first two lines are equivalent — in the first line, the resistance parameter of R4 is named explicitly, and in the second line the resistance parameter is implicit. In the remaining lines, parameter names are all implicit, and the default parameters of the associated devices are used.

Example:

```
.STEP R4:R 3.0K 15.0K 2.0K
.STEP R4 3.0K 15.0K 2.0K
.STEP VCC 4.0 6.0 1.0
.STEP ICC 4.0 6.0 1.0
.STEP C1 0.45u 0.50u 0.1u
```

Independent sources require further explanation. Only some of the many different types of independent sources have default parameters. Sources subject to .DC sweeps (swept sources) have no default parameter, as this could easily lead to infinite loops should a device be specified in both a .DC and .STEP line. Table 7.5 defines various independent source default parameters.

Table 7.5: Default parameters for independent sources.

<table>
<thead>
<tr>
<th>Source Type</th>
<th>Default</th>
</tr>
</thead>
<tbody>
<tr>
<td>Sinusoidal source</td>
<td>V0 (DC value, Offset)</td>
</tr>
<tr>
<td>Exponential source</td>
<td>V1 (DC value, Initial value)</td>
</tr>
<tr>
<td>Pulsed source</td>
<td>V2 (Pulsed value)</td>
</tr>
<tr>
<td>Constant, or DC source</td>
<td>V0 (Constant value)</td>
</tr>
<tr>
<td>Piecewise Linear source</td>
<td>No default</td>
</tr>
<tr>
<td>SFFM source</td>
<td>No default</td>
</tr>
<tr>
<td>Swept source (specified on a .DC line)</td>
<td>No default</td>
</tr>
</tbody>
</table>

7.4.6 Output files

Users can think of .STEP simulations as several distinct executions of the same circuit netlist. The output data, as specified by a .PRINT line, however, goes to a single (*.prn) file. For convenience, Xyce also creates a second auxilliary file with the *.res suffix.

Figure 7.3 shows an example file named clip.cir, which when run will produce files clip.cir.res and clip.cir.prn. clip.cir.res contains one line for each step, showing what parameter value was used on that step. clip.cir.prn is the familiar output format, but the INDEX field recycles to zero each time a new step begins. As the default behavior distinguishes each step's output
only by recycling the INDEX field to zero, it can be beneficial to add the sweep parameters to the .PRINT line. For the default file format (format=std), Xyce will not automatically include these sweep parameters, so for plotting it is usually best to specify them by hand.

If using the default .prn file format (format=std), the resulting .STEP simulation output file will be a simple concatenation of each step's underlying analysis output. If using format=probe, the data for each execution of the circuit will be in distinct sections of the file, and it should be easy to plot the results using PROBE. If using format=tecplot, the results of each .STEP simulation will be in a distinct tecplot zone. Finally, format=raw will place the results for each .STEP simulation in a distinct “plot” region.
7.5 Harmonic Balance Analysis

Harmonic balance (HB) is a technique that solves for the steady state solution of nonlinear circuits in the frequency domain. In harmonic balance simulation, voltages and currents in a nonlinear circuit are represented by truncated Fourier series. HB directly computes the frequency spectrum of voltages and currents at the steady state solution. This can be more efficient than transient analysis in applications where transient analysis may take long time to reach the steady state solution. In particular, HB is well suited for simulating analog RF and microwave circuits.

**Xyce** supports single-tone HB for driven circuits in its serial build. That means, harmonic balance analysis can be only applied on a circuit that is excited by a periodic source with one fundamental frequency. HB outputs the real and imaginary components of voltages and currents in frequency domain. **Xyce** also provides time domain responses of a circuit.

For HB simulation, an initial guess of the solution is required. A good initial guess is important for HB to converge. By default, **Xyce** uses transient analysis to determine the initial guess, often called “Transient Assisted HB”. This option is controlled by the parameter, TAHB, which is enabled if TAHB=1 and disabled if TAHB=0 in .options hbint. If enabled, the starting time of the transient analysis can be modified by specifying parameter STARTUPPERIODS in .options hbint. The **Xyce** Reference Guide [3] provides a detailed explanation of the HB options.

### 7.5.1 .HB Statement

To run a HB simulation, the circuit netlist file must contain a .HB command.

**Example:**

```
.HB 1e4
```

The parameter following .HB is the fundamental frequency and must be specified by the user. The **Xyce** Reference Guide [3] provides a detailed explanation of the .HB statement.

### 7.5.2 HB Options

Key parameters for .HB simulation can be specified by .options hbint.

**Example:**

```
.options hbint numfreq=41 STARTUPPERIODS=2
```

As shown in the example, numfreq specifies the total number of harmonic frequencies to be calculated, which must be an odd number. For this example, the user will be returned 20 negative and 20 positive harmonics plus the dc component.

STARTUPPERIODS specifies the number of time periods that **Xyce** should integrate through using normal transient analysis before generating the initial conditions for HB analysis. For this example,
**Xyce** will integrate through two periods before computing the initial conditions, which requires an additional period. Thus, **Xyce** will integrate through three periods to compute the initial conditions for HB analysis.

### Nonlinear Solver Options

The HB analysis uses a different set of default nonlinear solver parameters than that of transient and DC analysis. Nonlinear solver parameters for HB simulation can be specified by using `.options nonlin-hb`.

**Example:**

```
.options nonlin-hb abstol=1e-6
```


### Linear Solver Options

The single-tone HB analysis provided by **Xyce** employs direct solvers in the transient analysis used to generate initial conditions. However, during the HB analysis, only matrix-free operators are available, which require the use of iterative solvers. Section [10.3] provides a more detailed discussion of iterative solvers.

Preconditioners have been developed for the iterative solvers used in HB analysis. You can set iterative solver and preconditioner options using the `.options hb-linsol` statement.

**Example:**

```
.options linsol-hb type=aztecoo prec_type=block_jacobi AZ_tol=1e-9
```

where, `type` specifies the iterative solver to use in the HB analysis and `AZ_tol` is the relative tolerance for the iterative solver. Any of the iterative solver options in section [10.3] are valid. However, `prec_type` specifies which HB-specific preconditioner to use. The choices for this option are `none` (default) and `block_jacobi`.

### 7.5.3 Output

During analysis a number of output files may be generated. The selection of which files are created depends on a variety of factors, most obvious of which is the `.PRINT HB` command. Table [7.6] lists the format options and files created. The column labeled “Additional Columns” lists the additional data that is written, though not specified on the `.PRINT HB` line.

### 7.5.4 User Guidance

One of the most common errors in HB simulation setup is the use of too few harmonic frequencies (i.e., `numfreq` is too small). One way to determine the optimum number of harmonic frequencies
Table 7.6. Output generated for HB analysis

<table>
<thead>
<tr>
<th>Trigger</th>
<th>Files</th>
<th>Additional Columns</th>
</tr>
</thead>
<tbody>
<tr>
<td>.PRINT HB</td>
<td>circuit-file.HB.TD.prn, circuit-file.HB.FD.prn</td>
<td>INDEX TIME, FREQUENCY</td>
</tr>
<tr>
<td>.PRINT HB NOINDEX</td>
<td>circuit-file.HB.TD.prn, circuit-file.HB.FD.prn</td>
<td>TIME, FREQUENCY</td>
</tr>
<tr>
<td>.PRINT HB FORMAT=CSV</td>
<td>circuit-file.HB.TD.csv, circuit-file.HB.FD.csv</td>
<td>TIME, FREQUENCY</td>
</tr>
<tr>
<td>.PRINT HB FORMAT=RAW</td>
<td>circuit-file.raw</td>
<td></td>
</tr>
<tr>
<td>.PRINT HB FORMAT=TECPLLOT</td>
<td>circuit-file.HB.TD.dat, circuit-file.HB.FD.dat</td>
<td>TIME, FREQUENCY</td>
</tr>
<tr>
<td>runxyce -r</td>
<td>circuit-file.raw</td>
<td>All circuit variables printed</td>
</tr>
<tr>
<td>runxyce -r -a</td>
<td>circuit-file.raw</td>
<td>All circuit variables printed</td>
</tr>
<tr>
<td>.PRINT HB</td>
<td>circuit-file.startup.prn</td>
<td>INDEX TIME</td>
</tr>
<tr>
<td>.PRINT HB FORMAT=CSV</td>
<td>circuit-file.startup.csv</td>
<td>TIME</td>
</tr>
<tr>
<td>.PRINT HB FORMAT=TECPLLOT</td>
<td>circuit-file.startup.dat</td>
<td>TIME</td>
</tr>
<tr>
<td>.PRINT HB</td>
<td>circuit-file.hb.ic.prn</td>
<td>INDEX TIME</td>
</tr>
<tr>
<td>.PRINT HB FORMAT=CSV</td>
<td>circuit-file.hb.ic.csv</td>
<td>TIME</td>
</tr>
<tr>
<td>.PRINT HB FORMAT=TECPLLOT</td>
<td>circuit-file.hb.ic.dat</td>
<td>TIME</td>
</tr>
<tr>
<td>.OP</td>
<td>log-file</td>
<td>Operating point information</td>
</tr>
</tbody>
</table>

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is to first simulate the circuit with a small numfreq, then increase the numfreq until the solution stops changing within a significant bound. Requesting too many harmonic frequencies is wasteful of memory and simulation time, so it is not practical to just clobber the problem with a very high numfreq either.

7.6 AC Analysis

The AC small-signal analysis of Xyce computes AC output variables as a function of frequency. The program first computes the DC operating point of the circuit and linearizes the circuit. The resultant linear circuit is then analyzed over a user-specified range of frequencies. The desired output of an AC small-signal analysis is usually a transfer function (voltage gain, transimpedance, etc). If the circuit has one AC input, it is convenient to set that input to unity and zero phase so output variables have the same value as the transfer function of the output variable with respect to input.

7.6.1 .AC Statement

One may specify .AC analyses by adding a .AC line in the netlist. Some examples of typical .AC lines include:

Example:

```
.AC DEC 10 1K 100MEG
.AC DEC 10 1 10K
.AC LIN 100 1 100HZ
```

The examples include some types of sweep (linear and decade). The Xyce Reference Guide [3] provides a complete description of all types of sweep.

7.6.2 AC Voltage and Current Sources

Xyce assumes the AC source to be a cosine waveform at a specified phase angle. Its frequency must be defined in a separate "AC" command defining the frequency for all the sources in the circuit. The unique information for the individual source is the name (which must start with "V" or "I"), the node numbers, the magnitude of the source, and its phase angle. Some examples are as follows:

Example:

```
Vac 4 1 AC 120V 30
Vin 1 0 1.44 ac .1
Iin 1 0 1.44e-5 ac 0.1e-5 sin(0 1 1e+5 0 0)
```

NOTE: The type, AC, must be specified because the default is DC. If not specified, Xyce assumes the phase angle to be zero degrees. The units of the phase angle are in degrees.
7.6.3 Output

During analysis a number of output files may be generated. The selection of which files are created depends on a variety of factors, most obvious of which is the .PRINT command. Table 7.7 lists the format options and files created. The column labeled “Additional Columns” lists the additional data that is written, though not specified on the .PRINT line.

Table 7.7. Output generated for AC analysis

<table>
<thead>
<tr>
<th>Trigger</th>
<th>Files</th>
<th>Additional Columns</th>
</tr>
</thead>
<tbody>
<tr>
<td>.PRINT AC</td>
<td>circuit-file.FD.prn</td>
<td>INDEX FREQUENCY INDEX TIME</td>
</tr>
<tr>
<td>.PRINT AC NOINDEX</td>
<td>circuit-file.FD.prn</td>
<td>INDEX FREQUENCY TIME</td>
</tr>
<tr>
<td>.PRINT AC FORMAT=CSV</td>
<td>circuit-file.FD.csv</td>
<td>FREQUENCY TIME</td>
</tr>
<tr>
<td>.PRINT AC FORMAT=RAW</td>
<td>circuit-file.raw</td>
<td>TIME</td>
</tr>
<tr>
<td>.PRINT AC FORMAT=TECPLLOT</td>
<td>circuit-file.dat</td>
<td>TIME</td>
</tr>
<tr>
<td>.PRINT AC FORMAT=PROBE</td>
<td>circuit-file.csd</td>
<td>TIME</td>
</tr>
<tr>
<td>runxyce -r</td>
<td>circuit-file.raw</td>
<td>All circuit variables printed</td>
</tr>
<tr>
<td>runxyce -r -a</td>
<td>circuit-file.raw</td>
<td>All circuit variables printed</td>
</tr>
<tr>
<td>.OPTIONS NONLIN CONTINUATION=&lt;method&gt;...</td>
<td>circuit-file.HOMOTOPY.prn</td>
<td>INDEX TIME</td>
</tr>
<tr>
<td>.PRINT AC NOINDEX .OPTIONS NONLIN CONTINUATION=&lt;method&gt;...</td>
<td>circuit-file.HOMOTOPY.prn</td>
<td>INDEX TIME</td>
</tr>
</tbody>
</table>

7.6.4 Using the .PRINT AC Command

Running Xyce on AC analysis produces an output results file named .cir.FD.prn. Obtaining this file requires that the .PRINT AC line be specified.

Xyce supports printing the real and imaginary parts of phasor values (complex numbers) for AC analysis output as voltages or currents. For instance, specify “V(1)” to print the real part and imaginary part of a voltage at nodes 1. Some complete examples are as follows:

Example:

.print AC v(3)
Support for other formats of AC analysis output, such as magnitude, phase (angle), and options to print each format, is still a work in progress for Xyce.
8. Using Homotopy Algorithms to Obtain Operating Points

Chapter Overview

This chapter includes the following sections:

- Section 8.1 Homotopy Algorithms Overview
- Section 8.4 MOSFET Homotopy
- Section 8.2 Natural Parameter Homotopy
- Section 8.3 Natural Multiparameter Homotopy
- Section 8.5 GMIN Stepping Homotopy
- Section 8.6 Pseudo Transient
8.1 Homotopy Algorithms Overview

Often, circuit convergence problems are most prominent during the DC operating point calculation. Unlike transient solves, DC operating point analysis cannot rely on a good initial guess from a previous step, and cannot simply reduce the step size when the solver fails. Additionally, operating points often have multiple solutions, with no reliance on intent. Multiple solutions can, even for converged circuit problems, result in a standard Newton solve being unreliable. For example, it has been observed that the operating point solution to a Schmidt trigger circuit changed with the computational platform.

Homotopy methods can often provide solutions to difficult nonlinear problems, including circuit analysis, even when conventional methods (e.g., Newton’s method) fail [9] [10]. This chapter gives an introduction to using homotopy algorithms (sometimes called continuation algorithms) in Xyce. The Xyce Reference Guide [3] provides a more complete description of solver options.

8.1.1 HOMOTOPY Algorithms Available in Xyce

Most of the several types of homotopy Xyce are accessed by setting .options nonlin continuation=1, which allows the user to sweep existing device parameters (models and instances), as well as a few reserved artificial parameter cases. The most obvious natural parameter to use is the magnitude(s) of independent voltage or current sources, the choice of which is equivalent to “source stepping” in SPICE. Section 8.2 provides a Xyce source-stepping example. For some circuits (as in the aforementioned Schmidt trigger), source stepping leads to turning points in the continuation.

A special Xyce-only homotopy, an algorithm designed specifically for MOSFET circuits [11], involves two internal MOSFET model parameters — one for the MOSFET gain, and the other for the nonlinearity of the current-voltage relationship. This algorithm is invoked with .options nonlin continuation=2, and has proven to be effective in some large MOSFET circuits. Section 8.4 provides a detailed example.

Xyce invokes another well-known SPICE method, “GMIN stepping,” with .options nonlin continuation=3 or .options nonlin continuation=gmin, and is a special case where the parameter being swept is artificial. Section 8.5 provides an example of GMIN stepping.

8.2 Natural Parameter Homotopy

Figure 8.1 shows a natural parameter homotopy netlist with parameters pertinent to the homotopy algorithm highlighted in red. For this example, the parameter being swept is the DC value of the voltage source \( V_{DD_{dev}} \). As a result, this example demonstrates a version of “source stepping” similar to that of SPICE.

8.2.1 Explanation of Parameters, Best Practice

Figure 8.1 also illustrates the following “best practice” rules:
Figure 8.1. Example natural parameter homotopy netlist. NOTE: This usage example of source stepping shows a circuit that does not require homotopy to run. Most circuits complex enough to require homotopy would not fit on a single page.
.options nonlin continuation=1. Sets the algorithm to use natural parameter homotopy.

.options loca conparam=VDDdev. If using natural parameter homotopy, it is necessary include a setting for conparam. It sets which input parameter to perform continuation. The parameter name is subject to the same rules as parameter used by the .STEP capability. (section 7.4.2). In this case, the parameter is the magnitude of the DC voltage source, VDDdev. For this type of voltage source, it was possible to use the default device parameter (section 7.4.5)

.options loca initialvalue=0.0. This is required.

.options loca maxvalue=5.0. This is required.

.options loca stepcontrol=1 or .options loca stepcontrol=adaptive. This specifies homotopy steps to be adaptive, rather than constant. This is recommended.

.options loca maxsteps=100. This sets the maximum number of continuation steps for each parameter.

.options loca maxnliters=200. This is the maximum number of nonlinear iterations, and has precedence over the similar number that can be set on the .options nonlin line.

.options loca aggressiveness=1.0. This refers to the step size control algorithm, and the value of this parameter can be anything from 0.0 to 1.0. 1.0 is the most aggressive. In practice, try starting with this set to 1.0. If the solver fails, then reset to a smaller number.

NOTE: Although using the magnitudes of independent voltage and current sources is a fairly obvious approach, it does not seem to work very well in practice.

8.3 Natural Multiparameter Homotopy

It is possible to use the natural parameter homotopy specification to have Xyce sweep multiple parameters in sequential order. This requires specifying many of the parameters in the .options loca statement as vectors, delineated by commas, rather than as single parameters.

NOTE: This is a usage example — the circuit itself does not require homotopy to run. Most circuits complex enough to require homotopy would not fit on a single page.

8.3.1 Explanation of Parameters, Best Practice

The solver parameters set in figure 8.2 are the same as those from figure 8.1 but many of them are in vector form. Specify any parameters specific to the continuation variable as a vector, including conparam, initialvalue, minvalue, maxvalue, initialstepsize, minstepsize, maxstepsize, and aggressiveness. Otherwise, the specification is identical.
Figure 8.2. Example multiparameter homotopy netlist.  
NOTE: This netlist reproduces MOSFET homotopy with a manual specification.
8.4 MOSFET Homotopy

Figure 8.3 contains a MOSFET homotopy example netlist, and is the same circuit as was used in figure 8.3, except some of the parameters are different. As before, the lines pertinent to the homotopy algorithm are highlighted in red.

```
THIS CIRCUIT IS A MOS LEVEL 1 MODEL CMOS INVERTER
.TRAN 20ns 30us 0 5ns
.PRINT tran v(vout) v(in) v(1)
.options timeint reltol=5e-3 abstol=1e-3

* HOMOTOPY Options
.options nonlin continuation=mos

VDDdev VDD 0 5V
RIN IN 1 1K
VIN1 1 0 5V PULSE (5V 0V 1.5us 5ns 5ns 1.5us 3us)
R1 VOUT 0 10K
C2 VOUT 0 0.1p
MN1 VOUT IN 0 0 CD4012_NMOS L=5u W=175u
MP1 VOUT IN VDD VDD CD4012_PMOS L=5u W=270u
.MODEL cd4012_pmos PMOS
.MODEL cd4012_nmos NMOS
.END
```

Figure 8.3. MOSFET homotopy netlist example. NOTE: This is a usage example — the circuit itself does not require homotopy to run. Most circuits complex enough to require homotopy would not fit on a single page.

8.4.1 Explanation of Parameters, Best Practice

There are a few differences between the netlist in figures 8.1 and 8.3. This example shows one set of options, but there are numerous options of working combinations.

MOSFET homotopy requires only .options nonlin continuation=2 or .options nonlin continuation=mos parameters, which specifies use of the special MOSFET homotopy. This is a two-pass homotopy, in which first a parameter concerning gain is swept from 0 to 1, and then a parameter relating to the nonlinearity of the transfer curve is swept from 0 to 1. The default parameters will work for a variety of MOSFET circuits, so it often will be unnecessary to override them using an .options loca line. However, it is possible to override the default parameters using the same .options loca parameters described in section 8.2.1.
8.5 GMIN Stepping

GMIN stepping is a type of homotopy commonly available in circuit simulators. Although SPICE automatically attempts GMIN stepping if the initial operating point fails, Xyce requires it to be manually specified by setting continuation=3 or continuation=gmin. Figure 8.4 provides a netlist example of GMIN stepping.

```
THIS CIRCUIT IS A GMIN STEPPING EXAMPLE.
.TRAN 20ns 30us 0 5ns
.PRINT tran v(vout) v(in) v(1)
.options timeint reltol=5e-3 abstol=1e-3

* HOMOTOPY Options
.options nonlin continuation=gmin

VDDdev VDD 0 5V
RIN IN 1 1K
VIN1 IN 0 5V PULSE (5V 0V 1.5us 5ns 5ns 1.5us 3us)
R1 VOUT 0 10K
C2 VOUT 0 0.1p
MN1 VOUT IN 0 0 CD4012_NMOS L=5u W=175u
MP1 VOUT IN VDD VDD CD4012_PMOS L=5u W=270u
.MODEL cd4012_pmos PMOS
.MODEL cd4012_nmos NMOS
.END
```

Figure 8.4. Example GMIN stepping netlist. NOTE: The continuation parameter is gmin. It can also be specified using continuation=3.

The name "GMIN stepping" can be somewhat confusing, as "GMIN" is also a user-specified device package parameter (unrelated to this algorithm) that one may set. In the device context, "GMIN" refers to a minimum conductance applied to many device models to enhance convergence. In the homotopy context, it refers to the conductance of resistors attached from every circuit node to ground.

The conductance, which is the continuation parameter, is initially very large, and is iteratively reduced until the artificial resistors have a very high resistance. At the end of the continuation, the resistors are removed from the problem. At this point, assuming the continuation has been successful, the original user-specified problem has been solved.
8.5.1 Explanation of Parameters, Best Practice

In general, GMIN stepping can be very useful. It should be considered the first option whenever a circuit fails to obtain an operating point. One advantage is that it has the potential to be successful for any circuit type. Unlike MOSFET homotopy, it doesn’t require specific device models to be present to run.
8.6 Pseudo Transient

Pseudo transient continuation is very similar to GMIN stepping, in that both algorithms involve placing large artificial terms on the Jacobian matrix diagonal, and progressively making these terms smaller until the original circuit problem is recovered. One difference is, rather than doing a series on Newton solves, Pseudo transient does a single nonlinear solve while progressively modifying the pseudo transient parameter. Figure 8.5 provides an example of pseudo transient homotopy options.

```
* HOMOTOPY Options
  .options nonlin continuation=9
   
  .options loca
  + stepper=natural
  + predictor=constant
  + stepcontrol=adaptive
  + initialvalue=0.0
  + minvalue=0.0
  + maxvalue=1.0e12
  + initialstepsize=1.0e-6
  + minstepsize=1.0e-6
  + maxstepsize=1.0e6
  + aggressiveness=0.1
  + maxsteps=200
  + maxnliters=200
  + voltagescalefactor=1.0
```

Figure 8.5. Pseudo transient solver options example. NOTE: The continuation parameter is set to 9.

8.6.1 Explanation of Parameters, Best Practice

Pseudo transient has not been observed to be as successful as MOSFET-homotopy for large MOSFET circuits. It may, however, be a good candidate for difficult non-MOSFET circuits as it tends to be faster because the total number of matrix solves is smaller.
y
9. Results Output and Evaluation Options

Chapter Overview

This chapter illustrates how to output simulation results to data or output files and includes the following sections:

- Section 9.1 Control of Results Output
- Section 9.2 Additional Output Options
- Section 9.3 Output Analysis
- Section 9.4 Graphical Display of Solution Results
9.1 Control of Results Output

*Xyce* supports one solution output command, .PRINT, which is quite flexible, and supports several output formats.

### 9.1.1 .PRINT Command

The .PRINT command sends the analysis results to an output file. *Xyce* supports several options on the .PRINT line of netlists that control the format of the output. The syntax for the command is as follows:

```
.PRI{NT <analysis type> [options] <output variable> [<output variable>]*
```

Table 9.1 gives the various options currently available to the .PRINT command.

<table>
<thead>
<tr>
<th>Option</th>
<th>Action</th>
</tr>
</thead>
<tbody>
<tr>
<td>FORMAT=</td>
<td>Controls the output format. See Table 9.2</td>
</tr>
<tr>
<td>&lt;STD</td>
<td>NOINDEX</td>
</tr>
<tr>
<td>FILE=&lt;filename&gt;</td>
<td>Output filename. The default is the netlist filename with &quot;prn&quot; appended. foo.cir.prn, where foo.cir is the input netlist filename.</td>
</tr>
<tr>
<td>WIDTH=&lt;field-width&gt;</td>
<td>Column width for the output data</td>
</tr>
<tr>
<td>PRECISION=&lt;floating-point-precision&gt;</td>
<td>Number of significant digits past the decimal point</td>
</tr>
<tr>
<td>FILTER=&lt;floor-value&gt;</td>
<td>Absolute value below which output variables will be printed as 0.0</td>
</tr>
<tr>
<td>DELIMITER=&lt;TAB</td>
<td>COMMA&gt;</td>
</tr>
</tbody>
</table>

Table 9.2 gives the various output formats currently available to the .PRINT command.
Table 9.2. .PRINT FORMAT options.

<table>
<thead>
<tr>
<th>Format...</th>
<th>Action...</th>
</tr>
</thead>
<tbody>
<tr>
<td>STD</td>
<td>Outputs data in standard columns</td>
</tr>
<tr>
<td>NOINDEX</td>
<td>Outputs the same as the STD except the index column is omitted.</td>
</tr>
<tr>
<td>PROBE</td>
<td>Output is formatted to be compatible with the PSpice Probe plotting utility.</td>
</tr>
<tr>
<td>RAW</td>
<td>Output conforms to the Spice binary rawfile. Use the -a command line option to produce an ascii rawfile.</td>
</tr>
<tr>
<td>TECPLOT</td>
<td>Output for use in the TecPlot graphics package.</td>
</tr>
<tr>
<td>CSV</td>
<td>Produces a comma separated value format.</td>
</tr>
</tbody>
</table>

The <output variable> parameter can be nodal voltages or device currents, as given by

- V(<node name>)
- V(<node name>,<node name>) (the voltage difference between the first and second nodes)
- I(<two-terminal device>)
- Ik(<three-or-more-terminal device>) (the k indicates the device node from which to acquire the value, which is device specific; see the Xyce Reference Guide [3] for details)

Voltage variables specified in the frequency domain have special processing to handle complex results. For file formats which have a complex output capability, the complex value is written. However, for file formats, such as STD and CSV, the complex value is written as two columns of data, the real part followed by the imaginary part. Pseudo names may also be used to compute scalar values from a complex voltage variable. These are given in Table 9.3.

Table 9.3. Pseudo Variables for Complex Output

<table>
<thead>
<tr>
<th>Variable</th>
<th>Definitions</th>
</tr>
</thead>
<tbody>
<tr>
<td>VR(node)</td>
<td>Voltage Real Component</td>
</tr>
<tr>
<td>VI(node)</td>
<td>Voltage Imaginary Component</td>
</tr>
<tr>
<td>VM(node)</td>
<td>Voltage Magnitude</td>
</tr>
<tr>
<td>VP(node)</td>
<td>Voltage Phase, Radians</td>
</tr>
<tr>
<td>VDB(node)</td>
<td>Voltage Magnitude, Decibels</td>
</tr>
</tbody>
</table>
In addition to the above, internal device variables can be specified as an <output variable>. These take the form, \( N(\text{device variable}) \). The format of the device variable called by \( N \) is device-specific, and exact forms can be found in the Xyce Reference Guide [3].

Finally, a parameter or expression may also be specified as an <output variable>. To do so, enclose the parameter or expression within curly braces ({{}}). See Section 4.3 for a description of parameters and expressions.

Example:
```
.PRINT TRAN FILE=Output.prn V(3) I(R3) ID(M5) V(4)
.PRINT DC FORMAT=TECPLLOT FILE=Output.dat V(2) {I(C3)+abs(V(4))*5.0}
.print AC v(3)
```

### 9.2 Additional Output Options

#### 9.2.1 .OPTIONS OUTPUT Command

The main purpose of the .OPTIONS OUTPUT command is to provide control of the interval at which data is written to files specified by .PRINT TRAN commands. This can be especially useful in controlling the size of the results file for simulations that require a large number of time steps. Also, reducing the output frequency from the default, which outputs results at every time-step, provides an additional benefit of improved performance.

The format for controlling the output frequency is:

```
.OPTIONS OUTPUT INITIAL_INTERVAL=<interval> [<t0> <i0> [<t1> <i1> ...]]
```

where INITIAL_INTERVAL=<interval> specifies the starting interval time for output and <tx ix> specifies later simulation times (tx) where the output interval will change to (ix).

The following example shows the output being requested (via the netlist .OPTIONS OUTPUT command) every \( 1 \mu s \) for the first 10\( \mu s \), every \( 1 \mu s \) for the next 10\( \mu s \), and every 5\( \mu s \) for the remainder of the simulation:

Example:
```
.OPTIONS OUTPUT INITIAL_INTERVAL=.1us 10us 1us 20us 5us
```

### 9.3 Output Analysis

#### 9.3.1 .MEASURE

Xyce supports analysis of the data from a simulation through the .MEASURE command. Using .MEASURE one can locate extrema in a voltage or current node, calculate integrals, derivatives,
Fourier transforms, and locate transient events. The general syntax is:

```
.MEASURE <analysis type> <measure name> <measure type> <simulation variable> [qualifiers]
```

where `<analysis type>` is the analysis under which the measure should be calculated. Currently only transient analysis (`.TRAN`) is supported. The `<measure name>` is the name by which this measure is referred. This name is used in the summary output at the end of the simulation to report the value of this measure. The `<measure type>` is the type of calculation which be done. Currently supported measure types are:

- **AVG**: Computes the arithmetic mean.
- **DERIV**: Computes the derivative of a simulation variable.
- **DUTY**: Fraction of time that a given simulation variable is greater than `ON` and does not fall below `OFF` (`ON` and `OFF` are defined later in this section).
- **FOUR**: Calculates the Fourier transform of the solution variable for the `.TRAN` analysis type using the fundamental frequency `AT`. By default, the DC component and first nine harmonics are computed; more can be reported by setting `NUMFREQ` to the desired value. More interpolation points can be used in the Fourier analysis by setting `GRIDSIZE`, which is 200 by default.
- **FREQ**: An estimate of the frequency of a solution variable found by cycle counting during the simulation. Thresholds are defined through the values of `ON` and `OFF`.
- **INTEG**: Calculates the integral of a solution variable through second order numerical integration.
- **MAX**: Returns the maximum value of a solution variable.
- **MIN**: Returns the minimum value of a solution variable.
- **OFF_TIME**: Returns the time that a solution variable is below `OFF`, and not greater than `ON` for the simulation.
- **ON_TIME**: Returns the time that a solution variable is above `ON`, and not less than `OFF` for the simulation.
- **PP**: Returns the difference between the maximum value and the minimum value of a solution variable during the simulation.
- **RMS**: Computes the root-mean-squared value of a solution variable.
- **WHEN**: Returns the time when a solution variable reaches a specified fixed value or is equal to another solution variable.

The `<simulation variable>` specifies a voltage or current node that will be used in this measure, such as `V(a)`. The measure `WHEN` is different from the other measures in that it can take one or two
solution variables. For example, WHEN \( v(a)=5 \) returns the time when \( V(a) \) equals 5. Or, if WHEN \( V(a) = V(b) \) is specified, the time when \( V(a) \) equals \( V(b) \) is returned.

The .MEASURE command can also take optional [qualifiers] that limit the time window when .MEASURE is applied. The [qualifiers] also place numeric limits on what state a value is considered to be in (e.g., ON and OFF), and provide numeric qualification on comparisons of values (e.g., MINVAL). The supported qualifiers are:

- **TD=value** A time delay before which the measurement should be taken or checked.
- **RISE=r|LAST** The number of rises after which the measurement should be checked. If LAST is specified, then the last rise found in the simulation will be used.
- **FALL=f|LAST** The number of falls after which the measurement should be checked. If LAST is specified, then the last fall found in the simulation will be used.
- **CROSS=c|LAST** The number of zero crossings after which the measurement should be checked. If LAST is specified, then the last zero crossing found in the simulation will be used.
- **MINVALUE=value** An allowed absolute difference between the simulation variable and the variable to which it is being compared. This has a default value of 1.0e-12. One may need to specify a larger value to avoid missing the test condition in a transient run.
- **ON=value** The value at which a signal is considered to be on for frequency, duty and on time calculations.
- **OFF=value** The value at which a signal is considered to be off for frequency, duty and off time calculations.

An example of using .measure is shown in the following netlist:

\[
\begin{align*}
VS & 1 0 \text{ SIN}(0 1.0 1\text{KHZ} 0 0) \\
VP & 2 0 \text{ PULSE}(0 1 0.2\text{ms} 0.2\text{ms} 0.2\text{ms} 1\text{ms} 2\text{ms}) \\
R1 & 1 0 100 \\
R2 & 2 0 100 \\
.\text{TRAN} & 0 10\text{ms} \\
.\text{PRINT} & \text{ TRAN \ FORMAT=NOINDEX V(1) V(2)} \\
.\text{MEASURE} & \text{ TRAN \ avg1 AVG V(1)} \\
.\text{MEASURE} & \text{ TRAN \ avg2 AVG V(2)} \\
.\text{MEASURE} & \text{ TRAN \ duty1 DUTY V(1) ON=0.75 \ OFF=0.25}
\end{align*}
\]

The measure \( \text{avg1} \) returns the average of \( v(1) \), and \( \text{avg2} \) returns the average of \( v(2) \). Additionally, \( \text{duty1} \) computes the fraction of time that \( v(1) \) is above 0.75 V, without falling below 0.25 V.
The next netlist provides an example of using the `when` measure:

```
VS 1 0 SIN(0 1.0 1KHZ 0 0)
VP 2 0 PULSE( 0 100 0.2ms 0.2ms 0.2ms 1ms 2ms )
R1 1 0 100
R2 2 0 100
.TRAN 0 10ms 0 1.0e-5
.PRINT TRAN FORMAT=NOINDEX V(1) V(2)
.MEASURE TRAN hit1_75 WHEN V(1)=0.75 MINVAL=0.02
.MEASURE TRAN hit2_75 WHEN V(1)=0.75 MINVAL=0.08 RISE=2
```

In the above netlist, the measure called `hit1_75` will return the simulation time where \( v(1) \) reaches a value of 0.75, while `hit2_75` returns the second time that \( v(1) \) reaches a value of 0.75. The `MINVAL` option acts at an absolute tolerance in this case. So, the above measure statements are more exactly interpreted as `hit1_75` is the simulation time when \( v(1) \) reaches a value of 0.75 ± 0.02 and `hit2_75` is the simulation time when \( v(1) \) reaches a value of 0.75 ± 0.08 on its second rise.

9.3.2 .FOUR

Fourier analysis can be performed as a part of the transient analysis using the `.FOUR` command. The general syntax is:

```
.FOUR freq ov1 <ovn>*
```

where `freq` is the fundamental frequency used for Fourier analysis. The `ov1` parameter is the desired solution variable to be analyzed, specifically:

- \( V(<\text{node name}>) \)
- \( V(<\text{node name}>,<\text{node name}>) \) (the voltage difference between the first and second nodes)
- \( I(<\text{two-terminal device}>) \)
- \( I_k(<\text{three-or-more-terminal device}>) \) (see the `.PRINT` section, 9.1.1 for more detail)
- \( N(\text{device variable}) \) (see the `.PRINT` section, 9.1.1 for more detail)
- The pseudo-variables given in Table 9.3 for complex output handling

At least one solution variable must be specified, but Fourier analysis can be performed on several solution variables for each fundamental frequency, `freq`. Multiple `.FOUR` lines may be used in a
netlist. All results from Fourier analysis will be returned to the user in a file with the same name as the netlist file suffixed with a .four.

Fourier analysis is performed over the last period (1/freq) of the transient simulation. The dc component and the first nine harmonics are calculated. The number of harmonics computed by .FOUR is static. This is the main difference between .FOUR and the Fourier analysis in .MEASURE, where the later will allow the user to select the number of harmonics. The default options for the Fourier analysis in .MEASURE is the same as .FOUR. For instance, these two lines will result in the same Fourier analysis:

```
.FOUR 20MEG V(2)
.MEASURE TRAN FOURV2 FOUR V(2) AT=20MEG
```

The Fourier analysis in .MEASURE will allow for more harmonics to be computed using the NUMFREQ option and more interpolation points to be used in the Fourier analysis with GRIDSIZE. For instance, to compute twenty harmonics (including the dc component), the previous .MEASURE line can be amended to:

```
.MEASURE TRAN FOURV2 FOUR V(2) AT=20MEG NUMFREQ=20
```

To increase the number of interpolation points from 200, which is the default, to 500, the line can be amended to:

```
.MEASURE TRAN FOURV2 FOUR V(2) AT=20MEG NUMFREQ=20 GRIDSIZE=500
```

For maximum accuracy of the Fourier analysis, it is recommended that the time integration option DELMAX should be set to period/100. This is the preferred approach to improving the accuracy of the Fourier analysis over increasing the number of interpolation points.

### 9.3.3 .SENS

The .SENS command instructs Xyce to calculate the steady-state (DC) sensitivities of an output expression with respect to a specified list of circuit parameters. The syntax for the command is as follows:

- `.SENS objfunc=<output expression> param=<circuit parameter(s)>`
- `.options SENSITIVITY [direct=<1 or 0>] [adjoint=<1 or 0>]`

The parameter objective function parameter, objfunc, is required. The list of circuit parameters must have at least one entry as well. Xyce can compute a direct sensitivity, an adjoint sensitivity, or both. An example of using .SENS is shown in the following netlist:
R1 A B 10.0
R2 B 0 10.0

* input nodes:
Va A 0 5

.dc Va 5 5 1
.print dc v(A) v(B)

.SENS objfunc={0.5*(V(B)-3.0)**2.0} param=R1:R,R2:R
.options SENSITIVITY direct=1 adjoint=1

.END

The output for this particular example is:

Direct Sensitivities:
R1:R dOdp = 6.2500e-02
R2:R dOdp = -6.2500e-02

Adjoint Sensitivities:
R1:R dOdp = 6.2500e-02
R2:R dOdp = -6.2500e-02

The .SENS capability can only be used for DC calculations. If performing a sweep, it computes the sensitivities for the final sweep step.

9.4 Graphical Display of Solution Results

Although Xyce does not provide integrated graphical display options, it produces output in a form that may readily be used with commonly available graphical tools, including TecPlot, gnuplot, and MS Excel (see figure 9.1 for an example plot using TecPlot, http://www.amtec.com). The standard Xyce print format (FORMAT=STD or FORMAT=NOINDEX) is well suited for use with gnuplot. Comma separated variable (FORMAT=CSV) is the best choice for import into Excel. FORMAT=TECPLT produces output specifically targeted at the TecPlot tool. And by using the FORMAT=PROBE option to the .PRINT command, Xyce is able to output .csd files that can be read by the PSpice Probe utility to view the results. See the PSpice Users Guide [4] for instructions on using the Probe tool, and the Xyce Reference Guide [3] for details on the .PRINT command options.
Figure 9.1. TecPlot plot of diode clipper circuit transient response from Xyce .prn file.
Chapter Overview

This chapter provides guidance for running a parallel version of Xyce, and includes the following sections:

- Section 10.1 Introduction
- Section 10.2 Problem Size
- Section 10.3 Linear Solver Options
- Section 10.4 Transformation Options
10.1 Introduction

Xyce is designed from the ground up to be distributed-memory parallel, supported by the message-passing interface (MPI) standard. Although many of the issues pertinent to running in parallel are still being researched, Xyce is mature enough that some general principles have emerged for efficiently running problems in a parallel environment. In addition to the information in this chapter, reference [12] provides supplemental information about Xyce parallel performance.

Parallel simulations must be run from the command line. Section [2.2.1] provides information about the parallel execution syntax for Xyce.

10.2 Problem Size

Running Xyce in parallel is often useful for circuits with thousands of devices or more. However, due to the overhead of interprocessor communication, there is an optimal number of processors that will achieve the best performance. This number is dependent upon many factors, including the number and type of devices, topology of the circuit, and the characteristics of the computing architecture. It is difficult to know a priori what this optimal number of processors is. However, it is apparent when that optimal number is exceeded because, as the number of processors is increased, the total simulation time will also increase. This is due to the increasing amount of required communication and decreasing amount of work per processor. In other words, the benefit of distributing the problem is outweighed by the communication overhead, so increasing the processor count beyond this optimal point is counterproductive.

10.2.1 Ideal Problem Size

In general, a circuit needs to be relatively large to take full advantage of the parallel capability of Xyce. However, parallelism is achieved in two distinct phases of the code: the device evaluation and the linear solve. The device evaluation is, as the name implies, the evaluation of all the device equations in order to compute the residual vector and Jacobian entries for Newton’s method. Xyce distributes the number of devices over the number of processors in parallel, so their evaluation enables speedups in the total simulation time even for thousands of devices.

The linear solve phase is more computationally complex. The Jacobian matrix generated by most circuits is sparse and has heterogeneous structure, in that there is not a regular sparsity pattern in the matrix nonzeros. Sparse, direct linear solvers have proven to be efficient on these types of linear systems up into the tens to hundreds of thousands of unknowns. They become less efficient for linear systems in the hundreds of thousands of unknowns. This is where iterative linear solvers can provide scalable performance because of their inherent parallelism. Unfortunately, the effectiveness of iterative linear solvers is dependent upon preconditioning the linear system (see Section 10.3.5). The benefit of direct over iterative linear solvers is that they rarely fail to compute a solution, so direct linear solvers are the more robust option for enabling simulations to complete.

In general, there are three modes in which Xyce can be executed: “Serial load, serial solve”, “Parallel load, serial solve”, and “Parallel load, parallel solve”. Each of these modes optimizes the
amount of available parallelism for a given linear system size, see Table 10.1 for a summary. The “load” refers to the device evaluation phase combined with the assembly of the Jacobian matrix and residual vector, the “solve” refers to the linear solve phase. “Serial load, serial solve” is the only mode of computation that a serial version of Xyce will perform, but it can also be obtained in a parallel version of Xyce by using only one MPI processor. Both the “Parallel load” simulation modes require a parallel build of Xyce, where the linear solver method can be a direct method (“serial solve”) or iterative method (“parallel solve”) using the options discussed in Section 10.3. Hybrid linear solvers, which combine the best attributes of both direct and iterative methods, provide both a robust and scalable option. They are not reflected in Table 10.1, but more information about these types of linear solvers will be discussed in Section 10.3.6.

Table 10.1. Xyce simulation modes.

<table>
<thead>
<tr>
<th>Mode</th>
<th>Linear System Size</th>
<th>Reason</th>
</tr>
</thead>
<tbody>
<tr>
<td>“Serial load, serial solve”</td>
<td>$10^0 - 10^2$</td>
<td>MPI overhead cannot speed up device evaluation or linear solve.</td>
</tr>
<tr>
<td>“Parallel load, serial solve”</td>
<td>$10^3 - 10^4$</td>
<td>Distributed device evaluations can speed up the simulation, but iterative linear solvers are not more efficient than direct methods.</td>
</tr>
<tr>
<td>“Parallel load, parallel solve”</td>
<td>$10^5$ or more</td>
<td>Distributed device evaluations can speed up the simulation and so can iterative linear solvers, if an efficient preconditioner is available.</td>
</tr>
</tbody>
</table>

10.2.2 Smallest Possible Problem Size

Circuits consist of a discrete set of components (voltage nodes, devices, etc.). For parallel simulation, it is preferable that Xyce be able to put at least one discrete component of the problem on each processor. In practice, this means the circuit should be distributed across fewer processors than the number of nodes and devices it contains.

10.3 Linear Solver Options

The different linear solvers available in Xyce are:

- KLU
- SuperLU and SuperLU DIST (optional)
- The AztecOO iterative solver library
- The Belos iterative solver library
AztecOO and Belos are the parallel iterative solvers and KLU and SuperLU (optional) are the serial direct solvers that are available for both serial and parallel builds of Xyce. If KLU or SuperLU is used with a parallel version of Xyce, the devices are evaluated and linear problem is assembled in parallel, but the linear system is solved in serial on processor 0. This can be quite effective for circuits with tens of thousands of devices or fewer (see Table 10.1). The ShyLU hybrid linear solver, which combines the robustness of a direct solver with the scalability of an iterative solver, will be discussed in Section 10.3.6.

The user can specify the solver through the .OPTIONS LINSOL control line in the netlist. The default linear solver used by Xyce is described in Table 10.2. By default, a parallel version of Xyce uses AztecOO as the linear solver when the linear system is larger than a thousand unknowns. For any linear system smaller than a thousand unknowns, Xyce uses KLU as the linear solver. A serial version of Xyce uses KLU as its default linear solver. To use a solver other than the default the user needs to add the option “TYPE=<solver>” to the .OPTIONS LINSOL control line in the netlist, where <solver> is ’KLU,’ ’SUPERLU,’ ’SUPERLUDIST,’ ’AZTECOO,’ ’BELOS,’ or ’SHYLU.’

Table 10.2. Xyce default linear solver.

<table>
<thead>
<tr>
<th>Solver</th>
<th>Version</th>
<th>Linear System Size</th>
</tr>
</thead>
<tbody>
<tr>
<td>KLU</td>
<td>Serial</td>
<td>all</td>
</tr>
<tr>
<td>KLU</td>
<td>Parallel</td>
<td>1 – 1000 unknowns</td>
</tr>
<tr>
<td>AztecOO</td>
<td>Parallel</td>
<td>1001+ unknowns</td>
</tr>
</tbody>
</table>

10.3.1 KLU

KLU is a serial, sparse direct solver native to the Amesos package in Trilinos [13] and is the default solver for serial builds of Xyce. KLU is the default solver for small circuits in parallel builds of Xyce as well, but this requires the linear system to be solved on one processor and the solution communicated back to all processors. As long as the linear system can fit on one processor, KLU is often a superior approach to using an iterative linear solver.

Some of the solver parameters for KLU can be altered through the .OPTIONS LINSOL control line in the netlist. Table 10.3 lists solver parameters and their default values for KLU.

10.3.2 SuperLU and SuperLU DIST

SuperLU is a serial, sparse direct solver and SuperLU DIST is a parallel, sparse direct solver with an interface in the Amesos package. SuperLU and SuperLU DIST support are optionally built in Xyce, so they are not available by default in any Xyce build or provided binary. Furthermore, to enable SuperLU and SuperLU DIST support in Xyce, it is necessary to build SuperLU and SuperLU DIST support in Amesos/Trilinos. Similar to KLU, SuperLU can be used in a parallel
Table 10.3. KLU linear solver options.

<table>
<thead>
<tr>
<th>Option</th>
<th>Description</th>
<th>Default Value</th>
</tr>
</thead>
<tbody>
<tr>
<td>KLU_REPIVOT</td>
<td>Recompute pivot order each solve</td>
<td>1 (true)</td>
</tr>
<tr>
<td>OUTPUT_LS</td>
<td>Write out linear systems solved by KLU to file every # solves</td>
<td>0 (false)</td>
</tr>
<tr>
<td>OUTPUT_BASE_LS</td>
<td>Write out linear systems before any transformations to file every # solves</td>
<td>0 (false)</td>
</tr>
<tr>
<td>OUTPUT_FAILED_LS</td>
<td>Write out linear systems KLU failed to solve to file</td>
<td>0 (false)</td>
</tr>
</tbody>
</table>

version of Xyce, but the linear system is solved on one processor. SuperLU DIST can only be used in a parallel version of Xyce, the Amesos interface handles the redistribution of the matrix into the format required by SuperLU DIST. Xyce does not allow modifications to SuperLU and SuperLU DIST solver parameters.

10.3.3 AztecOO

AztecOO is a package in Trilinos [13] that offers an assortment of iterative linear solver algorithms. Xyce uses the Generalized Minimal Residual (GMRES) method [14] from this suite of iterative solvers. Some of the solver parameters for GMRES can be altered through the 'OPTIONS LINSL' control line in the netlist. Table 10.4 provides a list of solver parameters for AztecOO and their default values.

Table 10.4. AztecOO linear solver options.

<table>
<thead>
<tr>
<th>Option</th>
<th>Description</th>
<th>Default Value</th>
</tr>
</thead>
<tbody>
<tr>
<td>AZ_max_iter</td>
<td>Maximum allowed iterations</td>
<td>500</td>
</tr>
<tr>
<td>AZ_tol</td>
<td>Iterative solver (relative residual) tolerance</td>
<td>1.0e-12</td>
</tr>
<tr>
<td>AZ_kspace</td>
<td>Krylov subspace size</td>
<td>500</td>
</tr>
<tr>
<td>OUTPUT_LS</td>
<td>Write out linear systems solved by AztecOO to file every # solves</td>
<td>0 (false)</td>
</tr>
<tr>
<td>OUTPUT_BASE_LS</td>
<td>Write out linear systems before any transformations to file every # solves</td>
<td>0 (false)</td>
</tr>
</tbody>
</table>

Common AztecOO Warnings

If Xyce is built with the verbosity enabled for the linear algebra package, it is not uncommon to see warnings from AztecOO usually indicating the solver returned unconverged due to a numerical issue.
**NOTE:** AztecOO warnings *do not* indicate the entire simulation has failed. **Xyce** uses a hierarchy of solvers so if the iterative linear solver fails, the nonlinear solver or time integrator will usually make adjustments and attempt the step again; so the warnings can often be ignored. If the entire simulation eventually fails (i.e., gets a “time-step-too-small” error), then the AztecOO warnings might contain clues as to what went wrong.

The simplest reason for AztecOO to return unconverged would be when the maximum number of iterations is reached, resulting in the following warning:

***************************************************************
Warning: maximum number of iterations exceeded without convergence
***************************************************************

Another reason AztecOO may return unconverged is when the GMRES Hessenberg matrix is ill-conditioned, which is usually a sign that the matrix and/or preconditioner is nearly singular, resulting in the following warning:

***************************************************************
Warning: the GMRES Hessenberg matrix is ill-conditioned. This may indicate that the application matrix is singular. In this case, GMRES may have a least-squares solution.
***************************************************************

It is also common to lose accuracy when either the matrix or preconditioner, or both, are nearly singular. GMRES relies on an estimate of the residual norm, called the recursive residual, to determine convergence. **Xyce** uses the recursive residual instead of the actual residual for computational efficiency. However, numerical issues can cause the recursive residual to differ from the actual residual. When AztecOO detects but cannot rectify this situation, it outputs the following warning:

***************************************************************
Warning: recursive residual indicates convergence though the true residual is too large.
***************************************************************

Sometimes this occurs when storage is overwritten (e.g. the solution vector was not dimensioned large enough to hold external variables). Other times, this is due to roundoff. In this case, the solution has either converged to the accuracy of the machine or intermediate roundoff errors occurred preventing full convergence. In the latter case, try solving again using the new solution as an initial guess.

***************************************************************
10.3.4 Belos

Belos is a package in Trilinos [13] that offers an assortment of iterative linear solver algorithms. Many of the algorithms available in Belos can also be found in AztecOO. However, Belos offers a few computational advantages because its solvers are implemented using templated C++. In particular, AztecOO can solve linear systems only in double-precision arithmetic, while Belos can solve linear systems that are complex-valued or in extended-precision arithmetic. At this time, Xyce is using a subset of Belos capabilities, the default method is GMRES, and the interface to Belos will recognize most of the AztecOO linear solver options, as shown in Table 10.5.

<table>
<thead>
<tr>
<th>Option</th>
<th>Description</th>
<th>Default Value</th>
</tr>
</thead>
<tbody>
<tr>
<td>AZ_max_iter</td>
<td>Maximum allowed iterations</td>
<td>500</td>
</tr>
<tr>
<td>AZ_tol</td>
<td>Iterative solver (relative residual)</td>
<td>1.0e-12</td>
</tr>
<tr>
<td>AZ_kspace</td>
<td>Krylov subspace size</td>
<td>500</td>
</tr>
<tr>
<td>OUTPUT_LS</td>
<td>Write out linear systems solved by Belos to file every # solves</td>
<td>0 (false)</td>
</tr>
<tr>
<td>OUTPUT_BASE_LS</td>
<td>Write out linear systems before any transformations to file every # solves</td>
<td>0 (false)</td>
</tr>
</tbody>
</table>

Table 10.5. Belos linear solver options.

10.3.5 Preconditioning Options

Iterative linear solvers often require the assistance of a preconditioner to efficiently compute a solution of the linear system

\[ Ax = b \]  \hspace{1cm} (10.1)

to the requested accuracy. A preconditioner, \( M \), is an approximation to the original matrix \( A \) that is inexpensive to solve. Then (10.1) can be rewritten to include this (right) preconditioner as

\[ AM^{-1}y = b, \]  \hspace{1cm} (10.2)

where \( x = M^{-1}y \) is the solution to the original linear system. If \( M = A \), then the solution to the linear system is found in one iteration. In practice, \( M \) is a good approximation to \( A \), then it will take few iterations to compute the solution of the linear system to the requested accuracy. By default, Xyce uses a non-overlapped additive Schwartz preconditioner with an incomplete LU factorization on each subdomain [13]. The parameters of the incomplete LU factorization are found in Table [10.6]. This is a simple preconditioner that always works, but is not always the most effective, so other preconditioning options will be presented in this section.

Xyce provides access to preconditioning packages in Trilinos [13], such as Ifpack and ML (optionally), through an expanded preconditioning interface. If modifications to the preconditioner are
necessary, the user may specify the preconditioner through the `.OPTIONS LINSOL` control line in the netlist. Table 10.6 provides a list of preconditioner parameters and their default values.

**Table 10.6.** Preconditioner options.

<table>
<thead>
<tr>
<th>Option</th>
<th>Description</th>
<th>Default Value</th>
</tr>
</thead>
<tbody>
<tr>
<td>prec_type</td>
<td>Preconditioner</td>
<td>Ifpack</td>
</tr>
<tr>
<td>AZ_ilut_fill</td>
<td>ILU fill level</td>
<td>2.0</td>
</tr>
<tr>
<td>AZ_drop</td>
<td>ILU drop tolerance</td>
<td>1.0e-3</td>
</tr>
<tr>
<td>AZ_overlap</td>
<td>ILU subdomain overlap</td>
<td>0</td>
</tr>
<tr>
<td>AZ_athresh</td>
<td>ILU absolute threshold</td>
<td>0.0001</td>
</tr>
<tr>
<td>AZ_rthresh</td>
<td>ILU relative threshold</td>
<td>1.0001</td>
</tr>
<tr>
<td>ML_MAX_LEVEL</td>
<td>ML maximum allowable levels</td>
<td>5</td>
</tr>
<tr>
<td>USE_IFPACK_FACTORY</td>
<td>Additive Schwarz w/ KLU subdomain solve</td>
<td>0 (false)</td>
</tr>
<tr>
<td>USE_AZTEC_PRECOND</td>
<td>Use native ILU from AztecOO package</td>
<td>0 (false)</td>
</tr>
</tbody>
</table>

In practice, the choice of an effective preconditioner is highly problem dependent. By default, Xyce provides a preconditioner that works for most circuits, but is not the best preconditioner for all circuits. One simple modification to the default preconditioner that often makes it more effective is the use of a sparse direct solver on each subdomain, instead of an inexact factorization:

`.OPTIONS LINSOL USE_IFPACK_FACTORY=1`

This preconditioner will fail if there is a singular subdomain matrix because the KLU solver on that subdomain will fail. If numerical difficulties are not encountered during the simulation, this preconditioner is superior to inexact factorizations. A more advanced preconditioner that has been effective for certain types of circuits uses the block triangular form (BTF) permutation of the original matrix before generating the additive Schwartz preconditioner. This preconditioner, which is published in [16], will be presented in Section 10.4.4.

### 10.3.6 ShyLU

ShyLU is a package in Trilinos [13] that provides a hybrid linear solver designed to be a black-box algebraic solver [17]. ShyLU support is optionally built in Xyce, so it is not available by default in any Xyce build or provided binary. Furthermore, to enable ShyLU support in Xyce, it is necessary to build the ShyLU package in Trilinos.

ShyLU is hybrid in both the parallel programming sense - using MPI and threads - and in the mathematical sense - using features from direct and iterative methods. Xyce uses ShyLU as a global Schur complement solver [15]. This solver can be expensive, but also has proven to be a robust and scalable approach for circuit matrices [18].

ShyLU is under active development and testing in Xyce, so a minimum number of options are provided to the user for controlling this flexible solver. For instance, the diagonal blocks of the partitioned matrix are solved using KLU, while the Schur complement is solved using an iterative method (AztecOO’s GMRES specifically). The matrix partitioning is generated using a wide
separator, which is a conventional vertex separator where all the vertices that are adjacent to the separator in one of the subgraphs are added in. This solution approach is static, the only options that can be modified are shown in Table 10.7. This includes the maximum number of iterations and solver tolerance used by GMRES and the dropping threshold that ShyLU uses to generate a preconditioner for GMRES.

<table>
<thead>
<tr>
<th>Option</th>
<th>Description</th>
<th>Default Value</th>
</tr>
</thead>
<tbody>
<tr>
<td>AZ_max_iter</td>
<td>Maximum allowed iterations</td>
<td>30</td>
</tr>
<tr>
<td>AZ_tol</td>
<td>Iterative solver (relative residual) tolerance</td>
<td>1.0e-12</td>
</tr>
<tr>
<td>ShyLU_rthresh</td>
<td>Relative dropping threshold for Schur complement</td>
<td>1.0e-3</td>
</tr>
<tr>
<td>OUTPUT_LS</td>
<td>Write out linear systems solved by ShyLU to file every # solves</td>
<td>0 (false)</td>
</tr>
<tr>
<td>OUTPUT_BASE_LS</td>
<td>Write out linear systems before any transformations to file every # solves</td>
<td>0 (false)</td>
</tr>
</tbody>
</table>

Table 10.7. ShyLU linear solver options.

10.4 Transformation Options

Transformations are often used to permute the original linear system to one that is easier or more efficient for direct or iterative linear solvers. Xyce has many different permutations that can be applied to remove dense rows and columns from a matrix, reduce fill-in, find a block triangular form, or partition the linear system for improved parallel performance.

10.4.1 Removing Dense Rows and Columns

The transformation that reduces the linear system through removal of all rows and columns with single non-zero entries in the matrix is called singleton filtering. The values associated with these removed entries can be resolved in a pre- or post-processing phase with the linear solve. A by-product of this transformation is a more tractable and sparse linear system for the load balancing and linear solver algorithms. This functionality can be turned on by adding ‘TR_SINGLETON_FILTER=1’ to the ‘.OPTIONS LINSOL’ control line in the netlist. This option is enabled by default whenever iterative solvers are used in Xyce.

10.4.2 Reordering the Linear System

Approximate Minimum Degree (AMD) ordering is a symmetric permutation that reduces the fill-in for direct factorizations. If given a nonsymmetric matrix \( A \), the transformation computes the AMD ordering of \( A + A^T \). This functionality may be turned on by adding ‘TR_AMD=1’ to the ‘.OPTIONS LINSOL’ control line in the netlist. For parallel builds of Xyce, AMD ordering is enabled by default whenever iterative solvers are used. In parallel, the AMD ordering is performed only on the local
graph for each processor, not the global graph. This is to reduce the fill-in for the incomplete LU factorization used by the additive Schwartz preconditioner, see Section 10.3.5.

10.4.3 Partitioning the Linear System

Partitioning subdivides the linear system and then distributes it to the available processors. A good partition can have a dramatic effect on the parallel performance of a circuit simulation tool. There are two key components to a good partition:

- **Effective load balance**
- **Minimizing communication overhead.**

An effective load balance ensures the computational load of the calculation is equally distributed among available processors. Minimizing communication overhead seeks to distribute the problem in a way to reduce impacts of underlying message passing during the simulation run. For runs with a small number of devices per processor the communication overhead becomes the critical issue, while for runs with larger numbers of devices per processor the load balancing becomes more important.

**Xyce** provides for graph and hypergraph partitioning via the **Zoltan** library of parallel partitioning heuristics integrated into **Xyce**. The Isorropia package in Trilinos provides access to **Zoltan** and can be controlled through the ‘.OPTIONS LINSOL’ control line in the netlist. Table 10.8 provides the partitioning options and their default parameters. For parallel builds of **Xyce**, when iterative solvers are used, **Isorropia** is enabled by default to use graph partitioning via ParMETIS. The linear system is statically load balanced at the beginning of the simulation based on the graph of the Jacobian matrix.

**Table 10.8.** Partitioning options.

<table>
<thead>
<tr>
<th>Option</th>
<th>Description</th>
<th>Default Value</th>
</tr>
</thead>
<tbody>
<tr>
<td>TR_PARTITION</td>
<td>Partitioning package</td>
<td>0 (none), serial,</td>
</tr>
<tr>
<td></td>
<td></td>
<td>1 (Isorropia), parallel</td>
</tr>
<tr>
<td>TR_PARTITION_TYPE</td>
<td>Isorropia partitioner type</td>
<td>GRAPH</td>
</tr>
</tbody>
</table>

**Xyce** includes an expanded partitioning interface to allow the user to access multiple partitioners through Isorropia. Users may change the partitioner provided by adding ‘TR_PARTITION_TYPE’ to the ‘.OPTIONS LINSOL’ control line in the netlist. There are two options for partitioning: graph (‘TR_PARTITION_TYPE=GRAPH’) and hypergraph (‘TR_PARTITION_TYPE=HYPERGRAPH’). Occasionally it is desirable to turn off the partitioning option, even for parallel simulations. To do so, users can add the ‘TR_PARTITION=0’ to the ‘.OPTIONS LINSOL’ control line.

These techniques can be very effective for improving the efficiency of the iterative linear solvers. See the **Zoltan User Guide** [19] for more details.
10.4.4 Permuting the Linear System to Block Triangular Form

The block triangular form (BTF) permutation is often useful for direct and iterative solvers, enabling a more efficient computation of the linear system solution. In particular, the BTF permutation has shown promise when it is combined with an additive Schwartz preconditioner (see Section 10.3.5) in the simulation of circuits with unidirectional flow.

The global BTF transformation computes the permutation of the linear system to block triangular form, and uses the block structure to partition the linear system. The partitioning can be a simple linear distribution of block rows, ‘TR_GLOBAL_BTF=1’, or a hypergraph partitioning of block rows, ‘TR_GLOBAL_BTF=2.’ As the global BTF transformation includes elements of other transformations, it is imperative to turn off other linear solver options. To use the global BTF, the linear solver control line in the netlist should contain:

```
.OPTIONS LINSOL TR_GLOBAL_BTF=<1,2> TR_SINGLETON_FILTER=1 + TR_AMD=0 TR_PARTITION=0
```

This transformation is only useful in parallel when using a preconditioned iterative solver. It is often more effective when combined with the exact factorization of each subdomain, given by the ‘USE_IFPACK_FACTORY=1’ option. In practice, the structure that this transformation takes advantage of is found in CMOS memory circuits [16].
11. Handling Power Node Parasitics

Chapter Overview

This chapter includes the following sections:

- Section 11.1, *Power Node Parasitics*
- Section 11.2, *Two Level Algorithms Overview*
- Section 11.3, *Examples*
- Section 11.4, *Restart*
11.1 Power Node Parasitics

Parasitic elements (R, L, C) are frequently required for circuit simulations to capture important circuit behavior. Most parasitic elements (interconnect, etc.) can be added to netlists without causing any difficulties for the Xyce solvers. Small circuits in particular are very robust to the addition of parasitic elements. Larger circuits, however, that must be simulated in parallel will in general tend to have more solver difficulties with the addition of parasitic devices. Of particular note are parasitic elements attached to the power and/or ground nodes of large digital circuits. An example of this is shown in figure 11.1. As these nodes tend to be highly connected, they can potentially have very high impact on solver difficulties.

One of the parallel algorithms used by Xyce is called singleton removal [16], which is applied at the linear solver level and is crucial for getting many large circuits to run in parallel. This algorithm takes advantage of the fact that, in circuit simulation, some solution values are available explicitly, rather than being a quantity that needs to be calculated as the solution to a particular equation. In circuit simulation, such quantities are usually the values of independent sources. For instance, the presence of an independent voltage source at a particular node in a circuit fixes the voltage at that node to be the value of the independent source; therefore, equations reflecting the value of the voltage at that particular node do not have to be added to the set of linear equations used (in part) to determine the voltages at all the nodes in the circuit. The technique of fixing such node voltages without including them in the rest of the linear solve can be handled in a preprocessing phase referred to as the singleton removal phase.

When simulating in parallel, singleton removal is crucial as some voltage sources (especially power supplies in digital circuits) are connected to hundreds or thousands of circuit nodes. This presents a big problem in parallel because having numerous connections can often mean a communication bottleneck during the linear solve. Using singleton removal eliminates that bottleneck.

While singleton removal can result in a great improvement for circuits with ideal power supplies, for circuits with nonideal power supplies, the communication bottleneck remains. Once parasitic elements are placed between the power supply and the rest of the circuit, it is only the voltage at the circuit node directly connected to the independent source that can be removed via singleton removal. Other nodes connected to this independent source through parasitic elements have

![Figure 11.1](image.png)

**Figure 11.1.** Power node parasitics example. NOTE: An RLC network sits between the VDD, VSS sources and the main circuit, so these highly connected nodes cannot be removed with a singleton filter.
voltages that must now be solved for directly.

## 11.2 Two Level Algorithms Overview

Fortunately, Xyce [12] provides a workaround that allows power node parasitics to be included in large circuits without breaking singleton removal. The workaround requires the use of a two-level Newton solve, in which the problem is divided into two very separate pieces, each for the most part treated as an entirely separate circuit with minimal coupling terms linking the pieces together.

For power-node problems, two-level users will typically split the netlist into "top" and "inner" netlists. The top netlist contains the power node parasitics and the ideal voltage sources, and very little else. The inner circuit should contain the rest of the circuit. Xyce couples the two circuits through an "EXT" (external) device in the top circuit, and two or more independent voltage sources on the inner circuit. The values on the inner voltages are imposed from the top circuit, and the currents and conductances of the EXT device come from the inner circuit.

Xyce will construct a different linear system for each circuit. As such, the inner circuit will appear to have independent sources, allowing the singleton removal algorithm to work.

Since at least the 1980s, literature has included the two-level Newton algorithm, although mostly as it applied to circuit-device simulation. [20] and [21] provide a mathematical description, while [12] provides more information about the Xyce implementation.

## 11.3 Examples

### 11.3.1 Explanation and Guidance

Figures 11.2 and 11.3 provide an example of a circuit that uses the two level algorithm. The top circuit (compTop.cir) (figure 11.2) invokes the inner circuit (complInner.cir) with the extern device, y1. To run this circuit, the user will only specify the top circuit on the command line:

```
Xyce compTop.cir <return>
```

The extern device (YEXT y1 sits between the contents of compTop.cir and complInner.cir and is connected to two nodes in the top-level circuit, DD1 and SS1. From the perspective of compTop.cir, the YEXT y1 device looks like a nonlinear two-terminal resistor, which is the equivalent of the entire inner circuit.

In the inner circuit, Xyce applies nodes DD1 and SS1 though the independent sources Vconnect0000 and Vconnect0001. By convention, the inner circuit must contain and independent voltage source for each node to which the EXT device is connected. The default naming convention requires that these sources be named vconnectxxxx, with xxxx being a four-digit integer starting at 0000.

**NOTE:** The .tran statement on the inner circuit must match the .tran statement on the top circuit. The same is true for .DC analysis. Also, as both circuit files have their own .print statements,
Figure 11.2. Two-level top netlist example.

both will produce *.prn output files.

The coupling between the top and inner layers requires extra linear solves, so when using this algorithm the code will run more slowly. In general, one can expect a factor-of-two slowdown, for circuits that can be run either as conventional or two-level simulations. So, in practice this algorithm should only be applied when it is really needed (i.e., when conventional simulations fail).

Finally, when using this method, one must take particular care with file names. In practice, a Xyce user may frequently change netlist file names to reflect new details about the run. When this happens, the name of the netlist invoked on the **YEXT** **y1** line must be changed. Failure to do so may result in using the wrong file for the inner simulation.

11.4 Restart

Restart works with the two-level algorithm. However, as the two-level algorithm involves two separate netlist input files, a two-level restart requires a separate restart file for each phase of the problem. So, the two files (e.g., **compTop.cir** and **compInner.cir**) require **.options restart** statements, and the statements in the two files must be consistent with each other.

Currently, the user must enforce this because the code does not make any attempt to check consistency between the top and inner file **".options restart"** statements.
Figure 11.3. Two-level inner netlist example.
12. Specifying Initial Conditions

Chapter Overview

This chapter includes the following sections:

- Section 12.1 Initial Conditions Overview
- Section 12.2 Device Level IC= Specification
- Section 12.3 .IC and .DCVOLT Initial Condition Statements
- Section 12.4 .SAVE Statements
- Section 12.5 DCOP Restart
- Section 12.6 UIC and NOOP
12.1 Initial Conditions Overview

Xyce provides several different options for users to set an initial condition. Reasons for setting initial conditions include, but are not limited to:

- Improving the robustness of the DCOP solution
- Optimizing performance by reusing DCOP solution of a previous run to start new transient runs
- Setting an initial state for a digital circuit
- Initiating an oscillator circuit.

As noted, setting initial conditions can be particularly useful for multistate digital circuits. Figure 12.1 provides an example result demonstrating how initial conditions can be used to set the state of a digital circuit. In this case, obtaining the state purely through transient simulation can be time-consuming and often is not practical.

![Figure 12.1](image)

**Figure 12.1.** Example result with (left) and without (right) IC=preset. NOTE: The preset example starts in the initial state directly out of the DCOP calculation, while the nonpreset example requires a long transient to equilibrate.
12.2 Device Level IC= Specification

Many devices in Xyce support setting initial junction voltage conditions on the device instance line with the IC= keyword. This is frequently used to set the state of digital circuits. Figure 12.2 presents a simple inverter example demonstrating the use of IC= on a BSIMSOI device.

While many circuit simulators have a similar IC= capability, Xyce implementation differs in some important respects. For any device with an IC= statement, Xyce enforces the junction drop in parallel with the device junction as a voltage source in parallel with the device. Xyce then applies the parallel voltage source through the DCOP calculation, and then removes it prior to the beginning of the transient. This strongly enforces the requested junction drop, meaning that if the DCOP converges, the requested voltage drop will in the solution. In many other circuit codes, Xyce applies IC= as a weaker constraint, with the intent of improving DCOP calculation robustness.

IC= can be applied to the following devices: BSIM3, BSIM4, BSIMSOI, Capacitor, and Inductor.

---

Figure 12.2. Example netlist with device-level IC=.

```
MOS LEVEL=10 INVERTER WITH IC=

.subckt INV IN OUT VDD GND
MN1 OUT IN GND GND GND NMOS w=4u l=0.15u IC=2,0
MP1 OUT IN VDD GND VDD PMOS w=10u l=0.15u
.ends

.tran 20ns 30us
.print tran v(vout) v(in)+1.0 v(1)

VDDdev VDD 0 2V
RIN IN 1 1K
VIN1 1 0 2V PULSE (2V 0V 1.5us 5ns 5ns 1.5us 3.01us)
R1 VOUT 0 10K
C2 VOUT 0 0.1p
XINV1 IN VOUT VDD 0 INV
.MODEL NMOS NMOS ( LEVEL = 10 )
.MODEL PMOS PMOS ( LEVEL = 10 )

.END
```
.IC and .DCVOLT are equivalent methods for specifying initial conditions. How Xyce applies them, however, depends on whether the UIC parameter is present on the .TRAN line. If UIC is not specified, then Xyce applies the conditions specified by a .IC and .DCVOLT statements throughout the DCOP phase, ensuring the specified values will be the solved values at the end of the DCOP calculation. Xyce allows unspecified variables to find their computed values, consistent with the imposed voltages.

If UIC is specified on the .TRAN line, then Xyce skips the DCOP calculation altogether, and uses the values specified on .IC and .DCVOLT lines as the initial values for the transient calculation. Unspecified values are set to zero.

For the UIC and non-UIC cases, Xyce ignores specified values that do not correspond to existing circuit variables. Also, the .IC capability can only set voltage values, not current values.

12.3.1 Syntax

```
.IC V(node1) = val1 <V(node2) = val2> ...
.DCVOLT V(node1) = val1 <V(node2) = val2> ...
```

where: val1, val2, ... specify nodal voltages and node1, node2, ... specify node numbers.
12.3.2 Example

```
.IC V(1) = 2.0  V(A) = 4.5
.DCVOLT 1 2.0 A 4.5
```

Fig. 12.3 provides a more complete example (showing a full netlist).
12.4 .SAVE Statements

_Xyce_ stores operating point information using _SAVE_ statements, and then reuses it to start subsequent transient simulations. Using _SAVE_ results in solution data being stored in a text file, comprised of _NODESET_ or _IC_ statements. This file can be applied to other simulations using _INCLUDE_.

The form of _SAVE_ is as follows:

```
.SAVE <TYPE=type_keyword> <FILE=save_file> <LEVEL=level_keyword> <TIME=save_time>
```

where:

type_keyword can be set to “NODESET” or “IC”. By default, it will be “IC”.

save_file is the user-specified output file name for the *.ic file. If this is not specified, _Xyce_ uses _netlist.cir.ic_.

level_keyword is an Hspice compatibility parameter. _Xyce_ supports “ALL” and “NONE.”

save_time is an Hspice compatibility parameter. Currently unsupported, _Xyce_ outputs the *.ic file at time=0.0.
12.5 DCOP Restart

DCOP restart is a capability similar to .NODESET and .SAVE used in combination. Similar to .NODESET, starting a simulation with DCOP restart will result in Xyce performing two nonlinear solves. The first solve strictly enforces the previous answer, and the second solve allows all the values to float and obtain their unconstrained solution. The second solve relies on the results of the first solve as an initial guess.

If the UIC keyword appears on the .TRAN line, Xyce applies the contents of the DCOP restart file as the initial condition and skips the DCOP calculation altogether. This is, the same as for .IC and .NODESET.

While .NODESET and DCOP restart are similar, there are a few differences. The biggest difference is the handling of voltage source voltages and currents. DCOP restart will attempt to restart from all the variables of the simulation, including voltage source variables. .NODESET, on the other hand, will ignore specified variables associated with voltage sources, and explicitly does not allow currents to be set. In general, voltage sources are constraints in and of themselves, so reconstraining them can cause singular matrices. To avoid this issue, DCOP restart makes changes to the linear system to prevent matrices from being singular.

12.5.1 Saving a DCOP restart file

To create a DCOP restart file, add a .DCOP output=filename line to the netlist:

```
.dcop output=saved.op
```

This will result in Xyce producing the file “saved.op” immediately after the operating point calculation. The produced file is similar to a *.ic file that can be produced by .SAVE, but with different format. Both file types are two-column text files. One column has the variable name, the other column the value of that variable.

12.5.2 Loading a DCOP restart file

To use a DCOP restart file, add a .DCOP input=filename line to the netlist:

```
.dcop input=saved.op
```

If the specified file does not exist in the local directory, Xyce will simply ignore the .DCOP statement and run normally.
12.6 UIC and NOOP

As noted earlier, the UIC key word on the TRAN line will disable the DCOP calculation, and result in Xyce immediately going to transient. If the user specifies .IC, .NODESET, or .DCOP input, then the transient calculation will use the specified initial values as the initial starting point. The NOOP keyword works exactly the same way as UIC.

```
pierce oscillator
 c1 1 0 100e-12
 c2 3 0 100e-12
 c3 2 3 99.5e-15
 c4 1 3 25e-12
 l1 2 4 2.55e-3
 r1 1 3 1e5
 r2 3 5 2.2e3
 r3 1 4 6.4
 v1 5 0 12
 Q1 3 1 0 NBJT
 .MODEL NBJT NPN (BF=100)
 .print tran v(2) v(3)

 .tran 1ns 1us UIC
 .ic v(2)=-10000.0 v(5)=12.0
```

Figure 12.4. Example netlist with UIC.
NOTE: This circuit is a Pierce oscillator, which only oscillates if the operating point is skipped. If the .IC statement is not included, the oscillator will take a long time to achieve its steady-state amplitude. By including the .IC statement, the amplitude of node 2 is preset to a value close to its final steady-state amplitude. The transient in this example only runs for 10 cycles as a demonstration. In general, the time scales for this oscillator are much longer and require millions of cycles.

12.6.1 Example

```
.tran 1ns 1us UIC
.tran 1ns 1us NOOP
```

Some circuits, particularly oscillator circuits, will only function properly if the operating point is skipped, as they need an inconsistent initial state to oscillate. Figure 12.4 presents a Pierce oscillator example.
13. Working with .PREPROCESS Commands

Chapter Overview

This chapter includes the following sections:

- Section 13.1 Introduction
- Section 13.2 Ground Synonym Replacement
- Section 13.3 Removal of Unused Components
- Section 13.4 Adding Resistors to Dangling Nodes
13.1 Introduction

In an effort to make Xyce more compatible with other commercial circuit simulators (e.g., HSPICE), some optional tools have been added to increase the netlist processing capabilities of Xyce. These options, which occur toward the beginning of a simulation, have been incorporated not only to make Xyce more compatible with different (i.e. non-Xyce) netlist syntax, but also to help detect and remove certain singular netlist configurations that can often cause a Xyce simulation to fail. Because all of the commands described in this section occur as a precursory step to setting up a Xyce simulation, they are all invoked in a netlist file via the keyword .PREPROCESS. This chapter describes each of the different functionalities that can be invoked via a .PREPROCESS statement in detail and provides examples to illustrate its use.

13.2 Ground Synonym Replacement

In certain versions of SPICE, keywords such as GROUND, GND, and GND! can be used as node names in a netlist file to represent the ground node of a circuit. Xyce, however, only recognizes node 0 as an official name for ground. Hence, if any of the prior node names is encountered in a netlist file, Xyce will treat these as different nodes from ground. To illustrate this point, consider the netlist of figure 13.1. When the node Gnd is encountered in the definition of resistor R3, Xyce instantiates this as a new node. The schematic diagram corresponding to this netlist (figure reffig:gndreplace2) shows that the resistor R3 is “floating” between node 2 and a node with only a single device connection, node Gnd. When Xyce executes the netlist of figure 13.1 the voltage V(2) will evaluate to 0.5V.

If one would rather treat Gnd the same as node 0 in the above example, use the figure 13.3 netlist instead. When the statement .PREPROCESS REPLACEGROUND TRUE is present in a netlist, Xyce will treat any nodes named GND, GND!, GROUND, or any capital/lowercase variant of these keywords (e.g., gROund) as synonyms for node 0. Hence, according to Xyce, the figure 13.3 netlist corresponds to figure 13.4 schematic diagram, and the voltage V(2) will evaluate to 0.33V.

![Circuit with "floating" resistor R3](Image)

**Figure 13.1.** Example netlist where Gnd is treated as being different from node 0.
Figure 13.2. Circuit diagram corresponding to the netlist of figure 13.1 where node Gnd is treated as being different from node 0.

Circuit where resistor R3 does *not* float

V1 1 0 1
R1 1 2 1
R2 2 0 1
R3 2 Gnd 1

.PROCESS REPLACEGROUND TRUE

.DC V1 1 1 0.1
.PRINT DC V(2)
.END

Figure 13.3. Example netlist where Gnd is treated as a synonym for node 0.

Figure 13.4. Circuit diagram corresponding to figure 13.3 where node Gnd is treated as a synonym for node 0.
NOTE: Only one .PREPROCESS REPLACEGROUND statement is allowed per netlist file (this is to prevent the user from setting REPLACEGROUND to TRUE on one line and then to FALSE on another). There is no way to differentiate between different keywords (i.e., it is not possible to treat GROUND as a synonym for node 0 while allowing GND to represent an independent node). If REPLACEGROUND is set to TRUE, Xyce will treat both of these keywords as node 0 if present in a netlist file.

13.3 Removal of Unused Components

Consider a slight variant of the circuit in figure 13.3 with the netlist given in figure 13.5. Here, the resistor R3 is connected in a peculiar configuration: both terminals of the resistor are tied to the same circuit node, as is illustrated in figure 13.6. Clearly, the presence of this resistor has no effect on the other voltages and currents in the circuit since, by the very nature of its configuration, it has no voltage across it and, hence, does now draw any current. Therefore, in some sense, the component can be considered as “unused.” The presence of a resistor such as R3 is rarely or never introduced by design, rather the presence of such components is the result of either human or automated error.

While the presence of the resistor R3 in figure 13.3 does not change the behavior of the circuit, it adds an additional component to the netlist Xyce must include when solving for the voltages and currents in the circuit. If the number of such components in a given netlist is large, it is potentially desirable to remove them from the netlist to ease the burden on Xyce’s solver engines. This, in turn, can help to avoid possible convergence issues. For example, even though the netlist in figure 13.5 will run properly in Xyce, the netlist of figure 13.7 will abort. The voltage source V2 attempts to place a 1V difference between its two device terminals; however, as both nodes of the voltage source are the same, the voltage source is effectively shorted.

Xyce includes the following command to prevent similar situations:

```
.PREPROCESS REMOVEUNUSED <component list>
```

where <component list> is a list of device types separated by commas. For each device type
Figure 13.6. Circuit of figure 13.5 containing a resistor R3 whose terminals are tied to the same node (node 2).

Figure 13.7. Circuit with improperly connected voltage source V2

```plaintext
Circuit with improperly connected voltage source V2

V1 1 0 1
R1 1 2 1
R2 2 0 1
V2 2 2 1

.DC V1 1 1 0.1
.PRINT DC V(2)
.END
```

Figure 13.7. Circuit with an improperly connected voltage source V2.
specified in the list, **Xyce** checks for instances of that device type for which all of the device terminals are connected to the same node. If such a device is found, **Xyce** removes that device from the netlist. For instance, if executing the netlist of figure 13.8, **Xyce** will seek out such devices and remove them from the netlist. This causes the resistor R3 to be removed from the netlist. Figure 13.9 presents the schematic of the resulting **Xyce**-simulated circuit. NOTE: The presence of “C” in the REMOVEUNUSED statement does not cause **Xyce** to abort even though there are no capacitors in the netlist. Also, as in the case of a REPLACEGROUND statement, only one .PREPROCESS REMOVEUNUSED line may be present per netlist, or **Xyce** will abort.

Table 13.1 lists devices that can be removed via a REMOVEUNUSED statement. In the case of MOSFETs and BJTs, three device terminals must be the same (the gate, source, and drain in the case of a MOSFET; the base, collector, and emitter in the case of a BJT) to remove either device from the netlist.

Table 13.1 lists devices that can be removed via a REMOVEUNUSED statement. In the case of MOSFETs and BJTs, three device terminals must be the same (the gate, source, and drain in the case of a MOSFET; the base, collector, and emitter in the case of a BJT) to remove either device from the netlist.

### Circuit with improperly connected voltage source V2

```
V1 1 0 1  
R1 1 2 1  
R2 2 0 1  
R3 2 2 1  

.PREPROCESS REMOVEUNUSED R,C  

.DC V1 1 1 0.1  
.PRINT DC V(2)  
.END
```

**Figure 13.8.** Circuit with an “unused” resistor R3 removed from the netlist.

![Figure 13.8](image)

**Figure 13.9.** Circuit of figure 13.8 where resistor R3 has been removed via the .PREPROCESS REMOVEUNUSED statement.
Table 13.1: List of keywords and device types which can be used in a .PREPROCESS REMOVEUNUSED statement.

<table>
<thead>
<tr>
<th>Keyword</th>
<th>Device Type</th>
</tr>
</thead>
<tbody>
<tr>
<td>C</td>
<td>Capacitor</td>
</tr>
<tr>
<td>D</td>
<td>Diode</td>
</tr>
<tr>
<td>I</td>
<td>Independent Current Source</td>
</tr>
<tr>
<td>L</td>
<td>Inductor</td>
</tr>
<tr>
<td>M</td>
<td>MOSFET</td>
</tr>
<tr>
<td>Q</td>
<td>BJT</td>
</tr>
<tr>
<td>R</td>
<td>Resistor</td>
</tr>
<tr>
<td>V</td>
<td>Independent Voltage Source</td>
</tr>
</tbody>
</table>

13.4 Adding Resistors to Dangling Nodes

Consider the netlist of figure 13.10 and the corresponding schematic of figure 13.11. Nodes 3 and 4 of the netlist are what we will henceforth refer to as dangling nodes. We say that node 4 dangles because it is only connected to the terminal of a single device, while we say that node 3 dangles because it has no DC path to ground. The first of these situations—connection to a single device terminal only—can arise, for example, in a netlist which contains nodes representing output pins that are not connected to a load device. For instance, the resistance $R_2$ in figure 13.10 could represent the resistance of an output pin of a package that is meant to drive resistive loads. Hence, an actual physical implementation of the circuit of figure 13.11 would normally include a resistor between node 4 and ground, but, in creating the netlist, the presence of such an output load has been (either intentionally or unintentionally) left out.

The second situation—where a node has no DC path to ground—is sometimes an effect that is purposely incorporated into a design (e.g., the design of switched capacitor integrators (e.g., see [22], chapter 10), but oftentimes it is also the result of some form of error in the process of creating the netlist. For instance, when graphical user interfaces (GUIs) are used to create circuit schematics that are then translated into netlists via software, one very common unintentional error
Figure 13.11. Schematic of netlist in figure 13.10

is to fail to connect two nodes that are intended to be connected. To illustrate this point, consider
the schematic of figure 13.12. The schematic seems to indicate that the lower terminal of resistor
\(R_2\) should be connected to node 3. This is not the case as there is a small gap between node 3
and the line intended to connect node 3 to the resistor. Such an error can often go unnoticed when
creating a schematic of the netlist in a GUI. Thus, when the schematic is translated into a netlist
file, the resulting netlist would \textit{not} connect the resistor to node 3 and would instead create a new
node at the bottom of the resistor, resulting in the circuit depicted in figure 13.11.

While neither of the previous situations is necessarily threatening (\texttt{Xyce} will run the figure 13.10
netlist successfully to completion), there are times when it is desirable to somehow make a dan-
gling node \textit{not} dangle. For instance, returning to the example in which the resistor \(R_2\) represents
the resistance of an output pin, one may want to simulate the circuit when a 1K load is attached
between node 4 and ground in figure 13.11. In the case where a node has no DC path to ground,
the situation is slightly more dangerous if, for instance, the node in question is also connected to
a high-gain device such as the gate of a MOSFET. As the DC gate bias has a great impact on the
DC current traveling through the drain and source of the transistor, not having a well-defined DC
gate voltage can greatly degrade the simulated performance of the circuit.

In both prior examples, the only true way to “fix” each of these issues is to find all dangling nodes in
a particular netlist file and augment the netlist at/near these nodes to obtain the desired behavior.
If, however, the number of components in a circuit is very large (say on the order of hundreds of
thousands of components), manually augmenting the netlist file for each dangling node becomes
a practical impossibility if the number of such nodes is large.

Hence, it is desirable for \texttt{Xyce} to be capable of automatically augmenting netlist files so as
to help remove dangling nodes from a given netlist. The command \texttt{.PREPROCESS ADDRESISTORS}
is designed to do just this. Assuming the netlist of figure 13.13 is stored in the file \texttt{filename},
the \texttt{.PREPROCESS ADDRESISTORS} statements will cause \texttt{Xyce} to create a new netlist file called
\texttt{filename\_xyce.cir} (depicted in figure 13.14). The line \texttt{.PREPROCESS ADDRESISTORS NODCPATH 1G}
instructs \texttt{Xyce} to create a copy of the netlist file containing a set of resistors of value 1G that
are connected between ground and nodes which currently have no DC path to ground. Similarly,
the line \texttt{.PREPROCESS ADDRESISTORS ONETERMINAL 1M} instructs \texttt{Xyce} to add to the same netlist file
a set of resistors of value 1M that are connected between ground and devices that are connected
to only one terminal. The resistor \(RNODCPATH1\) in figure 13.14 achieves the first of these goals.
while \texttt{RONETERM1} achieves the second. Figure 13.15 shows a schematic of the resulting circuit represented by the netlist in figure 13.14.

\begin{figure}[h]
\centering
\begin{tikzpicture}
\node (v1) at (0,0) [draw, circle, fill=white, inner sep=1pt] {V1};
\node (r1) at (1,0) [draw, circle, fill=white, inner sep=1pt] {R1};
\node (c1) at (1,1) [draw, circle, fill=white, inner sep=1pt] {C1};
\node (c2) at (1,-1) [draw, circle, fill=white, inner sep=1pt] {C2};
\node (r2) at (2,0) [draw, circle, fill=white, inner sep=1pt] {R2};
\node (0) at (0,-2) [draw, circle, fill=white, inner sep=1pt] {0};
\node (1) at (1,2) [draw, circle, fill=white, inner sep=1pt] {1};
\node (2) at (2,1) [draw, circle, fill=white, inner sep=1pt] {2};
\node (3) at (2,-1) [draw, circle, fill=white, inner sep=1pt] {3};
\draw (v1) -- (r1);
\draw (r1) -- (c1);
\draw (c1) -- (r2);
\draw (r2) -- (0);
\draw (v1) -- (1);
\draw (c1) -- (2);
\draw (c2) -- (3);
\end{tikzpicture}
\caption{Schematic of a circuit with an incomplete connection between the resistor \( R2 \) and node 3.}
\end{figure}

\begin{figure}[h]
\centering
\begin{verbatim}
Circuit with two dangling nodes, nodes 3 and 4

V1 1 0 1
R1 1 2 1
C1 2 3 1
C2 3 0 1
R2 2 4 1

.PREPROCESS ADDRESISTORS NODCPATH 1G
.PREPROCESS ADDRESISTORS ONETERMINAL 1M

.DC V1 0 1 0.1
.PRINT DC V(2)
.END
\end{verbatim}
\caption{Netlist of circuit with two dangling nodes, nodes 3 and 4, with .PREPROCESS ADDRESISTORS statements.}
\end{figure}

Some general comments regarding the use of .PREPROCESS ADDRESISTOR statements include:

- \texttt{Xyce} does not terminate immediately after the netlist file is created. In other words, if \texttt{Xyce} is run on the filename of figure 13.13 netlist, it will attempt to execute this netlist as given (i.e., it tries to simulate the circuit of figure 13.11) and generates the file \texttt{filename\_xyce.cir} as a biproduct. It is important to point out that the resistors that are added at the bottom of the netlist file \texttt{filename\_xyce.cir} do \textbf{not} get added to the original netlist when \texttt{Xyce} is running on the file \texttt{filename}. If one wishes to simulate \texttt{Xyce} with these resistors in place, one must run \texttt{Xyce} on \texttt{filename\_xyce.cir} explicitly.

- The naming convention for resistors which connect to ground nodes which do not have a DC
XYCE-generated Netlist file copy: TIME='07:32:31 AM'
* DATE='Dec 19, 2007'
*Original Netlist Title:

*Circuit with two dangling nodes, nodes 3 and 4.

V1 1 0 1
R1 1 2 1
C1 2 3 1
C2 3 0 1
R2 2 4 1

*.PREPROCESS ADDRESISTORS NODCPATH 1G
*Xyce: "*.PREPROCESS ADDRESISTORS" statement
* automatically commented out in netlist copy.
*.PREPROCESS ADDRESISTORS ONETERMINAL 1M
*Xyce: "*.PREPROCESS ADDRESISTORS" statement
* automatically commented out in netlist copy.

.DAY 0 10
.PRINT DC V(2)

*.END

*XYCE-GENERATED OUTPUT: Adding resistors between ground
* and nodes connected to only 1 device terminal:

RONETERM1 4 0 1M

*XYCE-GENERATED OUTPUT: Adding resistors between ground
* and nodes with no DC path to ground:

RNODCPATH1 3 0 1G

.END

Figure 13.14. Output file filename_xyce.cir which results from
the .PREPROCESS ADDRESISTOR statements for the netlist of figure
[13.12](with assumed file name filename).
path to ground is \( \text{RNODCPATH}^i \), where \( i \) is an integer greater than 0; the naming convention is similar for nodes which are connected to only one device terminal (i.e., of the form \( \text{RONETERM}^i \)). \textit{Xyce} will not change this naming convention if a resistor with one of the above names already exists in the netlist.

Hence, if a resistor named \( \text{RNODCPATH}1 \) exists in netlist file \( \text{filename} \), and \textit{Xyce} detects there is a node in this netlist file that has no DC path to ground, \textit{Xyce} will add another resistor with name \( \text{RNODCPATH}1 \) to the netlist file \( \text{filename}_\text{xyce.cir} \) (assuming that either \texttt{.PREPROCESS ADDRESISTORS NODCPATH} or \texttt{.PREPROCESS ADDRESISTORS ONETERMINAL} are present in \( \text{filename} \)). If \textit{Xyce} is subsequently run on \( \text{filename}_\text{xyce.cir} \), it will exit in error due to the presence of two resistors with the same name.

- **Commands** \texttt{.PREPROCESS ADDRESISTORS NODCPATH} and \texttt{.PREPROCESS ADDRESISTORS ONETERMINAL} do not have to be simultaneously present in a netlist file. The presence of either command will generate a file \( \text{filename}_\text{xyce.cir} \), and the presence of both will not generate two separate files. As with other \texttt{.PREPROCESS} commands, however, a netlist file is allowed to contain only one \texttt{NODCPATH} and one \texttt{ONETERMINAL} command each. If multiple \texttt{NODCPATH} and/or \texttt{ONETERMINAL} lines are found in a single netlist file, \textit{Xyce} will exit in error.

- It is possible that a single node can have no DC path to ground and be connected to only one device terminal. If a \texttt{NODCPATH} and \texttt{ONETERMINAL} command are present in a given netlist file, only the resistor corresponding to the \texttt{ONETERMINAL} command is added to the netlist file \( \text{filename}_\text{xyce.cir} \) and the resistor corresponding to the \texttt{NODCPATH} command is omitted. If a \texttt{NODCPATH} command is present but a \texttt{ONETERMINAL} command is not, then \textit{Xyce} will add a resistor corresponding to the \texttt{NODCPATH} command to the netlist, as usual.

- In generating the file \( \text{filename}_\text{xyce.cir} \), the original \texttt{.PREPROCESS ADDRESISTOR} statements are commented out with a warning message. This is to prevent \textit{Xyce} from creating the file \( \text{filename}_\text{xyce.cir}_\text{xyce.cir} \) when the file \( \text{filename}_\text{xyce.cir} \) is run.

\textbf{NOTE:} This act is put in place simply to avoid generating redundant files. While \( \text{filename}_\text{xyce.cir}_\text{xyce.cir} \) would be slightly different from \( \text{filename}_\text{xyce.cir} \) (e.g., a different date and time stamp), both files would functionally implement the same netlist.
14. TCAD (PDE Device) Simulation with Xyce

Chapter Overview

This chapter provides guidance for using the mesh-based device simulation capability of Xyce. It includes the following sections:

- Section 14.1 Introduction
- Section 14.2 One-Dimensional Example
- Section 14.3 Two-Dimensional Example
- Section 14.4 Doping Profile
- Section 14.5 Electrodes
- Section 14.6 Meshing
- Section 14.8 Mobility Models
- Section 14.9 Bulk Materials
- Section ??, Solver Options
- Section 14.10 Output and Visualization
14.1 Introduction

This chapter describes how to use the mesh-based device simulation functionality of Xyce, which is based on the solution a coupled set of partial differential equations (PDEs), discretized on a mesh. Such devices are often referred to as Technology Computer-Aided Design (TCAD) devices. While the rest of Xyce is intended to be similar to analog circuit simulators such as SPICE, the TCAD device capability is intended to be similar to commercial device simulators, such as PISCES [23] and DaVinci [24].

Xyce offers two different TCAD devices — a one-dimensional device and a two-dimensional device — and enables both to be invoked in the same way as a conventional lumped parameter circuit device. Generally, this capability is intended for very detailed simulation of semiconductor devices, such as diodes, bipolar transistors, and MOSFETs. As the Xyce TCAD devices can be invoked from the netlist, they can be embedded in a circuit as part of a mixed-mode simulation.

The Xyce TCAD devices should be considered to be a beta-level capability. The primary focus of Xyce has been traditional analog circuit simulation, so these devices have not received the same level of attention. This capability should be regarded as a prototype for Charon [25], a high-performance TCAD simulator under development at Sandia.

14.1.1 Equations

Kramer [26] and Selberherr [27], among others, describe device simulation equations. The most common formulation and the one used in Xyce, is the drift-diffusion (DD) formulation, which consists of three coupled PDEs (a single Poisson equation for electrostatic potential and two continuity equations; one each for electrons and holes).

Poisson equation

The electrostatic potential \( \phi \) satisfies Poisson’s equation:

\[
- \nabla \cdot (\epsilon \nabla \phi(x)) = \rho(x)
\]  

(14.1)

where \( \rho \) is the charge density and \( \epsilon \) is the permittivity of the material. For semiconductor devices, local carrier densities and local doping determine charge density;

\[
\rho(x) = q(p(x) - n(x) + C(x))
\]  

(14.2)

Here, \( p(x) \) is the spatially dependent concentration of holes; \( n(x) \), the concentration of electrons; and \( q \), the magnitude of the charge on an electron. \( C(x) \) is the total doping concentration, which can also be represented as \( C(x) = N_D^+(x) - N_A^-(x) \), where \( N_D^+ \) the concentration of positively ionized donors, \( N_A^- \) the concentration of negatively ionized acceptors.
Species continuity equations

Continuity equations relate the convective derivative of the species concentrations to the creation and destruction of particles ("recombination/generation").

\[
\frac{\partial n(x)}{\partial t} + \nabla \cdot \Gamma_n = -R(x) \quad (14.3)
\]

\[
\frac{\partial p(x)}{\partial t} + \nabla \cdot \Gamma_p = -R(x) \quad (14.4)
\]

Here \( n \) is the electron concentration and \( p \) is the hole concentration. \( R \) is the recombination rate for both species. \( \Gamma_n \) and \( \Gamma_p \) are particle fluxes for electrons and holes, respectively. \( R \) is the recombination rate for both species, and the right hand sides are equal since creation and destruction of carriers occurs in pairs. The quantities \( \Gamma_n \) and \( \Gamma_p \) are electron and hole fluxes, and are determined from the following expressions:

\[
\Gamma_n = n(x)\mu_n E(x) + D_n \nabla n(x) \quad (14.5)
\]

\[
\Gamma_p = p(x)\mu_p E(x) + D_p \nabla p(x) \quad (14.6)
\]

\( \mu_n, \mu_p \) are mobilities for electrons and holes, and \( D_n, D_p \) are diffusion constants. \( E(x) \) is the electric field, which is given by the gradient of the potential, or \(-\partial \phi/\partial x\).

14.1.2 Discretization

**Xyce** uses a box-integration discretization, with the Scharfetter-Gummel method to model the flux of charged species. For a more-detailed description of this method, refer to [26] [27] [28].

14.2 One Dimensional Example

The one-dimensional device was the first PDE-based device to be implemented in **Xyce**. The single dimension limits its usefulness, but its simplicity makes it a good device to use for a preliminary example. One dimensional devices are almost always two-terminal diodes, and this fact allows for assumptions that simplify the specification and shorten the parameter list of the device.

Figure [14.2] provides an example netlist for a simulation of a one-dimensional diode, while figure [14.2] shows its corresponding schematic. This regulator circuit is based on the principle that connecting one or more diodes in series with a resistor and a power supply will produce a relatively constant voltage. The input voltage (node 2) is a sinewave, with a frequency of 50 Hz and an amplitude of 1 V. The expected output (node 3) signal should be (mostly) flat.

14.2.1 Netlist Explanation

Currently, there are almost no model parameters for PDE devices. The model line serves only to set the level. The default level is 1, for a one-dimensional device. Setting \texttt{level=2} will invoke
Figure 14.1. Voltage regulator circuit, using a one-dimensional TCAD diode. Figure 14.3 illustrates the result of this netlist. The PDE device instance line is in red, and the PDE device model line is in blue.
two-dimensional devices. In this example, the level is not explicitly set, and so Xyce uses the default value (1).

The instance line is where most of the specific parameters are set for a TCAD device. In this example, the line appears as:

\[
\text{YPDE Z1 3 4 DIODE na=1.0e17 nd=1.0e17 graded=1 l=5.0e-4 nx=101}
\]

Doping parameters \( na \) and \( nd \) represent the majority carrier doping levels on the N- and the P-sides of the junction, respectively. \( \text{graded=1} \) is also a doping parameter, and specifies that the junction is a graded junction, rather than an abrupt step-function junction. \( l=5.0e-4 \) specifies the length of the device, in cm. \( nx=101 \) specifies that there are 101 mesh points, including the two endpoints. For the one-dimensional device, the mesh is always uniform, so the size of each mesh cell, \( \Delta x \) will be:

\[
\Delta x = \frac{l}{nx - 1} = \frac{5.0e-4 \text{ cm}}{100} = 5.0e-6 \text{ cm}
\]

(14.7)

The mesh points \( i = 0 \rightarrow 101 \) will have the following locations, \( x_i \):

\[
\begin{align*}
x_i &= i \Delta x \\
x_0 &= 0.0 \text{ cm} \\
x_1 &= 5.0e-6 \text{ cm} \\
\vdots &\ \\
x_{101} &= 5.0e-4 \text{ cm}
\end{align*}
\]
14.2.2 Boundary Conditions and Doping Profile

The cited netlist example relies mostly on default parameters; therefore, it specifies nothing about electrodes, or boundary conditions, and has a minimal doping specification. A one-dimensional device can have only two electrodes connected to the circuit. The electrodes are at opposite ends of the domain, one at the first mesh point \((x=0.0 \text{ cm}, i=0)\) and the other at the opposite end of the domain, at the last mesh point \((x=5.0\times10^{-4} \text{ cm}, i=101)\).

The electrode associated with the first mesh point \((x=0.0 \text{ cm})\) is connected to the second circuit node on the instance line, while the electrode associated with the last mesh point \((x=l)\) is connected to the first circuit node on the instance line. For the doping used in this example, the junction is in the exact center of the device \((x=l/2)\), and the n-side is the region defined by \(x<l/2\), and the p-side is the region defined by \(x>l/2\). This default doping, along with the electrode-circuit connectivity, result in the one-dimensional device to behave like a traditional SPICE-style diode. For a complete discussion of how to specify a doping profile see section [14.4.1]. For a complete discussion of how to specify electrodes in detail (including boundary conditions), see section [14.5].

14.2.3 Results

Figure [14.3] shows the transient result of this circuit. The voltage drop across the diode \((V(3))\) is nearly the same for a wide range of currents, and is nearly constant. The voltage drop across the series resistor, \(R_1\), is much more sensitive \((V(2)-V(3))\), and so most of the voltage variation of the input sinewave is accounted for by \(R_1\).

Figure 14.3. Results for voltage regulator. In the left plot, the transient output is shown, in which the input voltage is blue and the output voltage is red. In the right plot, the initial carrier densities are shown, with the electron density in red and the hole density in blue.
14.3 Two-Dimensional Example

Figure 14.4 presents an example netlist for a simulation of a two-dimensional bipolar transistor. As before, the PDE device instance line is in red, while the PDE device model line is in blue. In this case, note that the model line specifies the level, which is set to 2. This is required for the two-dimensional device. This particular example is a DC sweep of a bipolar transistor device. Figure 14.5 presents a schematic illustrating this circuit.

```
Two-Dimensional Example
VPOS 1 0 DC 5V
VBB 6 0 DC -2V
RE 1 2 2K
RB 3 4 190K

YPDE BJT 5 3 7 PDEBJT meshfile=internal.msh
+ node = {name = collector, base, emitter}
+ tecplotlevel=2 txtdatalevel=1
+ mobmodel=arora
+ l=2.0e-3 w=1.0e-3
+ nx=30 ny=15

.MODEL PDEBJT ZOD level=2

* Zero-volt sources acting as an ammeter to measure the
* base, collector, and emitter currents, respectively
VMON1 4 6 0
VMON2 5 0 0
VMON3 2 7 0

.DC VPOS 0.0 12.0 0.5 VBB -2.0 -2.0 1.0
$options NONLIN maxstep=70 maxsearchstep=1
+ searchmethod=2
$options TIMEINT reltol=1.0e-3 abstol=1.0e-6
+ firstdcpstep=0 lastdcpstep=1
.PRINT DC V(1) I(VMON1) I(VMON2) I(VMON3)
.END
```

Figure 14.4. Two-dimensional BJT netlist. Figures 14.6 and 14.7 provide some of the results of this netlist.

14.3.1 Netlist Explanation

The two-dimensional device can have 2 to 4 electrodes. In this example there are three; nodes 5, 3, and 7, corresponding to the three names on the “node” line, which appears as:
Figure 14.5. Two-dimensional BJT circuit schematic. This schematic is for the circuit described by the netlist in figure 14.4. The mesh in the large circle is the mesh used in the example. The other mesh, which contains some mesh refinement, is included in the figure as an example of what is possible with an external mesh generator.

+ node = {name = collector, base, emitter}

This line specifies that node 5 is connected to an electrode named “collector,” node 3 is connected to an electrode named “base,” and node 7 is connected to an electrode named “emitter.” Although this example only contains the electrode names, the “node” specification can contain a lot of information. Section 14.5 provides a full explanation of the electrode parameters.

The next line contains parameters concerned with plotting the results, and appears as follows:

+ tecplotlevel=2 txtdatalevel=1

These are not related to the output specified by .PRINT, which outputs circuit data. The tecplotlevel command enables files to be output readable by Tecplot, which can then be used to create contour plots of quantities such as the electron density, electrostatic potential and the doping profile. Figures 14.6 and 14.7 contain examples of Tecplot-generated contour plots, which were generated from the results of this example.

The txtdatalevel command enables a text file with volume averaged information to be output to a file. Currently, Xyce will update both of these output files at each time step or DC sweep step.
The next line, `mobmodel=arora`, specifies which mobility model to use. Section 14.8 provides for more detail on available mobility models.

The last two lines, specify the mesh of the device, and are given by:

```
+  l=2.0e-3  w=1.0e-3
+  nx=30  ny=15
```

This numbers are used in nearly the same way as the one-dimensional case used \( l \) and \( nx \) parameters. The mesh is Cartesian, and the spacing is uniform.

### 14.3.2 Doping Profile

As in the one-dimensional example, the two-dimensional example in figure 14.4 specifies nothing about the doping profile, and thus relies on default settings. In this case there are three specified electrodes, which by default results in the doping profile of the bipolar junction transistor (BJT). Section 14.4 provides a complete description of how to specify a doping profile in detail, and describes the various default impurity profiles.

### 14.3.3 Boundary Conditions and Electrode Configuration

As in the one- and two-dimensional examples in figure 14.4 specify nothing about the electrode configuration or the boundary conditions, and rely on default settings. To be consistent with the default three-terminal doping, the device has terminals that correspond to that of a BJT. All three electrodes (collector, base, emitter) are along the top of the device.

By default all electrodes are considered to be neutral contacts. The boundary conditions applied to the electron density, hole density, and electrostatic potential are all Dirichlet conditions.

Section 14.5 discusses how to specify electrodes in detail (including boundary conditions).

### 14.3.4 Results

Figures 14.6, 14.7 and 14.8 provide results for the two-dimensional example. The first two figures are contour plots of the electrostatic potential. The first corresponds to the first DC sweep step, where VPOS is set to 0.0 Volts. The second corresponds to the final DC sweep step, in which VPOS has a value of 12.0 volts. The voltage source, VPOS, applies a voltage to the emitter load resistor, RE, so some of the 12.0V is dropped across RE, an the rest is applied to the BJT.

The third figure is an I-V curve of the dependence of the three terminal currents on applied emitter voltage. For the entire sweep, \( -2.0 \) V has been applied to the base load resistor and, as this transistor is a PNP transistor, this results in the transistor being in an “on” state. The emitter-collector current varies nearly linearly with the applied emitter voltage. Also, as can be expected because of current conservation, the three currents sum to nearly zero.
Note that the mesh used to generate these results is visible in figure 14.6, and was generated using the internal “uniform mesh”. This mesh will not produce a very accurate result, as it does not resolve the depletion regions very well. Accuracy can, in theory, be improved using mesh refinement near the depletion regions. However, such meshes must be read in from an external mesh generator (currently unsupported).

**Figure 14.6.** Initial two-dimensional BJT result. A Tecplot-generated contour plot of the electrostatic potential at the first DC sweep step of the netlist in figure 14.4.

**Figure 14.7.** Final two-dimensional BJT result. A Tecplot-generated contour plot of the electrostatic potential at the last DC sweep step of the netlist in figure 14.4.

### 14.4 Doping Profile

*Xyce* used the defaults in the two examples as no doping parameters were specified. Default profiles are uniquely specified by the number of electrodes. In practice, especially for two-dimensional simulations, the user will generally need to specify the doping profile manually.
14.4.1 Manually Specifying the Doping

Figure 14.9 shows a circuit netlist for a one-dimensional device with a detailed, manual specification of the doping profile. Figure 14.11 illustrates a similar, two-dimensional version of this problem. For this discussion, the one-dimensional example will be referred to, but information conveyed is equally applicable to the two-dimensional case.

In both examples, the parameters associated with doping are in red text. The doping is specified with one or more regions, which are summed together to obtain the total profile. Doping regions are specified in a tabular format, with each column representing a different region.

In the one-dimensional example, there are three regions, which are illustrated in figure 14.10. Region 1 is a uniform n-type doping, with a constant magnitude of $4.0\times10^{12}$ donors per cubic cm. This magnitude is set by the parameter $n_{\text{max}}$. As the doping in this region is spatially uniform, the only meaningful parameters are function (which in this case specifies a spatially uniform distribution), type (ntype or ptype) and $n_{\text{max}}$. The other parameters, $n_{\text{min}}$ through $\text{flatx}$ (1D) or $\text{flaty}$ (2D), are ignored for a spatially uniform region.

Region 2 is a more complicated region, in that the profile varies with space. This region is doped
Doping and Electrode specification example

```
vscope 0 1 0.0
rscope 2 1 50.0
cid 3 0 1.0u
r1 4 3 1515.0
vid 4 0 5.00

YPDE Z1DIODE 2 3 PDEDIODE nx=301 l=26.0e-4
* DOPING REGIONS: region 1, region 2, region 3
+ region= {name = reg1, reg2, reg3
+ function = uniform, gaussian, gaussian
+ type = ntype, ptype, ntype
+ nmax = 4.0e+12, 1.0e+19, 1.0e+18
+ nmin = 0.0e+00, 4.0e+12, 4.0e+12
+ xloc = 0.0, 24.5e-04, 9.0e-04
+ xwidth = 0.0, 4.5e-04, 8.0e-04
+ flatx = 0, 0, -1 }

*--------end of Diode PDE device ----------------

.MODEL PDEDIODE ZOD level=1
.options NONLIN maxsearchstep=1 searchmethod=2
.options TIMEINT reltol=1.0e-3 abstol=1.0e-6
.DC vscope 0 0 1
.print DC v(1) v(2) v(3) v(4) I(vscope) I(vid)
.END
```

**Figure 14.9.** One-dimensional example, with detailed doping
with p-type impurities, and has a Gaussian shape. Semiconductor processing often consists of an implant followed by an anneal, which results in a diffusive profile. The Gaussian function is a solution to the diffusion problem, when it is assumed that the impurity exists in a fixed quantity.

The peak of the Region 2 doping profile is given by the parameter $n_{\text{max}}$, and is $1.0 \times 10^{19}$ acceptors per cubic cm. This peak has a location in the device specified by $x_{\text{loc}}=24.5 \times 10^{-4}$ cm. The parameters $n_{\text{min}}$ and $x_{\text{width}}$ are fitting parameters.

Figure 14.10. Doping profile, absolute value
This corresponds to the doping specified by the netlist in figure 14.9

Region 3 is also based on a Gaussian function, but unlike Region 2, it is flat on one side of the peak. This is set by the $\text{flat} x$ parameter. Table 14.1 lists conventions for “flat” parameters.

Table 14.1: Description of the $\text{flat} x$, $\text{flat} y$ doping parameters

<table>
<thead>
<tr>
<th>$\text{flat} x$ or $\text{flat} y$ value</th>
<th>Description</th>
<th>$\text{1D Cross Section}$</th>
</tr>
</thead>
<tbody>
<tr>
<td>0</td>
<td>Gaussian on both sides of the peak ($x_{\text{loc}}$) location.</td>
<td>![Diagram of Gaussian profile]</td>
</tr>
</tbody>
</table>

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Table 14.1: Description of the flatx, flaty doping parameters

<table>
<thead>
<tr>
<th>flatx or flaty value</th>
<th>Description</th>
<th>1D Cross Section</th>
</tr>
</thead>
<tbody>
<tr>
<td>+1</td>
<td>Gaussian if $x&gt;x_{\text{loc}}$, flat (constant at the peak value) if $x&lt;x_{\text{loc}}$.</td>
<td></td>
</tr>
<tr>
<td>-1</td>
<td>Gaussian if $x&lt;x_{\text{loc}}$, flat (constant at the peak value) if $x&gt;x_{\text{loc}}$.</td>
<td></td>
</tr>
</tbody>
</table>

### 14.4.2 Default Doping Profiles

**Xyce** has a few default doping profiles that are invoked when the user doesn’t specify detailed doping information. The default doping profiles are an artifact of early TCAD device development in **Xyce**, but are sometimes still useful. In particular, the simple step-junction diode is often a useful canonical problem. It is convenient to invoke a step-junction doping without having to use the more complex region tabular specification.

Most real devices will have doping profiles that do not exactly match the default profiles. When attempting to simulate a realistic device, it will be necessary to skip the defaults and use the region tables described in the previous section.

**One-Dimensional Case**

For the one-dimensional case, **Xyce** assumes that the doping profile is a simple junction diode, with the junction location exactly in the middle. The acceptor and donor concentrations are given by the parameters $N_a$ and $N_d$, respectively.

The use of $N_a$ and $N_d$, implicitly specifies a step junction doping profile, and is mutually exclusive with the more complex “doping region” table specification, described in section [14.4.1](#). If a netlist is input to **Xyce** with a region table and $N_a$ (or $N_d$), the code will immediately exit with an error.

**Two-Dimensional Case**

Doping level defaults in the two-dimensional case are somewhat more complicated than in the one-dimensional case, because having two-dimensions allows for more configurations, and an arbitrary number (2 to 4) of electrodes. During **Xyce** development, it was decided default doping profiles would be determined uniquely by the number of electrodes present. Table [14.2](#) provides the three available default dopings. In the case of the BJT and MOSFET dopings, it is possible to specify either n-type or p-type using the type instance parameter. If the detailed, manual doping is used, then the type parameter is ignored.

For a two-electrode device, the default doping is that of a simple diode. **Xyce** uses the acceptor and donor doping parameters, $N_a$ and $N_d$, in the same manner as in the one-dimensional device—the junction is assumed to be exactly in the middle of the domain.

For a three-electrode device (as shown in the example), the default doping is that of a bipolar junction transistor (BJT). By default the transistor is a PNP, but by setting the instance parameter
type=NPN, an NPN transistor can be specified instead. The two-dimensional example in section 14.3 relies on this default.

For a four-terminal device, the default doping is that of a metal-oxide-semiconductor (MOSFET). The maximum number of electrodes is four, and no default profiles are available for more than four electrodes. By default this transistor is assumed to be NMOS, rather than PMOS.

Table 14.2: Default doping profiles for different numbers of electrodes

<table>
<thead>
<tr>
<th>Number of Electrodes</th>
<th>Doping Profile</th>
</tr>
</thead>
<tbody>
<tr>
<td>2</td>
<td>Step Function Diode</td>
</tr>
<tr>
<td>3</td>
<td>Bipolar Junction Transistor (BJT)</td>
</tr>
<tr>
<td>4</td>
<td>Metal-Oxide Semiconductor Field-Effect Transistor(MOSFET)</td>
</tr>
</tbody>
</table>
14.5 Electrodes

Because minimal electrodes were specified in the two examples, Xyce used the defaults. In practice, especially for two-dimensional simulations, the user must specify the electrodes in more detail.

14.5.1 Electrode Specification

A detailed electrode specification is specified in blue text in figure 14.11. As with the doping parameters, the electrode parameters are specified in a tabular format, in which each table column specifies the different electrode parameters. The name parameter is the only required parameter.

The number of specified electrodes must match the number of connected circuit nodes, and the order of the electrode columns, from left to right, is in the same order as the circuit nodes, also from left to right. In the figure 14.11 example, the first electrode column, which specifies an electrode named “anode,” is connected to the circuit through circuit node 2. Respectively, the second column, for the “cathode” electrode, is connected to the circuit via circuit node 3.

Boundary Conditions

In the example, the default bc parameter has been set to “Dirichlet” on all the electrodes. The bc parameter sets the type of boundary condition applied to the density variables, the electron density and the hole density. Dirichlet and Neumann are two possible settings for the bc parameter. If Dirichlet is specified, the electron and hole densities are set to a specific value at the contact, and the applied values enforce charge neutrality. See the Xyce Reference Guide [3] provides the charge-neutral equation. If Neumann is specified, Xyce applies a zero-flux condition, which enforces that the current through the electrode will be zero.

This parameter does not affect the electrostatic potential boundary condition. The boundary condition applied to the potential is always Dirichlet, and is (in part) determined from the connected nodal voltage. To apply a specific voltage to an electrode contact, a voltage source should be attached to it, such as VBB in figure 14.5.

Electrode Material

Table 14.3 lists several different electrode materials that can be specified. The main effect of any metal (nonneutral) material is that Xyce imposes a Schottky barrier at the contact, generally making numerical solutions more difficult, so materials should be applied with caution.

The Xyce Reference Guide [3] provides a detailed description of Schottky barriers and how they are imposed on contacts in Xyce. The guide also provides values for electron affinities of various bulk materials and workfunction values for the various metal contacts.

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Doping and electrode specification example
vscope  1  0  0.0
rscope  2  1  50.0
cid    3  0  1.0u
r1     4  3  1515.0
vid    4  0  1.00
*------------- Diode PDE device ------------------
YPDE Z1DIODE 2 3 PDEDIODE
+ tecplotlevel=1 txtdatalevel=1 cyl=1
+ meshfile=internal.msh
+ nx=25  l=70.0e-4 ny=40  w=26.0e-4
* ELECTRODES:  ckt node 2, ckt node 3
+ node = {name = anode, cathode
+  bc = dirichlet, dirichlet
+  start = 0.002, 0.002
+  end = 0.005, 0.005
+  side = top, bottom
+  material = neutral, neutral
+  oxideBndryFlag = 0, 0 }
* DOPING REGIONS:  region 1, region 2, region 3
+ region= {name = reg1, reg2, reg3
+  function = uniform, gaussian, gaussian
+  type = ntype, ptype, ntype
+  nmax = 4.0e+12, 1.0e+19, 1.0e+18
+  nmin = 0.0e+00, 4.0e+12, 4.0e+12
+  xloc = 0.0, 60.0e-04, 100.0
+  xwidth = 0.0, 4.0e-04, 1.0
+  yloc = 0.0, 24.5e-04, 9.0e-04
+  ywidth = 0.0, 4.5e-04, 8.0e-04
+  flatx = 0, -1, -1
+  flaty = 0, 0, -1 }
*---------end of Diode PDE device ----------------
.MODEL PDEDIODE ZOD  level=2
.options NONLIN maxsearchstep=1 searchmethod=2
.options TIMEINT reltol=1.0e-3 abstol=1.0e-6
.DC vscope 0 0 1
.print DC v(1) v(2) v(3) v(4) I(vscope) I(vid)
.END

Figure 14.11. Two-dimensional example, with detailed doping and detailed electrodes.
Table 14.3: Electrode Material Options. NOTE: Neutral contacts are the default, and pose the least problem to the solvers.

<table>
<thead>
<tr>
<th>Material</th>
<th>Symbol</th>
<th>Comments</th>
</tr>
</thead>
<tbody>
<tr>
<td>neutral</td>
<td>neutral</td>
<td>Default</td>
</tr>
<tr>
<td>aluminum</td>
<td>al</td>
<td></td>
</tr>
<tr>
<td>p+-polysilicon</td>
<td>ppoly</td>
<td></td>
</tr>
<tr>
<td>n+-polysilicon</td>
<td>npoly</td>
<td></td>
</tr>
<tr>
<td>molybdenum</td>
<td>mo</td>
<td></td>
</tr>
<tr>
<td>tungsten</td>
<td>w</td>
<td></td>
</tr>
<tr>
<td>molybdenum disilicide</td>
<td>modi</td>
<td></td>
</tr>
<tr>
<td>tungsten disilicide</td>
<td>wdi</td>
<td></td>
</tr>
<tr>
<td>copper</td>
<td>cu</td>
<td></td>
</tr>
<tr>
<td>platinum</td>
<td>pt</td>
<td></td>
</tr>
<tr>
<td>gold</td>
<td>au</td>
<td></td>
</tr>
</tbody>
</table>

There is also an oxideBndryFlag parameter, which if set to true (1), will model the contact as having an oxide layer in between the metal contact and the bulk semiconductor. By default, oxideBndryFlag is false (0).

**Location Parameters**

Each electrode has three location parameters: start, end, and side.

*Xyce* assumes the internal mesh to be rectangular, with electrodes on any of the sides. The four side possibilities are: top, bottom, right and left. These four sides are parallel to mesh directions. The start and end parameters are floating-point numbers that specify the starting and ending location of an electrode, in centimeters.

The lower left hand corner of the mesh rectangle is located at the origin. A side=bottom electrode with start=0.0 and end=1.0e-4 will originate at the lower left hand corner of the mesh (x=0.0, y=0.0) and end at (x=1.0e-4, y=0.0).

*Xyce* will attempt to match the specified electrode to the specified mesh. However, if the user specifies a mesh that is not consistent with the electrode locations, the electrodes will not be able to have the exact length specified. For example, if the mesh spacing is $\Delta x = 1.0e-5$, then the electrodes can only have a length that is a multiple of 1.0e-5.

### 14.5.2 Electrode Defaults

Defaults exist for each electrode parameter other than names. In practice, the electrode locations are usually explicitly specified using the electrode table. Default electrode locations were created to correspond with the default dopings; they should only be used in that context.
Location Parameters

In practice, the electrode locations will usually be explicitly specified, but they have defaults to correspond with the default dopings. The default electrode locations in one-dimensional devices are for a diode. One electrode is located at $x=x_{\text{min}}$, while the other is located at $x=x_{\text{max}}$.

The default electrode locations in two-dimensional devices depend on the number of electrodes, similar to the default dopings. Table [14.2] can be used to determine such configurations. For the two-terminal diode, the two electrodes are along the $y$-axis, at the $x=x_{\text{min}}$ and $x=x_{\text{max}}$ extrema. For the three-terminal BJT, all three electrodes are parallel to the $x$-axis, along the top, at $y=y_{\text{max}}$. For the four-terminal MOSFET, the drain, gate, and source electrodes are also along the top, but the bulk electrode spans the entire length of the bottom of the mesh, at $y=y_{\text{min}}$.

14.6 Meshes

One- and two-dimensional devices can create Cartesian meshes. For two-dimensional devices, users must specify `meshfile=internal.msh` to invoke the Cartesian meshing capability (this is necessary for historical reasons). Meshes generated in this manner are very simple as there are only two parameters per dimension, and the resulting mesh is uniform. Figure [14.6] provides an example of such a mesh. Mesh spacing is determined from the following expressions:

\[
\Delta x = \frac{l}{nx - 1} \tag{14.8}
\]

\[
\Delta y = \frac{w}{ny - 1} \tag{14.9}
\]

This mesh specification assumes the domain is a rectangle. Nonrectangular domains can only be described using an external mesh program. However, externally-generated meshes are not currently supported.

14.7 Cylindrical meshes

For two-dimensional devices, the simulation area may be a cylinder slice. This capability is turned on by the instance parameter `cyl=1`. It is assumed that the axis of the cylinder corresponds to the minimum radius (or $x$-axis value) of the mesh, while the circumference corresponds to the maximum radius (or maximum $x$-axis value).

14.8 Mobility Models

There are several mobility models available to the one- and two-dimensional devices, and they are listed in Table [14.4]. These models are fairly common, and can be found in most device simulators. [23] [24]. The Xyce Reference Guide [3] describes these models in more detail.
Table 14.4: Mobility models available for PDE devices

<table>
<thead>
<tr>
<th>Mobility Name</th>
<th>Description</th>
<th>Reference</th>
</tr>
</thead>
<tbody>
<tr>
<td>arora</td>
<td>Basic mobility model</td>
<td>Arora, et al. [29]</td>
</tr>
<tr>
<td>analytic or caughey-thomas</td>
<td>Basic mobility model</td>
<td>Caughy and Thomas [30]</td>
</tr>
<tr>
<td>carr</td>
<td>Includes carrier-carrier interactions</td>
<td>Dorkel and Leturq [31]</td>
</tr>
<tr>
<td>philips</td>
<td>Philips model</td>
<td>Klassen [32, 33]</td>
</tr>
</tbody>
</table>

Setting the `mobmodel` parameter to the name of the model (as provided in the first column of table 14.4) specifies the mobility model from the netlist. The mobility model is specified as an instance parameter on the device instance line, as (typically) `mobmodel=arora`. Figure 14.4 provides a more detailed example.

The default mobility is “arora”, which is a basic model lacking carrier or field dependence. Because it lacks these dependencies, it generally is more numerically robust. The “carr” model includes carrier-carrier dependence, as does the “philips” model. For all of these models, field dependence can be optionally turned on from the netlist, using the `fielddep=true` parameter.

### 14.9 Bulk Materials

The bulk material is specified using the `bulkmaterial` instance parameter. Xyce supports Silicon (si) as a default bulk material. It can also simulate several III-V materials, including Gallium Arsenide (gaas), Germanium (ge), Indium Aluminum Arsenide (inalas or alinas) Indium Galium Arsenide (ingaas or gainas), Indium Phosphate (inp), and Indium Galium Phosphate (ingap); but these materials have not been extensively tested. The mobility models described in the previous section each support most of these materials.

### 14.10 Output and Visualization

#### 14.10.1 Using the `.PRINT` Command

For simple plots (such as I-V curves), output results for Xyce can be generated with the `.PRINT` statement, which is described in detail in section 9.1.1. Figures 14.3 and 14.8 are examples of the kind of data that is produced with `.PRINT` statement netlist commands. These particular figures were plotted in Tecplot, but many other plotting programs would also have worked, including XDAMP [34].

#### 14.10.2 Multidimensional Plots

Device simulation has visualization needs which go beyond that of conventional circuit simulation. Multidimensional perspective and/or contour plots are often desirable. Xyce is capable of out-
putting multi-dimensional plot data in several formats, including Tecplot (available for purchase from http://www.tecplot.com), gnuplot (available free from http://www.gnuplot.info), and Sgplot. Currently, the options for each of these formats can only enable or disable the output of files, and when enabled, a new file (or a new append to an existing file) will happen at every time step or DC sweep step.

For long simulations, this may produce a prohibitive number of files. Currently, there is no equivalent to the .OPTIONS OUTPUT INITIAL_INTERVAL command, nor does the output of plot data currently use this command. Plot files are either output at every step or not at all.

For each type of plot file, the file is placed in the execution directory. Each individual device instance is given a unique file, or files, and the file names are derived from the name of the PDE device instance. The instance names provides the prefix, and the file type (Tecplot, gnuplot, Sgplot) determines the suffix.

**Tecplot Data**

Tecplot is a commercial plotting program from Amtec Engineering, Inc., and is the best choice for creating contour plots of spatially dependent data. All of the graphical examples in this chapter were created with Tecplot. (see figures 14.6 and 14.7 for examples) The output of Tecplot files is enabled using the instance parameter, \texttt{tecplotlevel=1}. If set to zero, no Tecplot files are output. If set to one, \texttt{Xyce} outputs a separate Tecplot file for each nonlinear solve. If set to two, \texttt{Xyce} creates a single Tecplot file containing data for every nonlinear solve and appends the file at the end of each solve.

By default \texttt{tecplotlevel} is set to one, meaning the code will produce a separate Tecplot file for each time step or DC sweep step. The suffix for a Tecplot (ASCII text) data file is *.dat.

**Gnuplot Data**

Gnuplot is an open source plotting program available on most Linux/Unix platforms. The parameter for this type of output is \texttt{gnuplotlevel=1}. This type of output file is off (zero) by default, meaning no gnuplot files will be output. The suffix for gnuplot files is *gnu.dat. Like Tecplot files, gnuplot files are also in ASCII text format.

**14.10.3 Additional Text Data**

\texttt{Xyce} can also output additional information for each PDE device by setting the instance parameter, \texttt{txtdatalevel=1}. It is on (1) by default, so this output will happen unless specifically disabled by setting the parameter to zero. A typical output file (associated with the netlist given in figure 14.4) is shown in figure 14.12.
Global data for DC step 1:
Current Time = 0.0000e+00
   Vmin = -8.6931e-06
   Vmax = 5.4030e-01
   NnMin = 0.0000e+00
   NnMax = 1.0000e+16
   NpMin = 3.9240e+03
   NpMax = 1.0000e+19

Information for electrode: COLLECTOR
potential: 2.9795e-01
current: 8.5365e-06
charge: -6.6211e-15
dIdVckt: 3.7993e-02
dQdVckt: 0.0000e+00

Information for electrode: BASE
potential: 5.4030e-01
current: -8.5408e-06
charge: 1.5958e-14
dIdVckt: 1.0463e+01
dQdVckt: 0.0000e+00

Information for electrode: EMITTER
potential: -8.6931e-06
current: 4.3465e-09
charge: -2.3232e-13
dIdVckt: 7.2130e+01
dQdVckt: 0.0000e+00

Figure 14.12. Text output, from the circuit given in figure 14.4.
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http://trilinos.sandia.gov


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